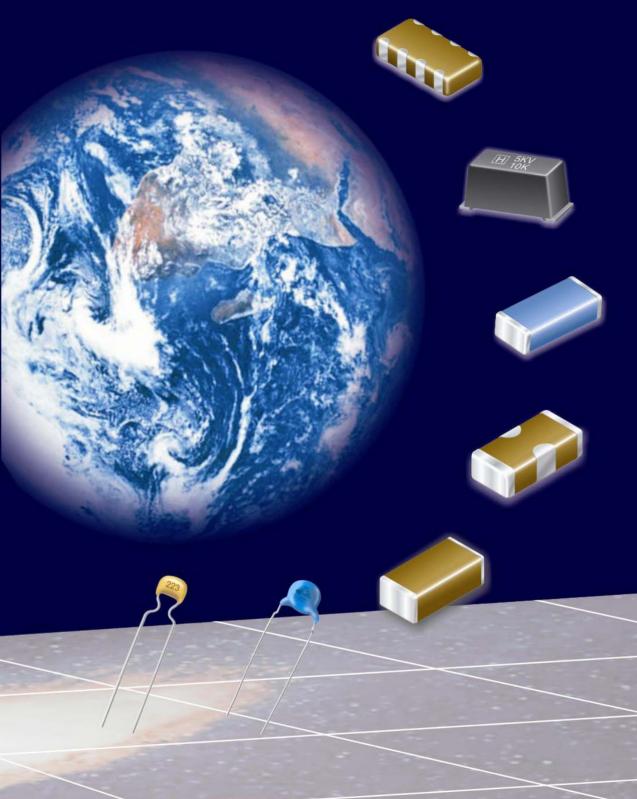


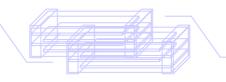
# CERAMIC CAPACITOR





禾伸堂企業股份有限公司 Holy Stone Enterprise Co., Ltd.





### Introduction

#### The Company



Holy Stone Enterprise Company Ltd. (Holy Stone) was established in June of 1981 as an agent and distributor of electronic components. In 1994, with technology

and cooperation from a Japanese partner, Holy Stone began manufacturing Multi-layer Ceramic Capacitors. Today, Holy Stone is recognized as an industry leader in application specific ceramic capacitors.

Holy Stone integrates active and passive component distribution with significant manufacturing capabilities. Holy Stone's unique business model combines the service and inventory management strengths of a broad line distributor with the technical knowledge and world class pricing of a manufacturer.

Holy Stone was founded by five engineers in 1981. Since this point Holy Stone has maintained a focus and commitment to providing customers with innovative products and exceptional service. The result of that unwavering commitment is evident is Holy Stone's phenomenal growth (2006 revenues of US\$360 million). Holy Stone also maintains a high profile on the Taiwan Stock Exchange, ranked in the top 100 companies and the leader among its peers.

#### Manufacturing Facilities

Holy Stone capacitors are produced in a modern 40,000 square meter factory located in Lungtan, Taiwan. In addition to the Lungtan factory, Holy Stone has



facilities in Dongguan and Wujiang China. The advanced materials research laboratory is located in Japan. The factory operating systems are certified to ISO-9001,ISO-14000 and QS-9000.

## Sales and Support Locations

Holy Stone administrative Headquarters are located in Taipei, Taiwan. Holy Stone maintains sales and support offices in Kaohsiung, Taiwan, Dongguan, China and Shanghai, China.



Holy Stone Enterprise Company Ltd has subsidiary companies in North America and in Europe. "HolyStone International", located in Murrieta, California, U.S.A. is responsible for sales and technical support in the Americas. "HolyStone (Europe) Ltd.", located in Norwich, England is responsible for sales and technical service for Europe. Holy Stone also has a network of independent Representatives, Distributors and Agents throughout the world.

#### **■The Environment**

Holy Stone is committed to the cause of achieving and maintaining a healthy environment. The factory is Certified to ISO-14000 and all standard products are designed and produced conforming to full RoHS compliance.

#### Our Employees

Holy Stone's success is measured by the satisfaction of our customers and share holders. Achieving that satisfaction is the result of the sum contribution of our employees. Those contributions come from all of our employees, whether they are engaged in administrative functions, manufacturing our goods or servicing our customers. Holy Stone strives to maintain a work environment that stimulates creativity, encourages enthusiasm and rewards results.

Our employees are Holy Stone, and you should know Holy Stone.



# Holy Stone ... a leader in ceramic capacitors!

- ➤ High capacitance NPO MLCC's to replace Film Capacitors for xDSL
- ➤ High C/V MLCC's for DC/DC Converters and Power Supplies
- ➤ High Voltage MLCC's for Inverter and Data Communication
- > Trigger MLCC's for High Energy Discharge for Strobe
- ➤ Low Profile Capacitors Thin Type X7R, X5R, Y5V
- ➤ Hi-Q Value and Low ESL at High Frequency
- > X2Y3 and X1Y2 Safety Certified MLCC's
- X1Y2 and X1Y1 Safety Certified Disc Capacitors
- ➤ High Voltage Disc Capacitors for Inverter and Power Supplies
- ➤ Large Size High Voltage/High Capacitance for Power Applications
- ➤ Polymer Terminations (Superterm) for crack prevention
- ➤ Coated Products for surface arc prevention





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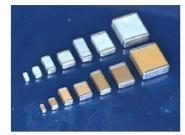
		пи	Stone
	Product Series	Application	Page
	HVC series High Voltage Capacitors	For Power Circuits (Backlight Inverter, DC to DC,)	3-12
	SCC series Safety Capacitors	For Isolation and Protection Circuits (UL,EN132400 Class X2/Y3,X1/Y2)	13-16
	TCX series Trigger Capacitors	For DSC Strobe Circuits	17-20
	LDC series Low Distortion Capacitors	For Oscillation and Filter Circuits	21-24
	NCC series Normal Chip Capacitors	For Decoupling Circuits	25-32
	HCC series High Capacitance MLCC	For Smoothing (DC to DC) and Decoupling Circuits	33-38
	VAC series Low Profile Capacitors – X7R/X5R/Y5V	For small and tin size electronic equipment (for FDP,LCD,HDD,CD-RWetc.)	39-42
	HCN series Hi-Cap NPO	For ADSL/XDSL (Replacement for Film Capacitor)	43-46
	HCX series Hi-Cap X7R	For Input, Output Filters (DC to DC)	47-50
	HCY series Y5U Characteristic MLCC	For Noise suppressor and by pass or decoupling (for DC to DC, DC Fanetc.)	51-54
	RFC series Radio Frequency Capacitors	For High Q & High Frequency Circuits (for Matching Resonant and Coupling Circuit)	55-58
	MCA series Multilayer Capacitor Arrays	For High Density Placement Requirement (for Cellular Phone, Pagers, Mother Board)	59-64
	SAC series Tip & Ring Capacitors	For telephone line ringer circuits	65-68
and a	MMC series Molding Style Capacitors	For Power Circuits (Backlight Inverter, DC to DC,)	69-72
1	FTC series Feed Thru' EMI Filter	For high speed digital integration circuit and decoupling of CPU power lines	73-76
	HTC series High Temperature Capacitors	For high operation temperature up to 200°C	77-80
P	HDC series High Voltage Ceramic Disc Capacitors	For xDSL, Power Circuits (Backlight Inverter, Power Supplier,)	81-86
P	HDC series Ultra High Voltage Ceramic Capacitors	For 10KV to 20KV Application (Pump, Hybrid engine ,Power Supplier,)	87-88
1	SDC series Safety Ceramic Disc Capacitors	For xDSL,Set Top Box, VOIP , Power Supplier (UL,CSA,EN132400 Class X1/Y2,X1/Y1)	89-94
13	RDC series Radial Dipped Ceramic Capacitors	For Car Electronic , Inverter and Converter, Power Supplier	95-98
P	RDH series – Ultra High Voltage Radial Dipped Cap	For Fuel pump, Water pump, Hybrid engine ,Power Supplier	99-104
-	AXC series – Axial Leader Ceramic Capacitors	For General Electronic, Power supplier	105-108
_			





# Multilayer Ceramic Chip Capacitors [High Voltage Capacitor]

# **HVC** Series – Middle Voltage (100V-1KV)



**Holy Stone** high voltage products are designed and manufactured to meet the general requirements of international standards.

The product offering is well suited for commercial and industrial applications and includes C0G (NPO) and X7R characteristics in 0603 to 2225 sizes with working voltages up to 1KV.

#### ◆ Features

- ☐ Special internal electrode design offers the highest voltage rating
- ☐ Surface mount suited for wave and reflow soldering
- ☐ High reliability
- RoHS compliant

## **♦** Applications.

☐ Suitable for LAN/WLAN interface, Back-Lighting Inverter ,DC-DC Converters, Ballast, Modems & Power Supplies.

## **♦ Summary of Specification**

Operation Temperature	-55~+125 ℃
Rated Voltage	100Vdc to 1000Vdc
Temperature Coefficient	NPO : $\leq$ ± 30ppm/ $^{\circ}$ C , -55~+125 $^{\circ}$ C (EIA Class $I$ )
	X7R : ≤ ± 15% , -55~+125 °C (EIA Class Ⅱ )
Capacitance Range	NPO :2pF to 100nF ; X7R :150pF to 2.2uF
Dissipation Factor :	NPO : Q≥1000 ; X7R : D.F.≤2.5%
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller
Aging	NPO:0%; X7R: 2.5 % per decade of time
Dielectric Strength	100V ≤ V < 500V : 200% Rated Voltage
	500V ≤ V < 1000V : 150% Rated Voltage
	1000V≦ V : 120% Rated Voltage

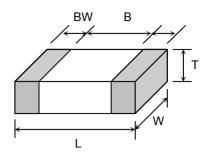
#### ♦ How To Order

С	1210	Х	103	K	102	Т	X
Product Code C: MLCC (Multilayer Ceramic Chip of Capacitor)	Chip Size  EX.: 0603: 1.6×0.80mm 0805: 2.0×1.25mm 1206: 3.2×1.60mm 1210: 3.2×2.50mm 1808: 4.6×2.00mm 1812: 4.6×3.20mm 2220: 5.7×5.00mm	Dielectric  Ex.: N: NPO X: X7R	Capacitance Unit: pF Ex.: 2R0:2.0pF 100:10x10º 471:47x10¹ 102:10x10²	Tolerance  Ex.: C:+/-0.25pF D:+/-0.50pF J:+/-5% K:+/-10% M:+/-20%	Rated Voltage Ex.: 251:250Vdc 631:630Vdc 102:1000Vdc	Packaging T: Taping &Reel B: Bulk	Special Requirement Ex.: O: Arc Prevention Coating X: Cushion Termination (Super Term)





#### **♦** Dimension

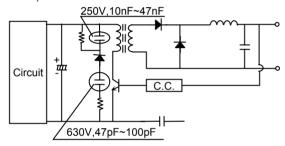


				Uni	t : mm [inches]
TYPE	L	W	T (max)	B (min)	BW (min)
0603	1.60±0.1	0.80±0.1	0.90	0.40	0.15
	[.063±.004]	[.031 ±.004]	[.039]	[.016]	[.006]
0805	2.00±0.20	1.25±0.20	1.45	0.70	0.20
	[.126±.012]	[.126±.012]	[.057]	[.059]	[.012]
1206	3.20±0.30	1.60±0.20	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1210	3.20±0.30	2.50±0.20	2.60	1.60	0.30
	[.126±.012]	[.126±.012]	[.102]	[.059]	[.012]
1808	4.60±0.30	2.00±0.20	2.20	2.50	0.30
	[.181±.012]	[.079±.008]	[.087]	[.098]	[.012]
1812	4.60±0.30	3.20±0.30	3.00	2.50	0.30
	[.181±.012]	[.126±.012]	[.118]	[.098]	[.012]
1825	4.6±0.30	6.35±0.40	3.00	2.50	0.30
	[.220±.012]	[.250±.016]	[.118]	[.098]	[.012]
2220	5.7±0.40	5.00±0.40	3.00	3.50	0.30
	[.220±.016]	[.197±.016]	[.118]	[.137]	[.012]
2225	5.7±0.40	6.35±0.40	3.00	3.50	0.30
	[.220±.016]	[.250±.016]	[.118]	[.137]	[.012]

## Application

#### **Example Circuit**

DC-DC Converter



**◆** Capacitance Range

Temperature	0:	Rated						tance Rang					
Characteristic	Size	Voltage	2R0 3R3 3R9 5R0 8R2	120 130 180 180 180 180 180 180 180 180 180 18	2220 2270 470 470	101 121 121 121 121 121	151 181 221 271 331	391 471 681 821	102 152 152 222 222	272 332 392 472 562	682 822 103 123 153	183 223 273 333 393	473 563 104
	0603	100V					ВВВВВ						
	0003	200V			ввввв								
		100V		вввв	ввввв	ВВВВВ	ВВВВВ	ввввв	В				
	0805	200V	BBBBB	вввв	ввввв	BBBBB	ВВВСС	CCCC					
	0003	250V	BBBBB	вввв	ввввв	ВВВВВ	ВВВСС	CCCC					
		500V	cccc	CCCC	CCCCC	CCCCC	cccc	CCCC					
		200V	BABABABAB	(BQBQBQBQI	BqBqBqBqBq	3 <b>4</b> B4B4B4B4B4	BdBdBdBdBd	BABABABABA	DEDEDEDEDE	EEEE			
	1206	250V		C	CCCCC	CCCCC	CCCCC	CCDDD	DEDEDEDEDE	EEEE			
	1200	500V		C	CCCCC	CCCCC	CCCCC	CCDDD	DEDED D				
		1KV		DDDD	DDDDD	DDDDD	EEEEE	EEEEE					
NPO		200V		BQBQBQBQI	BQBQBQBQBQB	3(B(B(B(B(B	BQBQBQBQBQ	B <b>(</b> B <b>(</b> B <b>(</b> B <b>(</b> B(	DDDDD	DEDEEEE			
0	1210	250V					CCCCC				EEE		
		500V			C	CICICIC	CCCCC	CCCC	DDDEE	FFF			
	1808	1KV	DDDDC	DDDD	DDDDD	DDDDE	EEEEE	EEEEF	EEEEF				
	1812	1KV				DDDD	DDDDD	DDDDD	EEFF	野野FFF	G		
	2220	1KV				DD	DDDDD	DDDDD	DDDEE	FFFFF	FFFF	G	
		250V				DD	DDDDD	DDDDD	DDDDD	DDDDC	EEFFF	₽ F F	
	1825	500V				DD	DDDDD	DDDDD	DDDDD	DDDDC	EEFFF	野野FFG	HHHH
		1KV				DD	DDDDD	DDDDD	DDDEE	F F F F	FFF		
		250V				DD	DDDDD	DDDDD	DDDDD	DDDDC	DEEF	野野野 F	
	2225	500V				DD	DDDDD	DDDDD	DDDDD	DDDDD	DEEF		
		1KV				DD	DDDDD	DDDDD	DDDEE	EEFF	FF F		
Symbol Code		S	0	Α	В	С	D	E	F	G	Н		
Thickness(m	m) [ 0.	3±0.03	0.5±0.05	0.6±0.1	0.85±0.1	1.0±0.1	1.25±0.15	1.6±0.2	2.0±0.2	2.4±0.2	2.8±0.2		

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





## **◆ Capacitance Range**

Capaci	tance	Range	
T		Detect	Capacitance Range (pF)
Temperature	Size	Rated	22
Characteristic	0000		
	0603	100V	BIBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
		100V	BBBB BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
	0805	200V	Robadadar andadadadadadadadadadadadadada andadadada
		250V	CCCC CCCCCCCCCCCCCCDDDD
		500V	dade dadadadade dada
		100V	CCCCCCCCCCCCCCCCCCCCCCCCCCCCCCCCCCCCCC
		200V	CCCCCCCCCCCCCCCCCDDD
	1206	250V	CCCCCCCCCCCCCCCCCCCCCCCCCDD
	1200	500V	dadadada dadadadada dadadada b
		630V	DDDDD DDDDDEEEE
		1KV	
		100V	
		200V	
	1210	250V	
		500V	DDEEEFF
X7R		1KV	DDDDDEFF
	4000	500V	DDDDDDDDDDDDDEEF
	1808	1KV	DDDDEEFFFF
		200V	DDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDD
	4040	250V	DDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDDD
	1812	500V	DDDDDDDDEEEEEGHH
		1KV	DDDDDDDDDDDDDDDDEE EEEEFFFFFGGH H
		250V	
	2220	500V	DDDDDDDDDDDDDDDDDDEEEE EEFFFFGGH
		1KV	DDDDDDDDDDDD EEEEEEFFFF FGGHH
		250V	
	1825	500V	DEEEEEEEFF FFFFG
		1KV	
		250V	
	2225	500V	
		1KV	DEEEEEEEFFF FFFGH
Symbol Code	<u> </u>	S	O A B C D E F G H
Symbol Code Thickness(mr		S±0.03 (	
1110001033(111	., 0.0	,_0.00	0.000.00   0.000.11   0.000.11   1.000.11   1.000.10   1.010.2   2.010.2   2.710.2   2.010.2

<sup>■</sup> Other dimensions, capacitance values and voltages rating are available. Please contact HEC.



# Multilayer Ceramic Chip Capacitors [High Voltage Capacitor]

# **HVC** Series – High Voltage Capacitors (2KV)



This series is offered in C0G(NPO) and X7R temperature characteristic in sizes from 1206 to 2220. This series can passed 1500VAC or 2250VDC Hi-Pot.

#### ◆ Features

- ☐ Standard for telecommunication devices (IEEE802.3) in LAN interface.
- ☐ Available with proprietary coating to prevent arcing and pass Hi-Pot test
- ☐ Surface mount suited for wave and reflow soldering
- ☐ Special internal electrode design offers the highest voltage rating
- □ RoHS compliant

### Application

- □ Suitable for telecommunication devices in LAN interface
- Ballast capacitor for back light inverter applications

## **♦** Summary of Specification

Operation Temperature	-55~+125 ℃
Rated Voltage	2KVdc
Temperature Coefficient	NPO : $\leq$ ± 30ppm/ $^{\circ}$ C , -55~+125 $^{\circ}$ C (EIA Class $I$ )
	X7R : ≤ $\pm$ 15% , -55~+125 $^{\circ}$ C (EIA Class ${                                  $
Capacitance Range	NPO :2pF to 470pF ; X7R :150pF to 10nF
Dissipation Factor :	NPO : Q≥1000 ; X7R : D.F.≤2.5%
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller
Aging	NPO:0%; X7R: 2.5 % per decade of time
Dielectric Strength	120% Rated Voltage

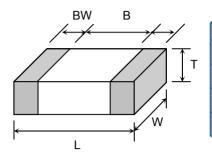
#### **♦** How To Order

С	1206	X	102	К	202	T	0
Product Code C: MLCC (Multilayer Ceramic Chip of Capacitor)	Ex.: 1206: 3.2×1.6mm 1808: 4.6×2.0mm 1812: 4.6×3.2mm 2220: 5.7×5.0mm	Dielectric Ex.: N: NPO X: X7R	Capacitance Unit: pF Ex.: 2R0:2.0pF 100:10×10° 471:47×10¹ 102:10×10²	Tolerance  Ex.: C:+/-0.25pF D:+/-0.50pF J:+/-5% K:+/-10% M:+/-20%	Rated Voltage Ex.: 202:2000Vdc	Packaging T: Taping &Reel B: Bulk	Special Requirement Ex.: O: Arc Prevention Coating X: Cushion Termination (Super Term)



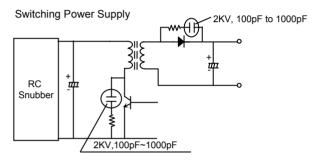


### **♦** Dimension



				Uni	t : mm [inches]
TYPE	L	W	T (max)	B (min)	BW (min)
1206	3.20±0.30	1.60±0.20	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1808	4.60±0.30	2.00±0.20	2.20	2.50	0.30
	[.181±.012]	[.079±.008]	[.087]	[.098]	[.012]
1812	4.60±0.30	3.20±0.30	3.00	2.50	0.30
	[.181±.012]	[.126±.012]	[.118]	[.098]	[.012]
2220	5.7±0.40	5.00±0.40	3.00	3.50	0.30
	[.220±.016]	[.197±.016]	[.118]	[.137]	[.012]

## ◆ **Application** Example Circuit



# **♦** Capacitance Range

Temperature	0.	Rated										Ca	paci	itan	ce R	ange	e (p	F)											
Characteristic	Size	Voltage	2R0	3R9 5R0	8R2	100	150	180	220	330	390	470	089	820	101	151	181	221	271	331	471	561	681	821	102	152	182	222	272
	1206	2KV				D D	D	D	DE	D D	D	D	DD	D	DI	D D/I	E D/E	D/E	D/E	D/E D.	Έ					I			
NPO	1808	2KV	D	DDD	D	D D	D	D	D [	D D	D	D	DD	D	D	JF E/I	E/F	E/F	E/F	E/F									
	1812	2KV											D	D	D	D D	D	D	Е	EF	F								
Temperature		Rated										Ca	paci	itan	ce R	ang	e (p	F)											
Characteristic	Size	Voltage	151	221 271	331	391 471	561	681	821	122	152	182	272	332	392	47.2 562	682	822	103	123	183	223	273	333	393	41.3	683	823	104
	1206	2KV		D D		DD	D	D	D D/	EE	E																		
X7R	1808	2KV	D	DDD	D	D D	D	D	DΕ	D D	D	D	D													I			
A/IX	1812	2KV		D	D	D D	D	D	DΕ	D D	D	E	E F	F	F	F		G	Н										
	2220	2KV								D	D	D	DD	E	E	FF	F	F	F										
Symbol Code	S	(	)	Α		[	3		(	С		[	)		Е			F			C	}			Н	٦			
Thickness(mm)	0.3±0	0.5±	0.05	0.6±0	0.1	0.85	±0.	1	1.0	±0.1	1	1.25:	±0.1	5	1.6±	0.2	2	2.0±	0.2	1	2.4±	±0.2	2 :	2.8	±0.2	<u>-</u>			

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.



# Multilayer Ceramic Chip Capacitors [High Voltage Capacitor]

# **HVC** Series – Ultra High Voltage (3KV-5KV)



Capacitors with voltage ratings or 3KV to 5KV are ideally suited for LCD back light inverter circuits.

#### **♦** Features

- ☐ Super term termination prevents cracking solution mechanical stress
- ☐ Special internal electrode design offers the highest voltage rating
- ☐ Surface mount suited for wave and reflow soldering
- □ High reliability
- ☐ RoHS compliant

## Applications

☐ Suitable for back-lighting inverter ,DC-DC converters, modems and power supplies

## ◆ Summary of Specification

Operation Temperature	-55~+125 ℃
Rated Voltage	3KVdc to 5KVdc
Temperature Coefficient	NPO : $\leq$ ± 30ppm/ $^{\circ}$ C , -55~+125 $^{\circ}$ C (EIA Class I )
	X7R : ≤ ± 15% , -55~+125 °C (EIA Class Ⅱ )
Capacitance Range	NPO :2pF to 1.0nF ; X7R :150pF to 2.7nF
Dissipation Factor :	NPO : Q≥1000 ; X7R : D.F.≤2.5%
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller
Aging	NPO:0%; X7R: 2.5 % per decade of time
Dielectric Strength	120% Rated Voltage

#### ♦ How To Order

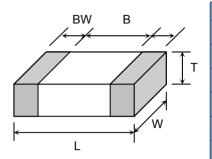
С	1808	N	5R0	С	302	Т	X
Product Code C: MLCC (Multilayer Ceramic Chip of Capacitor)	Ex.: 1206: 3.2×1.6mm 1808: 4.6×2.0mm 1812: 4.6×3.2mm 2208: 5.7×2.0mm 2211: 5.7×2.8mm 2220: 5.7×5.0mm	Dielectric Ex.: N: NPO X: X7R	Capacitance Unit: pF Ex.: 2R0:2.0pF 100:10x10° 471:47x10¹ 102:10x10²	Tolerance  Ex.: C:+/-0.25pF D:+/-0.50pF J:+/-5% K:+/-10% M:+/-20%	Rated Voltage Ex.: 302:3000Vdc 502:5000Vdc	Packaging T: Taping &Reel B: Bulk	Special Requirement Ex.: O: Arc Prevention Coating X: Cushion Termination (Super Term)





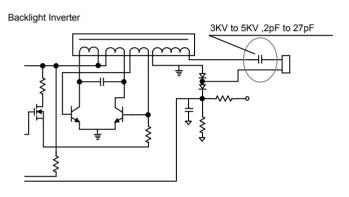
Unit: mm [inches]

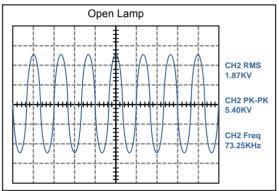
### **♦** Dimension



TYPE	L	W	T (max)	B (min)	BW (min)
1206	3.20±0.30	1.60±0.20	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1210	3.20±0.30	2.50±0.20	2.60	1.60	0.30
	[.126±.012]	[.126±.012]	[.102]	[.059]	[.012]
1808	4.60±0.30	2.00±0.20	2.20	2.50	0.30
	[.181±.012]	[.079±.008]	[.087]	[.098]	[.012]
1812	4.60±0.30	3.20±0.30	3.00	2.50	0.30
	[.181±.012]	[.126±.012]	[.118]	[.098]	[.012]
2208	5.7±0.40	2.00±0.20	2.20	3.50	0.30
	[.220±.016]	[.079±.008]	[.087]	[.137]	[.012]
2211	5.7±0.40	2.80±0.40	3.00	3.50	0.30
	[.220±.016]	[.110±.016]	[.118]	[.137]	[.012]
2220	5.7±0.40	5.00±0.40	3.00	3.50	0.30
	[.220±.016]	[.197±.016]	[.118]	[.137]	[.012]

# ◆ **Application** Example Circuit





# **♦ Capacitance Range**

-	•									
Temperature	0:	Rated			(	Capacitance	e Range (pl	=)		
Characteristic	Size	Voltage	2R0 3R3 3R9 5R0 8R0	100 150 150	220 220 270 330	580 680 680	101 121 151	221 271 271 331	391 471 561 681	102 102 122 152 182 727
	1206	3KV	DDDDD	DDDD	DDEE					
	1808	3KV	DDDDD	DDDD	DDDD		DEE	F E/F E/F E/F E	FFF	
	1000	5KV	FFFFF	BBB	366					
NPO	1812	3KV		DDD	DDDD	DDDD	FFFF	FFF	FFF	
	2208	5KV	FFFFF							
	2211	5KV	FFFFF	BBBB	BEBB	BEE				
	2220	5KV	FFFFF	FFF	FFFF	FFFF	FFF			
Temperature		Rated			(	Capacitance	e Range (pl	=)		•
Characteristic	Size	Voltage	151 181 221 271 331	561 681	102 102 122 152	222 222 272 332 332	582 562 682 822	103 123 153	223 273 273 333	393 473 563 683 823 104
	1808	3KV	DDDDD	DDDD	DDFF					
X7R	1000	4KV	D D D D D/E	)/E D/E D/F D/F D	)/F D/F					
	1812	3KV		D	DDEE	366				
Symbol Code	S	0	Α	В	С	D	E	F	G	Н
Thickness(mm)	0.3±0	0.5±0	0.6±0.1	0.85±0.1	1.0±0.1	1.25±0.15	1.6±0.2	2.0±0.2	2.4±0.2	2.8±0.2

<sup>■</sup> Other dimensions, capacitance values and voltages rating are available. Please contact HEC.



<b>HVC Series S</b>	pecification & Tes	t Condition

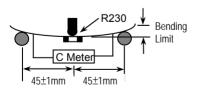
Item	Specification	Test Condition		
Operation Temperature	-55 to +125℃			
Visual	No abnormal exterior appearance	Visual Inspection		
Capacitance	Within The Specified Tolerance	Class Frequency Voltage		
Quality Factor	Class I (NPO): More Than 30pF : Q ≥1000 30pF & Below: Q≥400+20C (C:Cap., pF)	NPO C≤100pF 1MHz±10% 1.0±0.2Vrms C>100pF 1KHz±10%		
Dissipation Factor	Class II (X7R): Maximum 0.025	Tage		
Insulation Resistance	10,000M $\Omega$ or 500/C $\Omega$ whichever is smaller. (C in Farad)	V≦500V, Rated Voltage V> 500V, Applied 500Vdc Charge Time : 60sec. Is applied less than 50mA current.		
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	V<500V: 200% Rated Voltage 500V≦V<1000V: 150% Rated Voltage 1000≦V:120% Rated Voltage for 1~5 sec. Current is limited to less than 50mA. Withstanding voltage testing requires immersion of the element in a isolation fluid prevent arcing on the chip surface, at voltage over 1000Vdc.		
Temperature Capacitance Coefficient	Char.         Temp. Range         Cap. Change           NPO(N)         -55°C ~ +125°C         ± 30ppm/°C           X7R (X)         -55°C ~ +125°C         ± 15%	Class I:  [C2-C1/C1(T2-T1)] × 100%  Class II:  (C2-C1)/C1 × 100%  T1:Standard Temperature(25°C)  T2:Test Temperature  C1:Capacitance At Standard Temperature  C2:Capacitance At Test Temperature		
Adhesive Strength of Termination	No indication of peeling shall occur on the terminal electrode.	A 5N·f(≈0.5Kg·f) pull force shall be applied for 10±1 sec.		

# Resistance to Flexure of Substrate

No mechanical damage or capacitance change more than the following table.

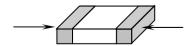
Char.	Capacitance Change
NPO(N)	$\leq$ ± 5.0% of initial value
X7R (X)	$\leq$ ± 12.5% of initial value

The board shall be bent 1.0mm with a rate of 1.0 mm/sec.



#### Solderability

More than 90% of the terminal surface is to be soldered newly, so metal part does not come out or dissolve .



Solder Temperature : 245±5°C

Dip Time :  $5 \pm 0.5$  sec.

Immersing Speed : 25±10% mm/s

Solder : H63A Flux :Rosin

Preheat : At 80~120 °C For 10~30sec.





# **HVC Series Specification & Test Condition**

Item		Specification	Test Condition			
Resistance to Soldering Heat	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48 $\!\pm$ 4 hours at room temperature after one hour heat treatment			
	Within 2.5% or ±0.25pF whichever F is larger of initial value  Class II (X7R):  Within ±10% of initial value		at 150 +0/-10°C before initial measure.  Preheat: at 150±10°C for 60~120sec.  Dip: solder temperature of 260±5°C  Dip Time: 10 ± 1sec.  Immersing Speed: 25±10% mm/s  Solder: H63A  Flux: Rosin			
	Insulation Resistance	To satisfy the specified initial value	Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours			
Temperature Cycle	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48±4 hours at room temperature after one hour heat			
	Capacitance	Class I (NPO): Within 2.5% or ±0.25pF whichever is larger of initial value	treatment at 150 +0/-10 °C before initial			
		Class II (X7R): Within ±7.5% of initial value	Step         Temp.(°C)         Time(min)           1         Min Rated Temp.+0/-3 (-55)         30			
	Q / Tan $\delta$	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.+3/-0 (125) 30			
	Insulation Resistance	To satisfy the specified initial value	$\frac{4 \qquad 25 \qquad 3}{\text{Measure at room temperature after cooling for Class I}: 24 \pm 2 \text{ Hours}}$ Class II: 48 \pm 4 Hours			
Humidity	Appearance No mechanical damage shall occur		Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measure.			
	Capacitance Class I (NPO):  Within 5% or ±0.5pF whichever		Temperature : $40\pm 2$ °C Relative Humidity : $90 \sim 95\%$ RH Test Time : $500 + 12/-0$ hr			
	Q / Tan o Class I (NPO):  More Than 20nF : O > 250		Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours			
		Class II (X7R): Maximum ±5.0%				
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)				





# **HVC Series Specification & Test Condition**

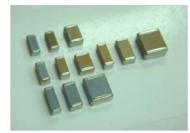
Item		Specification	Test Condition			
High Temperature Load	Appearance	No mechanical damage shall occur	Class II capacitors applied DC voltage (following table) is applied for one hour at maximum			
(Life Test)	Capacitance	Class I (NPO): Within 3% or ±0.3pF whichever is larger of initial value	operation temperature ±3°C then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage:			
		Class II (X7R): Within ±15% of initial value	Rated Voltage     Applied Voltage       V≤250Vdc     150%Rated Voltage       250Vdc < V< 1KVdc			
	Q / Tan $\delta$	Class I (NPO): More Than 30pF : Q ≥ 350 30pF & Below: Q≥275+2.5C	More Than 100%Rated Voltage 1KVdc(include 1KV)			
		Class II (X7R): Maximum ±5%	Temperature: max. operation temperature Test Time: 1000 +12/-0Hr Current Applied: 50 mA Max.			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever i smaller. (C in Farad)	is Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours			
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. board.			
	Capacitance	Within the specified tolerance	<ul> <li>Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz in about 1 min.</li> <li>Repeat this for 2 hours each in 3 perpendicular directions.</li> </ul>			
	$Q$ / $Tan\delta$	To satisfy the specified initial value				





# Multilayer Ceramic Chip Capacitors [Safety Capacitor – X2Y3 & X1Y2]

# **SCC** Series





The SCC series X2/Y3 & X1/Y2 safety capacitors are designed specifically for use in modem, facsimile, telephone and other electronic equipment.

These parts are compliant to EN132400,IEC60384-14 and UL60950 standards. These capacitors are available in C0G(NPO) and X7R dielectrics.

#### Features

- ☐ Small size & high capacitance
- ☐ Suitable for reflow soldering
- Surface mount
- ☐ Safety standard approval by EN 132400+A4:01 and UL 60950
- ☐ Certificate Number : by TUV R50005234 & UL E229738
- ☐ RoHS compliant

## Application

☐ The X2/Y3 & X1/Y2 specially designed for use in Modem, Facsimile, Telephone and other electronic equipment for lighting and surge protection, EMI Filter and Isolation.

## **♦** Safety Detail of Specification

EN132400: 1994 A2: 1998 +A3: 1998 +A4: 2001	Meets The Electrical Requirements and certification for Equipment requiring Class X1/Y2 and X2/Y3 devices.
IEC 60950 : 2000	Component Certified for Equipment requiring IEC 60950 compliance
IEC 384-14: 1993 A1: 1995	Component Certified for Equipment requiring IEC-384 compliance
UL 60950 : 2002 Third Edition	TNV/SELV Isolation Capacitors Certified To UL 60950

#### **♦** How To Order

SCC	1808	Х	102	К	502	Т	S
Product Code SCC: Safety Approved of MLCC Product	Ex.: 1808: 4.6x2.0mm 1812: 4.6x3.2mm 2208: 5.7x2.0mm 2211: 5.7x2.8mm 2220: 5.7x5.0mm 2825: 6.8x6.3mm	Dielectric Ex.: N: NPO X: X7R	Capacitance Unit: pF Ex.: 100:10x10º 471:47x10¹ 182:18x10²	Tolerance  Ex.:     J :+/- 5%     K :+/-10%     M:+/-20%	Class  Ex.: 202: X2 302: X2/Y3 502: X1/Y2 602: X1/Y2 for SCC2208N, SCC2211N, SCC2220N	Packaging T: Taping &Reel B: Bulk	Special Requirement Ex.: S: Arc Prevention Coating X: Cushion Termination (Super Term)

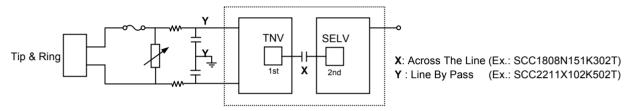




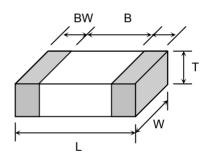
# **♦** Summary of Specification

Rated Voltage	AC 250Vrms		
Temperature Coefficient	NPO : < 30ppm/ ℃ , -55~+125 ℃ (EIA Class I )		
Temperature Coemicient	X7R : < ± 15% , -55~+125 ℃ (EIA Class Ⅱ)		
Capacitance Range	X2/Y3 :2.0pF ~ 2700pF ; X1/Y2 :2.0pF ~ 4700pF		
Capacitance Nange	X2:4700pF,5600pF		
Quality and Dissipation Factor	NPO: Q≥1000 ; X7R: D.F.≤2.5%		
Climatic Category	-55/125/21		
Insulation Resistance	<b>10G</b> Ω		
Voltage Proof	X Capacitor :Applied Voltage 1075Vdc(4.3Ur) Y Capacitor :Applied Voltage 1500Vac		
Impulse	Y3: 2.5KV (Compliant to IEC 60950); X2:2.5KV / Y2:5KV for three times		
Aging	NPO: 0 % ; X7R: 2.5 % per decade hr, Typical		

## ◆ Application Example Circuit



## **♦** Dimension



Unit : mm [inches]							
TYPE	L	W	T (max)	B (min)	BW (min)		
1808	4.60±0.3	2.00±0.2	2.20	2.50	0.20		
	[.181±.012]	[.079 ±.008]	[.087]	[.157]	[.008]		
1812	4.60±0.3	3.20±0.3	2.60	2.50	0.20		
	[.181±.012]	[.126±.012]	[.102]	[.157]	[.008]		
2208	5.70±0.4	2.00±0.2	2.20	4.00	0.30		
	[.220±.016]	[.079±.008]	[.087]	[.157]	[.012]		
2211	5.70±0.4	2.80±0.3	3.00	4.00	0.30		
	[.220±.016]	[.110±.012]	[.118]	[.157]	[.012]		
2220	5.70±0.4	5.00±0.4	3.00	4.00	0.30		
	[.220±.016]	[.197±.016]	[.118]	[.157]	[.012]		
2825	6.80±0.4	6.35±0.4	4.00	4.00	0.30		
	[.220±.016]	[.197±.016]	[.118]	[.157]	[.012]		

## ◆ Capacitance Range

		Temperature	Rated		Capacitance Range (pF)				
Class	Size Characteristic		Voltage	Certificated	88				
X2/Y3	1808	NPO	250Vrms	TUV/UL					
	1808	X7R	250Vrms	TUV/UL					
	1812	X7R	250Vrms	TUV/UL					
X1/Y2	1808	NPO	250Vrms	TUV/UL					
	1808	X7R	250Vrms	TUV/UL					
	1812	X7R	250Vrms	TUV/UL					
	2211	X7R	250Vrms	TUV/UL					
	2208	X7R	250Vrms	TUV/UL					
	2220	X7R	250Vrms	TUV/UL					
	2208	NPO	250Vrms	TUV/UL					
	2211	NPO	250Vrms	TUV/UL					
	2220	NPO	250Vrms	TUV/UL					
X2	2825	X7R	250Vrms	TUV					





					Holy Stone	
SCC Series Sp	ecification &	& Test Condition				
Item	Specif	ication	Te	est Condition		
Operation Temperature	-55 to +125℃					
Visual	No Abnormal E	Exterior Appearance	Visual Inspe	ction		
Capacitance	Within The Spe	ecified Tolerance	Char.	Frequency	Voltage	
Quality and Dissipation Factor		: OpF: Q ≥1000 v: Q≥400+20C (C:Cap., pF)	NPO C≤100pF C>100pF	1MHz±10% 1KHz±10%	1.0±0.2Vrms	
	Class II (X7R):		X7R	1KHz±10%	1.0±0.2Vrms	
	Maximum 2.5	% (0.025)		eat treatment at t room temp. for	150±5℃ for 30min. 24±2hr.	
Insulation Resistance	Minimum 10,00	$\Omega$ MO	Applied Vol Applied Vol		ge Time : 60sec.	
Voltage Proof	No dielectric b breakdown	reakdown or mechanical	X Capacitor Y Capacitor	Applied Voltage: X Capacitor :Applied Voltage 1075Vdc(4.3Ur) Y Capacitor :Applied Voltage 1500Vac For 1min. Current is limited to less than 50mA.		
Adhesive Strength of Termination				A 5N·f ( $\approx$ 0.5Kg·f) pull force 5N·f shall be applied for 10±1 section 10±1 sectio		
Resistance to Flexure of	No mechanical than the follow	I damage or change C more ing table.	The board sh mm/sec.	nm with a rate of 1.0		
Substrate	Capacitance C Class I (NPO) Class II (X7R)	$\leq$ $\pm$ 5% of initial value	_	C Meter	Bending Limit	
Solderability		of the terminal surface is to be a so metal part does not come .	Dip Time : 5 Immersing S Solder : F Flux :R	perature : 245±5 i ± 0.5 sec. Speed : 25±10% l63A losin At 80~120 °C Fo	mm/s	
Resistance To Soldering Heat	Appearance	No mechanical damage shall occur	Dip : solder	Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C		
	Capacitance	Cap. Change	Dip Time : 1 Immersing S		mm/s	
	Class I (NPO)	$\leq$ ±10% of initial value	Solder : F			
	Class II (X7R)	$\leq$ ±20% of initial value		tosin room temp. afte	r coolina for:	
	Insulation Resistance	More than 1,000M $\Omega$	Class II:			
	Voltage Proof	To satisfy the specified initial value				





# **SCC Series Specification & Test Condition**

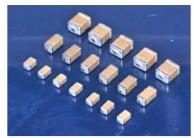
Item	Spec	ification	Test Condition		
Damp Heat / Steady State	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48±4 hours at room temperature after one hour deage		
	Capacitance	Cap. Change	treatment at 150 +0/-10°C before initial measure.		
		$\frac{1}{100} = \frac{1}{100} = \frac{1}$	Test Condition :		
		X7R $\leq \pm 20\%$ of initial value	Temperature : 40± 2(°C)		
	Q (NPO) Class I	More Than 30pF:Q≥350 30pF& Below:Q≥275+2.5C	Relative Humidity : 90 ~95%RH Test Time : 500 +12/-0 hr (21days)		
	Tan $\delta$ (X7R) Class ${ m II}$	Maximum 5% (0.05)	The capacitors with rated voltage(250Vac) applied.		
	Insulation Resistance	More than 1,000M $\Omega$	Measure at room temp. after cooling for: Class I : $24 \pm 2$ Hours Class II : $48 \pm 4$ Hours		
	Voltage Proof	To satisfy the specified initial value			
Endurance	Appearance	No mechanical damage shall occur	Impulse Voltage Each individual capacitor shall be subjected		
	Capacitance	Cap. Change	a 2.5KV(X2) and 5.0KV(X1/Y2) impulse for three times. Then the capacitors are applied to		
		NPO ≤ ±20% of initial value	life test.		
		X7R $\leq \pm 25\%$ of initial value	Additional impulse 2.5KV of Y3 compliant to EN60950 standard.		
	Q Class I	More Than 30pF:Q≥350 30pF& Below:Q≥275+2.5C	71(1.2us) = 1.67T $71(1.2us) = 1.67T$ $71(1.2us) = 1.67T$		
	Tan $\delta$ Class ${ m II}$	Maximum 5% (0.05)	50		
	Insulation Resistance	More than 1,000M $\Omega$	30 t		
	Voltage Proof	To satisfy the specified initial value	Temperature: 125°C Test Time: 1000hrs Applied Voltage: Class X Capacitors:1.25Ur (312.5Vac) Class Y Capacitors:1.70Ur (425Vac) Except that once every hour the voltage shall be increased to 1000Vrms for 0.1s.		
Passive Flammability	Capacitor did	n't burn at all	Volume Sample : 21.56mm3 Flame exposure time : 5 sec.Max.		
Active Flammability	The cheese c	loth shall not burn with a flame	The capacitors of class X2/Y3 & X1/Y2 each test capacitors applied Ur(250Vac).		
			Then each sample shall be subjected to 20 discharges from a tank capacitor, charge to a voltage that, when discharged, places Ui(Y3:2.5KV,Y2:5KV) across the capacitor under test. The interval between successive discharges shall be 5s.		





# Multilayer Ceramic Chip Capacitors [Trigger Capacitors for Strobe]

# **TCX** Series



**TCX** series are specifically designed with a proprietary material for discharge applications such as strobe circuit applications. The unique properties of the <u>X7E material</u>, and the design of TCX, makes them suitable for any discharge application which requires the capacitor to have <u>a good damping</u> characteristic.

**TCX series** are also suitable for applications where a significant change of capacitance value with temperature is not desired. TCX series is offered in <u>0805</u>, <u>1206</u> and <u>1210</u> sizes at 350 and 630 voltages.

#### **♦** Features

- ☐ Excellent Trigger Characteristics
- lue Low ESR & Low Tan  $\delta$
- Excellent DC Bias
- ☐ Provide Good Damping Characteristics Results in More Light.
- □ RoHS compliant

#### **♦** Applications

☐ Suitable for strobe trigger circuit in digital and electric cameras.

## **◆** Summary of Specification

Operation Temperature	-55~+125 ℃
Rated Voltage	350Vdc and 630Vdc
Temperature Coefficient	X7E : ≤ ± 4.7% , -55~+125 °C (EIA Class II )
Capacitance Range	1.0nF to 68nF
Dissipation Factor :	1.0% max. at 1KHz 25°C
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller (C in Farad)
Dielectric Strength	250V ≦ V < 500V : 200% Rated Voltage
	500V ≦ V < 1000V : 150% Rated Voltage
Capacitance Tolerance	± 5%, ± 10%, ± 20%
Aging	1.0% per decade hr, Typical

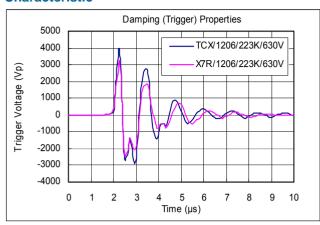
#### **♦** How To Order

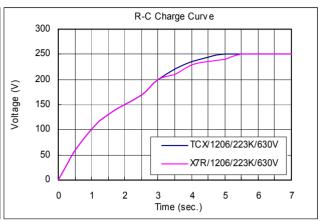
TCX	1206	С	223	К	631	Т
Product Code	Chip Size	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Packaging
TCX: Trigger Capacitor	Ex.: 0805 : 2.0×1.25 mm 1206 : 3.2×1.6 mm 1210 : 3.2×2.5 mm	C: X7E	Ex.: 102:10×10 <sup>2</sup> 473:47×10 <sup>3</sup>	Ex.: J: +/- 5% K: +/- 10% M: +/- 20%	Ex.: 351:350Vdc 631:630Vdc	T: Taping & Reel B: Bulk



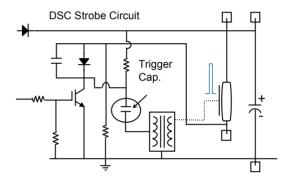


#### **♦** Characteristic

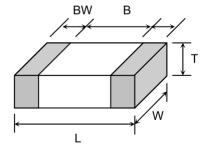




### ◆ **Application** Example Circuit



#### **♦ Dimension**



Unit	: mm	[inche	s]
------	------	--------	----

TYPE	L	W	T (max)	B (min)	BW (min)
0805	2.00±0.2	1.25±0.2	1.45	0.70	0.20
	[.079±.012]	[.049 ±.008]	[.057]	[.028]	[.008]
1206	3.20±0.3	1.60±0.2	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1210	3.20±0.3	2.50±0.2	1.80	1.60	0.30
	[.126±.012]	[.098±.008]	[.071]	[.063]	[.012]

## ◆ Capacitance Range

•										
Dielectric	C:	\/altana			Capacit	ance Rang	е			
Characteristic	Size	Voltage	102 122 152 182	272 332 392 472	562 682 822 103	123 153 183 223	273 333 393 473	563 683 823 104	154	
	0805	350V	CCCC			CCCDC	D			
1	1206 <b>-</b>	350V			(		CDEE			
X7E		630V		DE	DDDD	DEEE				
		350V				DDDDC	DDDD	DEE		
		630V					DDEE			
Symbol Code	S	0	Α	В	С	D	Е	F	G	Н
Thickness(mm)	0.3±0.0	3 0.5±0.05	0.6±0.1	0.85±0.1	1.0±0.1	1.25±0.15	1.6±0.2	2.0±0.2	2.4±0.2	2.8±0.2

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





				Thory otome	
TCX Series Sp	ecification 8	Test Condition			
Item	Spo	ecification	Test Condition		
Operation Temperature	-55 to +125℃				
Visual	No Abnormal E	Exterior Appearance	Visual Inspection		
Capacitance	Within The Spe	ecified Tolerance	Frequency	Voltage	
Dissipation Factor	Maximum 1.09	% (0.01)	1KHz±10%	1.0±0.2Vrms	
Insulation Resistance	10,000M $\Omega$ or smaller. (C in	500/C $\Omega$ whichever is Farad)	V≦500V, Rated Vol V> 500V, Applied 50 Charge Time : 60sec Current is limited to	00Vdc c.	
Dielectric Strength	No dielectric b breakdown	reakdown or mechanical	250V≦V<500V : 2 500V≦V<1000V: 1 for 1~5 sec. Current		
Temperature Capacitance Coefficient	Temperature F -55°C ~ +125		(C2-C1)/C1 $\times$ 100% C1:Capacitance at standard temperature(25°C C2:Capacitance at test temperature		
Adhesive Strength of Termination	No indication of terminal electron	of peeling shall occur on the ode.	A 5N·f ( $\approx$ 0.5Kg·f) pull force 5N·f shall be applied for 10±1 section 10±1 sectio		
Resistance to Flexure of Substrate	than the follow	I damage or change C more ing table. hange : $\leq \pm 12.5\%$ of initial value	mm/sec.	ent 1.0mm with a rate of 1.0  R230  Bending  Limit  Meter  45±1mm	
Solderability		of the terminal surface is to be y, so metal part does not come	Solder Temperature Dip Time: 5 ± 0.5 se Immersing Speed: 2 Solder: H63A Flux: Rosin Preheat: At 80~126	ec. 25±10% mm/s	
Resistance To Soldering Heat	Appearance Capacitance Tan δ (D.F.)	No mechanical damage shall occur  Cap. change within ±7.5% of initial value  To satisfy the specified initial value  To satisfy the specified initial	Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C  Dip Time : 10 ± 1sec.  Immersing Speed : 25±10% mm/s  Solder : H63A  Flux :Rosin  Measure at room temperature after cooli 48 ± 4 Hours		
	Resistance Dielectric Strength	value  To satisfy the specified initial value			





# TCX Series Specification & Test Condition

Item		Specification	Test Condition			
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at			
	Capacitance	Cap. change within ±7.5% of initial value	150 +0/-10 ℃ before initial measure.  Capacitor shall be subjected to five cycles of the temperature cycle as following:			
	Tan $\delta$ (D.F.)	To satisfy the specified initial value	Step Temp.(°C) Time(min)			
	Insulation	To satisfy the specified initial	1 Min Rated Temp.(-55)+0/-3 30			
	Resistance	value	2 25 3			
			3 Max Rated Temp.(+125)+3/-0 30			
			4 25 3			
			Measure at room temperature after cooling for 48 ±4 Hours			
Humidity	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measure.			
	Capacitance	Cap. change within ±12.5%of initial value	Temperature : 40± 2 °C Relative Humidity : 90 ~95%RH			
	Tan $\delta$ (D.F.)	Maximum 3.5% (0.035)	Test Time : 500 +12/-0 hr			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Measure at room temperature after cooling for $48 \pm 4$ Hours			
High Temperature Load	Appearance	No mechanical damage shall occur	Capacitors applied DC voltage of 120% the rated voltage is applied for one hour at			
(Life Test)	Capacitance	Cap. change within ±15% of initial value	maximum operation temperature±3°C then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage :120% of rated voltage			
	Tan $\delta$ (D.F.)	Maximum 3.5% (0.035)				
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is	Temperature : max. operation temperature (125°ℂ)			
	Resistance smaller. (C in Farad)		Test Time: 1000 +12/-0Hr Current Applied: current is limited to less tha 50mA.			
			Measure at room temperature after cooling for 48 $\pm$ 4 Hours			
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. board.			
	Capacitance	Within the specified tolerance	Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz			
	Tan $\delta$ (D.F.) To satisfy the specified initial value		from 10Hz to 55Hz and back to 10Hz in about 1 min.  repeat this for 2 hours each in 3 perpendicular directions.			





# Multilayer Ceramic Chip Capacitors [Low Distortion Capacitor]

# **LDC** Series



# **Low Distortion Capacitor (NPO/X7R Hybrid)**

### ◆ Features

- ☐ Small Size & High Capacitance
- ☐ Ultra Stable T/C for a Class II
- $\hfill \Box$  Excellent Bias,High Temperature Stability & Low Tan  $\,\delta$
- ☐ High Breakdown Voltage
- ☐ Replacement for Film Capacitors
- ☐ RoHS compliant

## **◆** Application

□ Suitable for Telecommunication (ADSL \ Modem...),Power (Inverter for oscillation Circuit) & Audio Circuit

## **♦ Summary of Specification**

Operation Temperature	-55~+125 ℃
Rated Voltage	25V and 50Vdc
Temperature Coefficient	X7E : ≤ ± 4.7% , -55~+125 °C (EIA Class II )
Capacitance Range	1nF ~ 270nF
Dissipation Factor :	For 50V : 1.2% max. at 1KHz 25℃
	For 25V : 2.0% max. at 1KHz 25℃
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller
Dielectric Strength	250% Rated Voltage for 5 second @ 50mA max. current
Capacitance Tolerance	± 5%, ± 10%, ± 20%
Aging	1.0% per decade hr , Typical

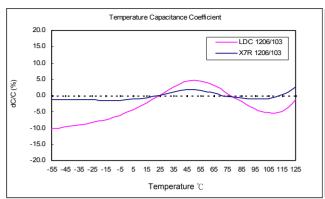
#### **♦** How To Order

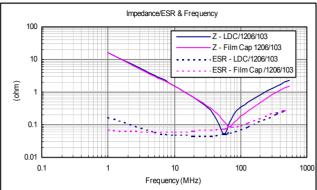
LDC	1206	С	103	K	025	T
Product Code LDC: Low Distortion Capacitor	Chip Size  Ex.: 0603: 1.6×0.80 mm 0805: 2.0×1.25 mm 1206: 3.2×1.60 mm 1210: 3.2×2.50 mm 1812: 4.6×3.20 mm 2220: 5.7×5.00 mm	Dielectric C: X7E	Capacitance Unit: pF Ex.: 102:10x10 <sup>2</sup> 224:22x10 <sup>4</sup>	Tolerance  Ex.: J:+/-5% K:+/-10% M:+/-20%	Rated Voltage  Ex.: 025:25Vdc 050:50Vdc	Packaging T: Taping & Reel B: Bulk



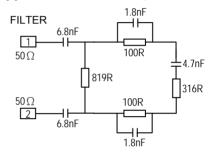


### **♦** Characteristic



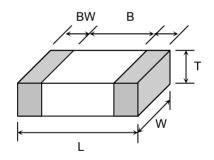


## ◆ Application Example Circuit



## **♦** Dimension

Unit: mm [inches]



TYPE	L	W	T (max)	B (min)	BW (min)
0603	1.60±0.1	0.80±0.1	0.90	0.40	0.15
	[.063±.004]	[.031 ±.004]	[.035]	[.016]	[.006]
0805	2.00±0.2	1.25±0.2	1.45	0.70	0.20
	[.079±.012]	[.049 ±.008]	[.057]	[.028]	[.008]
1206	3.20±0.3	1.60±0.2	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1210	3.20±0.3	2.50±0.2	1.80	1.60	0.30
	[.126±.012]	[.098±.008]	[.071]	[.063]	[.012]
1812	4.60±0.3	3.20±0.3	2.20	2.50	0.30
	[.181±.012]	[.126±.012]	[.087]	[.098]	[.012]
2220	5.70±0.4	5.00±0.4	2.20	3.50	0.30
	[.220±.016]	[.197±.016]	[.087]	[.137]	[.012]

### ◆ Capacitance Range

Dielectric Characteristic	Size	Rated Voltage	102	222 272 332 332		Pacitance I		583 683	104 154 224 224	2/4
	0603	50V	ВВВ	ВВВВ	ВВВВ	ВВ				
	0805	50V		C	CICICIC	CCCC	CC			
	1206	25V				CICICI	CICICICI	CICICICI	CC	
X7E		50V				CICICIO	CICICICI	CICICICI	CC	
	1210	50V						CC	CCCC	
	1812	50V						DD	DDDD	
	2220	50V								D
Symbol Code	S	0	Α	В	С	D	Е	F	G	Н
Thickness(mm)	0.3±0.03	0.5±0.05	0.6±0.1	0.85±0.1	1.0±0.1	1.25±0.15	1.6±0.2	2.0±0.2	2.4±0.2	2.8±0.2

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





# **LDC Series Specification & Test Condition**

	ecification a					
Item		Specificatio	n	Test Condition		
Operation Temperature	-55 to +125℃	,				
Visual	No Abnormal	Exterior Appear	rance	Visual Inspection		
Capacitance	Within The Sp	ecified Toleran	ce	Frequency Voltage		
Dissipation Factor	Rated Voltage	e 50V	25V	1KHz±10% 1.0±0.2Vrms		
	D.F. (max.)	1.2%	2.0%	Perform a heat temperature at 150±5℃ for 30min. then place at room temp. for 24±2hr.		
Insulation Resistance	10,000M $\Omega$ or (C in Farad)	500/C $\Omega$ which	never is smaller.	Applied Voltage : Rated Voltage Charge Time : 60sec. Current is limited to less than 50mA		
Dielectric Strength	No dielectric t breakdown	oreakdown or m	nechanical	250% of the rated voltage for 1 to 5 sec. Current is limited to less than 50mA.		
Temperature	Temperature I	Range Cap	. Change	(C2-C1)/C1 × 100%		
Capacitance Coefficient	-55°C∼ +12		± 4.7%	C1:Capacitance At Standard Temperature(25 C2:Capacitance At Test Temperature		
Adhesive Strength of Termination	No indication of terminal electron	of peeling shall ode.	occur on the	5N⋅f A 5N⋅f (≈ 0.5Kg⋅f) pull force shall be applied for 10±1 sec		
Resistance to Flexure of		al damage or ch following table	ange capacitance	The board shall be bend 1.0mm with a rate of 1.0 mm/sec.		
Substrate	Capacitance C	Change : $\leq \pm$ 12	2.5% of initial value	R230  Bending  Limit  45±1mm  Bending		
Solderability			al surface is to be t does not come	Solder Temperature : 245±5°C		
	out or dissolve		does not come	Dip Time: 5± 0.5 sec. Immersing Speed: 25±10% mm/s Solder: H63A Flux: Rosin		
	<del></del>		<b>—</b>	Preheat : At 80~120 °C For 10~30sec.		
Resistance To Soldering Heat	Appearance	No mechanic	al damage shall	Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C		
	Capacitance	Cap. change initial value	within ±7.5% of	Dip Time : 10 ± 1sec. Immersing Speed : 25±10% mm/s Solder : H63A		
	Tan $\delta$ (D.F.)	To satisfy the value	specified initial	Flux :Rosin  Measure at room temperature after cooling for 48 ± 4 Hours		
	Insulation Resistance	To satisfy the value	specified initial			
	Dielectric Strength	To satisfy the value	e specified initial	•		





# LDC Series Specification & Test Condition

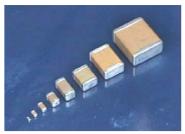
Item		Specification	Test Condition			
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour deage at 150 +0/-10 °C before initial measurement.			
	Capacitance	Cap. change within ±7.5% of initial value	Capacitor shall be subjected to five cycles of the temperature cycle as following:			
	Tan $\delta$ (D.F.)	To satisfy the specified initial value	Step         Temp.(°C)         Time(min)           1         Min Rated Temp.(-55)+0/-3         30			
	Insulation Resistance	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.(+125)+3/-0 30 4 25 3			
			Measure at room temperature after cooling for 48 ±4 Hours			
Humidity	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measure.			
	Capacitance	Cap. change within ±12.5% of initial value	Temperature : $40\pm 2~^{\circ}\text{C}$ Relative Humidity : $90~^{\circ}\text{SRH}$			
	Tan $\delta$ (D.F.)	50V 25V max. 3.5% max. 5.0%	Test Time : 500 +12/-0 hr			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Measure at room temperature after cooling for $48 \pm 4$ Hours			
Humidity Loading	Appearance	No mechanical damage shall occur	Capacitors applied DC voltage of the rated voltage is applied for one hour at maximum			
	Capacitance	Cap. change within ±12.5% of initial value	operation temperature±3℃ then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.			
	Tan $\delta$ (D.F.)	50V 25V max. 3.5% max. 5.0%	Applied Voltage :Rated Voltage Temperature : $40\pm2^{\circ}$ C Relative Humidity : $90 \sim 95\%$ RH Test Time : $500 + 12/-0$ Hr Current Applied : $50 \text{ mA Max}$ .			
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller. (C in Farad)				
			Measure at room temperature after cooling for 48 $\pm$ 4 Hours			
High Temperature Load (Life Test)	Appearance	No mechanical damage shall occur	Capacitors applied DC voltage of 200% the rated voltage is applied for one hour at maximum operation temperature±3°C then			
	Capacitance	Cap. change within ±15% of initial value	shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.			
	Tan $\delta$ (D.F.)	50V 25V max. 3.5% max. 5.0%	Applied Voltage :200% of Rated Voltage Temperature : max. operation temperature			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Test Time: 1000 +48/-0Hr Current Applied: 50 mA Max.			
			Measure at room temperature after cooling for 48 $\pm$ 4 Hours			





# Multilayer Ceramic Chip Capacitors [ Normal Chip Capacitor – NPO,X7R,X5R,Y5V ]

# **NCC** Series



Standard Multilayer Ceramic Chip Capacitors (MLCC's) are available in a full line of sizes and temperature coefficients, with voltage ratings from 6.3V to 50V.

#### Features

- □Surface mount suited for wave and reflow soldering
- ☐ Small size and high reliability
- ☐ Excellent in high frequency characteristic
- RoHS compliant

## Application

□Suitable for general electronics circuit, telecommunications, personal computers and peripheral, power circuit & mobile application...etc.

# Summary of Specification

### NPO Dielectric Characteristic

Operation Temperature : -55~+125 °C

Temperature Coefficient:  $\pm$  30ppm/°C , -55~+125 °C (EIA Class I)

0.5pF to 1nF Capacitance Range

Dissipation Factor: more than  $30pF: Q \ge 1000 (0.001)$ 

> 30pF& below: Q ≥ 400+20C C:pF  $10G\Omega$  or 500/C  $\Omega$  whichever is smaller

Insulation Resistance: 0 % per decade of time, typical

Aging:

Dielectric Strength: 250% Rated Voltage

## X7R Dielectric Characteristic

Operation Temperature : -55~+125 °C

Temperature Coefficient: ± 15%, -55~+125 °C (EIA Class II)

Capacitance Range 100pF to 680nF

Dissipation Factor: Please see HEC specification data sheet Insulation Resistance:  $10G\Omega$  or 500/C  $\Omega$  whichever is smaller

Aging: ≤ 2.5 % per decade hr, typical

Dielectric Strength: 250% Rated Voltage

#### X5R Dielectric Characteristic

Operation Temperature : -55~+85 °C

Temperature Coefficient: ± 15%, -55~+85 °C (EIA Class II)

Capacitance Range 3.3nF to 680nF

Dissipation Factor: Please see HEC specification data sheet Insulation Resistance:  $10G\Omega$  or  $500/C\Omega$  whichever is smaller

 $\leq$  2.5 % per decade hr, typical Aging:

Dielectric Strength: 250% Rated Voltage

#### Y5V Dielectric Characteristic

Operation Temperature : -30~+85 °C

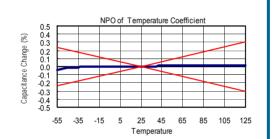
Temperature Coefficient: +22/ -82 %, -30~+85 °C (EIA Class II)

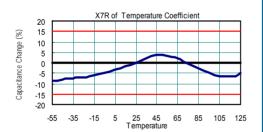
Capacitance Range 1nF to 470nF

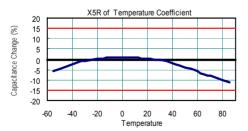
Please see HEC specification data sheet Dissipation Factor: Insulation Resistance:  $10G\Omega$  or 500/C  $\Omega$  whichever is smaller

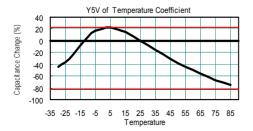
Aging: ≤ 7.0 % per decade hr, typical

Dielectric Strength: 250% Rated Voltage







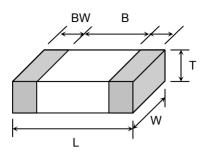






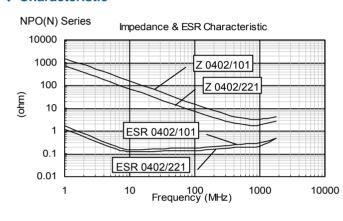
Unit: mm [inches]

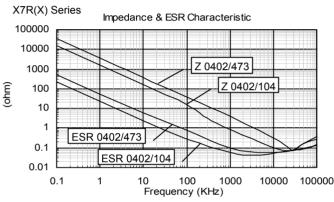
#### Dimension

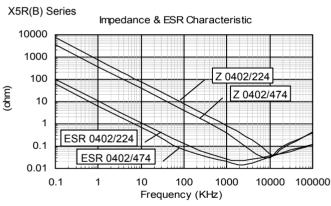


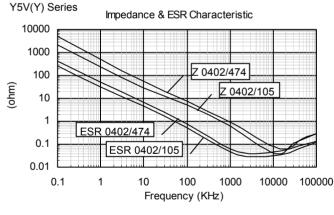
TYPE	L	W	T (max)	B (min)	BW (min)
0201	0.60±0.03	0.30±0.03	0.33	0.20	0.10
	[.024±.001]	[.011 ±.001]	[.013]	[.008]	[.004]
0402	1.00±0.05	0.50±0.05	0.55	0.30	0.15
	[.039±.002]	[.020 ±.002]	[.022]	[.012]	[.006]
0603	1.60±0.10	0.80±0.10	0.90	0.40	0.15
	[.063±.004]	[.031 ±.004]	[.035]	[.016]	[.006]
0805	2.00±0.20	1.25±0.20	1.45	0.70	0.20
	[.079±.012]	[.049 ±.008]	[.057]	[.028]	[.008]
1206	3.20±0.30	1.60±0.20	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]

#### **♦** Characteristic









#### ♦ How To Order

0402 104 010 M Τ **Product Code Chip Size** Capacitance Dielectric **Tolerance** Rated Voltage Packaging Unit: pF C: MLCC 007: 6.3Vdc T: Taping & Reel Ex.: (Multilayer 0201: N: NPO 102:10×10<sup>2</sup> C:+/- 0.25pF 010: 10Vdc B: Bulk Ceramic 0.6×0.30 mm X: X7R 473:47×103 D:+/- 0.50pF 016: 16Vdc 104:10×104 Chip of 0402: B:X5R F: +/- 1% 025: 25Vdc Y:Y5V G: +/- 2% 050: 50Vdc Capacitor) 1.0×0.50 mm 0603: J: +/- 5% 1.6×0.80 mm K: +/- 10% 0805: M:+/- 20% Z:+80/-20% 2.0×1.25 mm 1206: 3.2×1.60 mm





### **◆** Capacitance Range

Capacitan	ICE IV	ange	
Dielectric	Size	Rated	Capacitance Range (pF)
Characteristic	5.20	Voltage	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0
	0201	16V	
	25V		
NPO	NPO 0402	50V	
	0603	50V	BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
	0805	50V	BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
Dielectric	Size	Rated	Capacitance Range (pF)
Characteristic	SIZE	Voltage	1101 1121 1121 1121 1122 1122 1122 1123 123
		6.3V	S
	0201	16V	SISISISIS
		25V	SSSSSSSSSSSSSSSSSSSSSSSSSSSSSSSSSSSSSSS
		10V	
	0402	16V	00000000
	0402	25V	0000
		50V	
		16V	BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
X7R	0603	25V	BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
		50V	BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
		16V	BBB BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
	0805	25V	BBB BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
	0000	35V	BBB BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
		50V	BBB BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB
		16V	BBBBB
	1206	25V	BBBEEE
		50V	BBBCDD
Dielectric	CiTO	Rated	Capacitance Range (pF)
Characteristic Size		Voltage	3332 3472 3872 3872 3773 3773 3773 3773 3773 37
2004		6.3V	SSSS
0201 X5R 0402	0201	10V	SSSSS
		6.3V	0000
	0402	10V	0000000
		16V	0000000
	0603	10V	BB
	0003	16V	BBBBB
Symbol Code		S	O A B C D E F G H
Thickness(mn	n) 0.3	8±0.03 0	.5±0.05   0.6±0.1   0.85±0.1   1.0±0.1   1.25±0.15   1.6±0.2   2.0±0.2   2.4±0.2   2.8±0.2

<sup>■</sup> Other dimensions, capacitance values and voltages rating are available. Please contact HEC.



Dielectric	0:	Rated		citance	
Characteristic	Size	Voltage	102 222 472	103 223 473	104 224 474 105
	0201	6.3V			S
		10V			00
	0402	16V		00	0
	0402	25V	000	00	0
		50V	000	0	
		16V			ВВВ
Y5V	0603	25V			ввв
150		50V		ввв	В
		16V			ввв
	0805	25V			ВВВ
		50V			ввв
		16V		ввв	ВВВ
	1206	25V		ввв	ВВВ
		50V		ввв	ввв
Symbol Code		S	0	Α	
Thickness(mn	n) 0.3	3±0.03	0.5±0.05	0.6±0	.1 0.85

• Other dimensions, capacitance values and voltages rating are available. Please contact HEC.



NCC Series Specification & Test Condition
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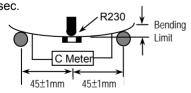
Item	Specification		Test Condition		
Operation Temperature	Char.         Operation Tem           NPO(N)         -55°C ~ +125°C           X7R (X)         -55°C ~ +125°C           X5R (B)         -55°C ~ +85°C           Y5V (Y)         -30°C ~ +85°C				
Visual	No abnormal exterior appearance	е	Visual Inspection	n	
Capacitance	Within The Specified Tolerance		Char.	Frequency	Voltage
Quality Factor	Class I (NPO): More Than 30pF : Q $\geq$ 1000 30pF & Below: Q $\geq$ 400+20C (	C:Cap., pF)	C≤100pF C>100pF	1MHz±10% 1KHz±10%	1.0±0.2Vrms
Dissipation Factor	Class II (X7R/X5R/Y5V): Shall meet the value in Table 1	Tble 2	X7R/X5R/Y5V Perform a heat to 30min. then place	1KHz±10% temperature at 15 te at room temp.	
Insulation Resistance	10,000M $\Omega$ or 500/C $\Omega$ whichev for rated voltage>10V and greate for rated voltage≤10V.		Charge Time: 6	: Rated Voltage 60±5 sec. ge current shall l	
Withstanding Voltage	No dielectric breakdown or mech breakdown	nanical		ed voltage for 1~ d to less than 50	
Temperature Capacitance Coefficient	Char.       Temp. Range         NPO(N)       -55°C ~ +125°C         X7R (X)       -55°C ~ +125°C         X5R (B)       -55°C ~ +85°C         Y5V (Y)       -30°C ~ +85°C	Class II: (C2-C1)/C1 > T1:Standard Tel T2:Test Temper C1:Capacitance	mperature(20°ℂ)		
Adhesive Strength of Termination	No indication of peeling shall occ terminal electrode.	cur on the	5N		Kg·f) pull force ied for 10±1 sec

# Resistance to Flexure of Substrate

No mechanical damage or capacitance change more than the following table.

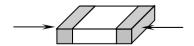
Char.	Capacitance Change
NPO(N)	$\leq$ ± 5.0% of initial value
X7R (X)	$\leq$ ± 12.5% of initial value
X5R (B)	$\leq$ ± 12.5% of initial value
Y5V (Y)	$\leq$ ± 30.0% of initial value

The board shall be bend 1.0mm with a rate of 1.0 mm/sec.



#### Solderability

More than 90% of the terminal surface is to be soldered newly, so metal part does not come out or dissolve .



Solder Temperature : 245±5°C

Dip Time :  $5 \pm 0.5$  sec.

Immersing Speed : 25 $\pm$ 10% mm/s

Solder : H63A Flux :Rosin

Preheat : At 80~120 ℃ For 10~30sec.





# NCC Series Specification & Test Condition

Item		Specification	Test Condition		
Resistance to Soldering Heat	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48± 4 hours at room temperature after one hour heat treatment at 150 +0/-10°C before initial measure.		
	Capacitance	Class I (NPO): Within 2.5% or $\pm$ 0.25pF whichever is larger of initial value Class II: Char. Cap. change $ \begin{array}{c c} X7R(X) & \leq \pm 7.5\% \text{ of initial value} \\ \hline X5R(B) & \leq \pm 20\% \text{ of initial value} \\ \hline \end{array} $	Preheat : at $150\pm10^{\circ}\text{C}$ for $60\sim120\text{sec}$ . Dip : solder temperature of $260\pm5^{\circ}\text{C}$ Dip Time : $10\pm1\text{sec}$ . Immersing Speed : $25\pm10\%$ mm/s Solder : H63A Flux : Rosin  Measure at room temperature after cooling for Class I : $24\pm2$ Hours Class II : $48\pm4$ Hours		
	Q / Tan δ	To satisfy the specified initial value			
	Insulation Resistance	To satisfy the specified initial value			
Temperature Cycle	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat		
	Capacitance	Class I (NPO): Within 2.5% or ±0.25pF whichever is larger of initial value Class II:	the temperature cycle as following:		
		Char. Cap. change $\times 7.5\%$ of initial value	Step Temp.(°C) Time(min)		
		$X5R(B)$ $\leq \pm 7.5\%$ of initial value	1 Min Rated Temp.+0/-3 30 2 25 3		
		Y5V(Y) $\leq \pm 20\%$ of initial value	3 Max Rated Temp.+3/-0 30		
	Q / Tan δ	To satisfy the specified initial value	4 25 3  Measure at room temperature after cooling for		
	Insulation Resistance	To satisfy the specified initial value	Class I : 24 ± 2 Hours Class II : 48 ± 4 Hours		
Humidity	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measure.		
	Capacitance	Class I (NPO): Within 5.0% or $\pm 0.5$ pF whichever is larger of initial value Class II: Char. Cap. change	Temperature : 40 $\pm$ 2 $^{\circ}$ C Relative Humidity : 90 ~95%RH Test Time : 500 +12/-0 hr		
	Q Class I	30pF & Over : Q ≥350 10 to 30pF : Q≥275+2.5C 30pF & Below: Q≥200+10C			
	Tan δ Class ∐	Shall meet the value in Table 1, Table 2			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)			





# NCC Series Specification & Test Condition

Item		Specification	Test Condition	
Humidity Loading	Appearance	No mechanical damage shall occur	Class II capacitors applied DC voltage of the rated voltage is applied for one hour at	
	Capacitance	Class I (NPO):  Within 7.5% or $\pm$ 0.75pF whichever is larger of initial value  Class II:  Char. Cap. change $ \begin{array}{ll} X7R(X) & \leq \pm 12.5\% \text{ of initial value} \\ X5R(B) & \leq \pm 12.5\% \text{ of initial value} \\ \hline Y5V(Y) & \leq \pm 30\% \text{ of initial value} \end{array} $		
	Q Class I Tan $\delta$ Class II	30pF & Over : Q ≥350 10 to 30pF : Q≥275+2.5C 30pF & Below: Q≥200+10C Shall meet the value in Table 1, Table 2	Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours	
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller for rated voltage>10V and greater 5/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)		
High Temperature Load	Appearance	No mechanical damage shall occur	Class II capacitors applied DC testing voltages is applied for one hour at maximum operation	
(Life Test)	Capacitance	Class I (NPO): Within 5.0% or $\pm$ 0.5pF whichever is larger of initial value Class II: Char. Cap. change $\frac{X7R(X)}{X5R(B)} \stackrel{\leq \pm 12.5\% \text{ of initial value}}{\leq \pm 30\% \text{ of initial value}}$	temperature ±3°C then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage :200%Rated Voltage However: 0201/X5R/104/6.3V and 0402/X5R/474,684/6.3V,10V ,applied voltage of 100%rated voltage Temperature: max. operation temperature	
	Q Class I	30pF & Over : Q ≥350 10 to 30pF : Q≥275+2.5C 30pF & Below: Q≥200+10C	Test Time: 1000 +48/-0Hr Current Applied: 50 mA Max.  Measure at room temperature after cooling for	
	Tan $\delta$ Class ${ m II}$	Shall meet the value in Table 1, Table 2	Class I : 24 ± 2 Hours Class II : 48 ± 4 Hours	
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)		
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. board.	
	Capacitance	Within the specified tolerance	Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz	
	Q / Tan δ	To satisfy the specified initial value	in about 1 min.  Repeat this for 2 hours each in 3 perpendicular directions.	





# **NCC Series Specification & Test Condition**

X7R(X)/X5R(B) Table 1

Size	Rated voltage	Capacitance Range	$ an \delta$ (D.F.)	
			Initial Vibration Resistance to solder heat Temperature cycle	Humidity Humidity loading High temperature loading
0201	DC 6.3V	C≦0.01uF	5.0 %	7.5 %
		C=0.1uF	15.0 %	25.0 %
	DC 10V	C≦0.01uF	5.0 %	7.5 %
	DC 16V	C≦2.2nF	2.5 %	5.0 %
		2.2nF <c≦3.3nf< td=""><td>5.0 %</td><td>7.5 %</td></c≦3.3nf<>	5.0 %	7.5 %
	DC 25V	C≦2.2nF	2.5 %	5.0 %
	DC 6.3V	C≦0.22uF	10.0 %	15.0 %
	DC 0.3V	C≦0.68uF	15.0 %	25.0 %
0402	DC 10V	C≦0.1uF	5.0 %	7.5 %
		C≦0.47uF	15.0 %	25.0 %
	DC 16V	C≦0.22uF	2.5 %	5.0 %
	DC 25V	C≦0.01uF	2.5 %	5.0 %
	DC 50V	C≦3.9nF	2.5 %	5.0 %
0603	DC 6.3V	All Capacitance	5.0 %	7.5 %
	DC 10V	All Capacitance	5.0 %	7.5 %
	DC 16V	C≦0.1uF	2.5 %	5.0 %
		C≦1uF	5.0 %	7.5 %
	DC 25V	All Capacitance	3.5 %	7.0 %
	DC 50V		2.5 %	5.0 %
0805	DC 16V	C≦0.47uF	2.5 %	5.0 %
		C≦1uF	5.0 %	7.5 %
	DC 25V	C≦0.47uF	2.5 %	5.0 %
	DC 50V	All Capacitance	2.5 %	5.0 %
1206	DC 16V	All Capacitance	2.5 %	5.0 %
	DC 25V		2.5 %	5.0 %
	DC 50V		2.5 %	5.0 %

#### Y5V(Y) Table 2

Yov(Y) Table 2.								
Size	Rated voltage	Capacitance Range	$ an \delta$ (D.F.)					
			Initial	Humidity				
			Vibration	Humidity loading				
			Resistance to solder heat	High temperature loading				
			Temperature cycle					
0201	DC 6.3V	All Capacitance	20.0 %	30.0 %				
0402	DC 10V	All Capacitance	12.5 %	15.0 %				
	DC 16V		9.0 %	11.0 %				
	DC 25V		5.0 %	7.5 %				
	DC 50V		5.0 %	7.5 %				
0603	DC 16V	All Capacitance	7.0 %	10.5 %				
	DC 25V		7.0 %	10.5 %				
	DC 50V		5.0 %	7.5 %				
0805	DC 16V	All Capacitance	7.0 %	10.5 %				
	DC 25V		7.0 %	10.5 %				
	DC 50V		5.0 %	7.5 %				
1206	DC 16V	All Capacitance	7.0 %	10.5 %				
	DC 25V		7.0 %	10.5 %				
	DC 50V		5.0 %	7.5 %				





# Multilayer Ceramic Chip Capacitors [ High Capacitance MLCC-X7R,X6S,X5R,Y5V ]

# **HCC** Series



#### Features.

- □ Surface mount suited for wave and reflow soldering
- ☐ High reliability and no polarity
- ☐ Small size and high capacitance value
- ☐ Excellent in high frequency characteristic
- □ RoHS compliant

### Application

- ☐ Ideal for smoothing and decoupling circuits
- ☐ Suitable for DC-DC converter, personal computer and peripherals, telecommunication and general electronic equipment

#### Summary of Specification

#### X7R Dielectric Characteristic

Operation Temperature : -55~+125 °C

Temperature Coefficient :  $\pm 15\%$  under -55~+125 °C (EIA Class II )

Capacitance Range 1.0uF to 10uF

Dissipation Factor : Please see HEC specification data sheet Insulation Resistance :  $10G\Omega$  or  $500/C\Omega$  whichever is smaller

Aging:  $\leq 2.5 \%$  per decade hr, typical

Dielectric Strength: 250% Rated Voltage

#### X6S Dielectric Characteristic

Operation Temperature : -55~+105 °C

Temperature Coefficient :  $\pm 22\%$  under -55~+105 °C (EIA Class II )

Capacitance Range 1.0uF to 22uF

Dissipation Factor : Please see HEC specification data sheet Insulation Resistance :  $10G\,\Omega$  or  $500/C\,\Omega$  whichever is smaller

Aging :  $\leq 2.5 \%$  per decade hr, typical

Dielectric Strength: 250% Rated Voltage

#### X5R Dielectric Characteristic

Operation Temperature : -55~+85  $^{\circ}$ C

Temperature Coefficient :  $\pm$  15% under -55~+85  $^{\circ}$ C (EIA Class  ${\rm II}$  )

Capacitance Range 1.0uF to 100uF

 $\begin{array}{ll} \mbox{Dissipation Factor}: & \mbox{Please see HEC specification data sheet} \\ \mbox{Insulation Resistance}: & \mbox{10G}\,\Omega \mbox{ or 500/C}\,\Omega \mbox{ whichever is smaller} \\ \mbox{10G}\,\Omega \mbox{$ 

Aging:  $\leq 2.5 \%$  per decade hr, typical

Dielectric Strength: 250% Rated Voltage

#### Y5V Dielectric Characteristic

Operation Temperature : -30~+85 °C

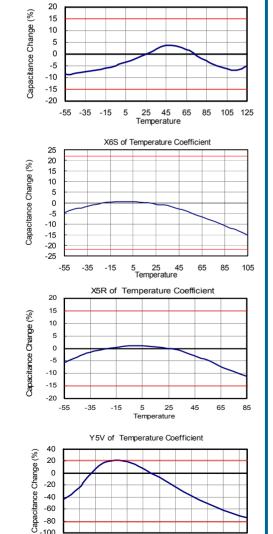
Temperature Coefficient : +22/-82%, -30~+85% (EIA Class  ${\rm II}$ )

Capacitance Range 1.0uF to 47uF

Dissipation Factor : Please see HEC specification data sheet. Insulation Resistance :  $10G\,\Omega$  or  $500/C\,\Omega$  whichever is smaller

Aging:  $\leq 7.0 \%$  per decade hr, typical

Dielectric Strength: 250% Rated Voltage



10 20 30 40

X7R of Temperature Coefficient

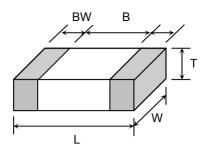




Unit: mm [inches]

100000

### Dimension



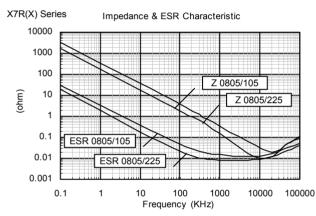
TYPE	L	W	T (max)	B (min)	BW (min)
0402	1.00±0.05	0.50±0.05	0.55	0.30	0.15
	[.039±.002]	[.020 ±.002]	[.022]	[.012]	[.006]
0603	1.60±0.10	0.80±0.10	0.90	0.40	0.15
	[.063±.004]	[.031 ±.004]	[.035]	[.016]	[.006]
0805	2.00±0.20	1.25±0.20	1.45	0.70	0.20
	[.079±.012]	[.049 ±.008]	[.057]	[.028]	[.008]
1206	3.20±0.30	1.60±0.20	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1210	3.20±0.30	2.50±0.20	2.60	1.60	0.30
	[.126±.012]	[.098±.008]	[.102]	[.063]	[.012]
1812	4.60±0.3	3.20±0.3	3.00	2.50	0.30
	[.181±.012]	[.126±.012]	[.118]	[.098]	[.012]
2220	5.7±0.40	5.00±0.40	3.00	3.50	0.30
	[.220±.016]	[.197±.016]	[.118]	[.137]	[.012]

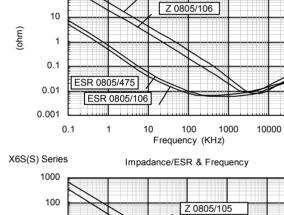
X5R(B) Series

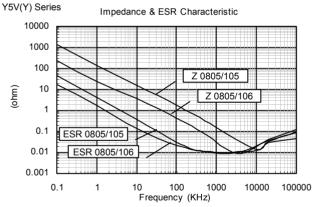
1000

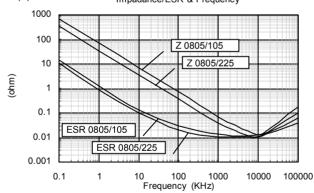
100

#### **♦** Characteristic









Impedance & ESR Characteristic

Z 0805/475

### **♦** How To Order

0805 106 010 **Product Code Chip Size** Dielectric Capacitance **Tolerance Rated Voltage** Packaging Unit: pF C: MLCC 0402: Ex.: Ex.: T: Taping 105:10×10<sup>5</sup> J:+/-5% 004: 4Vdc & Reel (Multilayer 1.0×0.50 mm X:X7R Ceramic S:X6S 106:10×106 K: +/- 10% 007: 6.3Vdc B: Bulk 0603: Chip of 1.6×0.80 mm B:X5R 226:22×106 M:+/- 20% 010: 10Vdc Capacitor) 0805: Y:Y5V Z:+80/-20% 016: 16Vdc 2.0×1.25 mm 025: 25Vdc 1206: 035: 35Vdc 050: 50Vdc 3.2×1.6 mm 1210: 3.2×2.5 mm



### ◆ Capacitance Range

Capa	JOIL	arro	C IXC	ıııg.																				
X7R (X	) Ser	ies																						
Size		0603				05				1206				12	10		1812	2220						
Code		10V	16V	6.3V	10V	16V	25V	10V	16V	25V	35V	50V	10V	16V	25V	35V	35V	35V						
105	В	В	В		D	D	D		Е	Е	E	Е		Е	Е	Е	F	F						
155																	F	F						
225 335	В	В	В	D	D	D		E	E	Ε				Е	E/F	F	F	Ę						
475				D D	D D			E	틑					Е	F	F		F						
685									_						Ė	•								
106								E					Е	Е	F	G		G						
X6S (S	) Ser	ies																						
	0402		603		0805			12	206			12	10		ľ									
Code				10V	16V		16V	25V		50\/	10V			50V										
105	В	101	В	101	101	D	101	201	E		101	101	201	F										
225				D	D	D							F											
475					D	D	Е	Е				F	F											
106		В		D			E	Е			F		G											
226 476											G	G	G											
X5R (E	) Cor	ioo																						Ī
Size		102			0603			1		0805			ı		10	206					1210			
Code			4V	6.3V			05)/	4V	0.01			05) (	6.3V	40) (			35V	50V	0.01/				35V	ł
105		0	40	6.3V	B	B		4٧	6.3V		D	25V	6.3V	100	E		E		0.3V	100	167	25V	F	ŀ
155	U	U		D	D	Б	D			U	U	U		Ε			<u> </u>						Г	l
225	0			В	В	В			D	D	D	D		Ē	Е	Е					Е	E/F	F	l
335									D	D	D	D		Е	E	E								l
475				В	В				D	D		D	E	E	E	E				F	F		F	l
106 226	-		B	В				D	D D	D	D		E	E	E	Е			G	F G	F G	GC	O	l
476								U	U				눝	퉅					G	G	G	G		l
107														_					G					ĺ
Y5V (\	′) Sei	ries																						
Size		02		06	603				0805					1206					12	10			18	12
Code	6.3V	10V	6.3	10V	16V	25V	6.3V	10V	16V	25V	50V	10V	16V	25V	35V	50V	6.3V	10V	16V	25V	35V	50V	35V	50V
105		0		В	В	В			В	В			В	D	D	D								
225			В	В	В			D	D	D			В	D	D									
475			В	В			D	D	D				D	D							F			F
106 226							D D	D	D			D		D/E				F	πШ	Ę	F	F	미파	F
476							ט					D	Е				F	F	F	F			F	H
107																	G							
Sym	ool Co	ode	T	S	T	0	Т	A	Т	В	T	С	T	D	Т	E	T	F	T	G	T	Н	ΤĬ	
Thickr			0.3	±0.03	0.5	±0.05	5 0.0	6±0.1	0.8	85±0.	.1 1	.0±0.	1 1.:	25±0	15	1.6±0	0.2	2.0±0	.2	2.4±	0.2	2.8±	0.2	

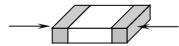
■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.



# **HCC Series Specification & Test Condition**

Item	Specification	Test Condition				
Operation Temperature	Char.         Operation Temp.           X7R (X)         -55°C ~ +125°C           X6S (S)         -55°C ~ +105°C           X5R (B)         -55°C ~ +85°C           Y5V (Y)         -30°C ~ +85°C					
Visual	No abnormal exterior appearance	Visual Inspection				
Capacitance	Within the specified tolerance	Capacitance Frequency Voltage				
Dissipation Factor	Please see HEC specification data sheet details	for $C \le 10 \text{uF}$ 1KHz±10% 1.0±0.2Vrms C>10uF 120Hz±20% 0.5±0.2Vrms				
		Perform a heat temperature at 150±5°C for 30min. then place at room temp. for 24±2hr.				
Insulation Resistance	$\begin{array}{ll} \text{10,000M}\Omega \text{ or 500/C}\Omega \text{ whichever is smaller} \\ \text{for rated voltage>10V and greater 100/C}\Omega \\ \text{for rated voltage} \leq \text{10V}. \\ \end{array} \begin{array}{ll} \text{Applied Voltage}: \text{Rated Voltage} \\ \text{Charge Time}: 60\pm5 \text{ sec.} \\ \text{Charge-Discharge current shall be} \\ \text{50mA current.} \end{array}$					
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	250% of the rated voltage for 1~5 sec. Current is limited to less than 50mA				
Temperature Capacitance Coefficient	Char.         Temp. Range         Cap. Char.           X7R (X) $-55^{\circ}$ C ~ +125 °C $\pm$ 15%           X6S (S) $-55^{\circ}$ C ~ +105 °C $\pm$ 22%           X5R (B) $-55^{\circ}$ C ~ +85 °C $\pm$ 15%           Y5V (Y) $-30^{\circ}$ C ~ +85 °C         +22/-82	C1:Capacitance At Standard Temperature (20°C) C2:Capacitance At Test Temperature				
Adhesive Strength of Termination	th No indication of peeling shall occur on the terminal electrode.  A 5N⋅f (≈ 0.5K) shall be applie					
Resistance to Flexure of Substrate	No mechanical damage or capacitance of more than the following table.  Char. Capacitance Change $\times$ X7R(X) $\leq \pm 12.5\%$ of initial value $\times$ X6S(S) $\leq \pm 12.5\%$ of initial value $\times$ X5R(B) $\leq \pm 12.5\%$ of initial value $\times$ Y5V(Y) $\leq \pm 30.0\%$ of initial value $\times$ X5R(B) $\leq \pm 30.0\%$ of initial value $\times$ Y5V(Y)	1.0 mm/sec.  R230  Bending  Limit  C Meter  45±1mm  Bending  Limit				
Solderability	More than 90% of the terminal surface is	•				

More than 90% of the terminal surface is to be soldered newly, so metal part does not come out or dissolve.



Dip Time :  $5 \pm 0.5$  sec.

Immersing Speed : 25±10% mm/s

Solder : H63A Flux :Rosin

Preheat : At 80~120 °C For 10~30sec.





# **HCC Series Specification & Test Condition**

Item	Spec	ification	Test Condition			
Resistance to Soldering Heat	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48± 4 hours at room temperature after one hour heat treatment			
	Capacitance	$ \begin{array}{ll} \mbox{Char.} & \mbox{Cap. change} \\ \mbox{X7R(X)} & \leq \pm 7.5\% \mbox{ of initial value} \\ \mbox{X6S(S)} & \leq \pm 7.5\% \mbox{ of initial value} \\ \mbox{X5R(B)} & \leq \pm 7.5\% \mbox{ of initial value} \\ \mbox{Y5V(Y)} & \leq \pm 20\% \mbox{ of initial value} \\ \end{array} $	at 150 +0/-10°C before initial measure.  Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C  Dip Time : 10 ± 1sec.  Immersing Speed : 25±10% mm/s			
	$Tan\delta$	To satisfy the specified initial value	Solder : H63A Flux : Rosin			
_	Insulation Resistance	To satisfy the specified initial value	Measure at room temperature after cooling for 48 ± 4 Hours			
Temperature Cycle	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat			
	Capacitance	$\begin{tabular}{lll} Char. & Cap. change \\ \hline X7R(X) & $\leq \pm 7.5\%$ of initial value \\ \hline X6S(S) & $\leq \pm 7.5\%$ of initial value \\ \hline X5R(B) & $\leq \pm 7.5\%$ of initial value \\ \hline Y5V(Y) & $\leq \pm 20\%$ of initial value \\ \hline \end{tabular}$	treatment at 150 +0/-10 °C befor initial measure.  Capacitor shall be subjected to five cycles of the temperature cycle as following:  Step Temp.(°C) Time(min)  1 Min Rated Temp.+0/-3 30			
	Tan $\delta$	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.+3/-0 30			
	Insulation Resistance	To satisfy the specified initial value	4 25 3  Measure at room temperature after cooling for 48 ± 4 Hours			
Humidity	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment			
	Capacitance		at 150 +0/-10 ℃ before initial measure.  Temperature : 40± 2 ℃  Relative Humidity : 90 ~95%RH  Test Time : 500 +12/-0 hr  Measure at room temperature after cooling for			
	Tan $\delta$	Please see HEC specification data sheet for details	48 ± 4 Hours			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)				





# **HCC Series Specification & Test Condition**

Item	Spec	ification	Test Condition			
Humidity Loading	Appearance	No mechanical damage shall occur	Class II capacitors applied DC voltage of the rated voltage is applied for one hour at maximum			
	Capacitance	$ \begin{array}{ll} \hline \text{Char.} & \text{Cap. change} \\ \hline \textbf{X7R(X)} & \leq \pm 12.5\% \text{ of initial value} \\ \hline \textbf{X6S(S)} & \leq \pm 12.5\% \text{ of initial value} \\ \hline \textbf{X5R(B)} & \leq \pm 12.5\% \text{ of initial value} \\ \hline \textbf{Y5V(Y)} & \leq \pm 30\% \text{ of initial value} \\ \hline \end{array} $	operation temperature $\pm 3^{\circ}\mathbb{C}$ then shall be set for 48 $\pm 4$ hours at room temperature and the initial measurement shall be conducted. Applied Voltage :Rated Voltage Temperature : $40\pm 2^{\circ}\mathbb{C}$			
	Tan $\delta$	Please see HEC specification data sheet for details	Relative Humidity: 90 ~95%RH Test Time: 500 +12/-0Hr Current Applied: 50 mA Max.			
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller for rated voltage>10V and greater 5/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)	Measure at room temperature after cooling for 48 $\pm$ 4 Hours			
High Temperature Load	Appearance	No mechanical damage shall occur	Class  ☐ capacitors applied DC testing voltage applied for one hour at maximum operation			
(Life Test)	Capacitance	$ \begin{array}{ll} \hbox{Char.} & \hbox{Cap. change} \\ \hline \hbox{X7R(X)} & \leq \pm 12.5\% \ \hbox{of initial value} \\ \hline \hbox{X6S(S)} & \leq \pm 12.5\% \ \hbox{of initial value} \\ \hline \hline \hbox{X5R(B)} & \leq \pm 12.5\% \ \hbox{of initial value} \\ \hline \hbox{Y5V(Y)} & \leq \pm 30\% \ \hbox{of initial value} \\ \hline \end{array} $	temperature ±3°C then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage :150%Rated Voltage However: The rated voltage is 4V/6.3V/10V, applied			
	Tan $\delta$	Please see HEC specification data sheet for details	voltage of 100% rated voltage. Temperature: max. operation temperature Test Time: 1000 +48/-0Hr			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)	Current Applied : 50 mA Max.  Measure at room temperature after cooling for 48 ± 4 Hours			
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. board.			
	Capacitance	Within the specified tolerance	Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz			
	Tan $\delta$	To satisfy the specified initial value	in about 1 min.  Repeat this for 2 hours each in 3 perpendicular directions.			





# Multilayer Ceramic Chip Capacitors [ Low Profile Capacitor – Thin Type X7R,X5R,Y5V ]

# **VAC** Series



### Low profile high capacitance MLCC's ideally suited for height restricted needs

#### **♦** Features

- ☐ High capacitance & rated voltage with maximum height of 0.5mm(size 0603) & 0.95 mm
- ☐ Surface mount suited for Wave and Reflow soldering
- RoHS compliant

## Application

- ☐ For small and height restricted electronic equipment and applications
- ☐ Suitable for FPD device, HDD, CD-RW, LCD device, cellular phone modules and portable devices...etc.

## Summary of Specification

### X7R Dielectric Characteristic

Operation Temperature : -55~+125 ℃

Temperature Coefficient: ± 15%, -55~+85 °C (EIA Class II)

Capacitance Range 1uF to 2.2uF Dissipation Factor: See Spec.

Insulation Resistance :  $10G\Omega$  or 500/C  $\Omega$  whichever is smaller

Aging :  $\leq 2.5 \%$  per decade hr , typical

Dielectric Strength: 250% Rated Voltage

#### X5R Dielectric Characteristic

Operation Temperature: -55~+85 °C

Temperature Coefficient :  $\pm$  15% , -55~+85  $^{\circ}$ C (EIA Class  ${\rm II}$  )

Capacitance Range 1uF to 22uF Dissipation Factor: See Spec.

Insulation Resistance :  $10G \Omega$  or  $500/C \Omega$  whichever is smaller

Aging :  $\leq 2.5 \%$  per decade hr , typical

Dielectric Strength: 250% Rated Voltage

#### Y5V Dielectric Characteristic

Operation Temperature : -30~+85 °C

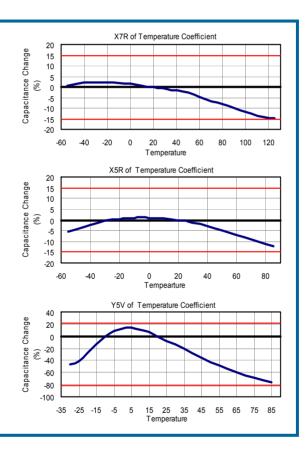
Temperature Coefficient: +22/-82 %, -30~+85 °C (EIA Class II)

Capacitance Range 1uF to 10uF Dissipation Factor: See Spec.

Insulation Resistance :  $10G \Omega$  or  $500/C \Omega$  whichever is smaller

Aging:  $\leq 7.0 \%$  per decade hr, typical

Dielectric Strength: 250% Rated Voltage

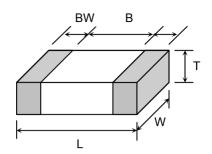


### How To Order

VAC	1206	В	106	K	007	<u> </u>
Product Code VAC:	Chip Size	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Packaging
Low Profile capacitor (Thin Type)	0603: 1.6x0.80 mm 0805: 2.0x1.25 mm 1206: 3.2x1.60 mm	Ex.: X:X7R B:X5R Y:Y5V	Ex.: 475:47×10 <sup>5</sup> 106:10×10 <sup>6</sup>	Ex.: K: +/- 10% M:+/- 20% Z :+80/-20%	Ex.: 007: 6.3Vdc 010: 10Vdc 016: 16Vdc 025: 25Vdc	T: Taping & Reel B: Bulk

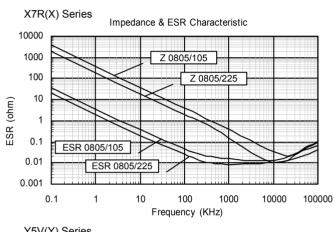


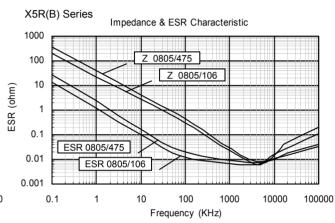
### **◆ Dimension**

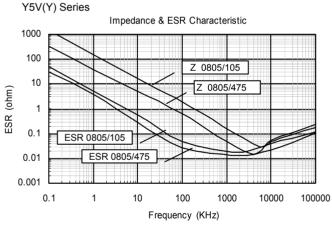


				Unit	: mm [inches]
TYPE	L	W	T (max)	B (min)	BW (min)
0603	1.60±0.10	0.80±0.10	0.50	0.40	0.15
	[.063±.004]	[.031±.004]	[.020]	[.016]	[.006]
0805	2.00±0.2	1.25±0.2	0.95	0.70	0.20
	[.079±.012]	[.049±.008]	[.037]	[.028]	[.008]
1206	3.20±0.3	1.60±0.2	0.95	1.50	0.30
	[.126±.012]	[.063±.008]	[.037]	[.059]	[.012]

### **♦** Characteristic







### ◆ Capacitance Range

X7R (X	() Ser	ies			X5R (E	3) Sei	ries										Y5V (	Y) Se	ries					
Size	80	05	12	206	Size		0603	1	0805			1206			Size		80	05			1206			
Code	16V	25V	16V	25V	Code	6.3V	10V	16V	6.3V	10V	16V	25V	6.3V	10V	16V	25V	Code	6.3V	10V	16V	25V	6.3V	10V	16V
105	В	В		В	105	T	T	T			В	В				В	105		В	В	В			
155	В		В	В	155				В		В				В		155							
225	В	В	В	В	225	T	T		В	В	В	В		В	В	В	225		В	В	В			В
335					335				В					В			335							
475					475				В	В			В	В			475	В	В	В	В		В	
106					106				В	В			В	В			106					В		
226					226								В				226							
Sym	hol C	odo	ī	Ŧ		B	ī																	

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.

0.85±0.1



Thickness(mm)

0.45±0.05



# VAC Series Specification & Test Condition

Item		ification				Test Condition	
Operation Temperature	Char. X7R (X) X5R (B) Y5V (Y)	Operation - -55°C ~ +1 -55°C ~ +8 -30°C ~ +8	<b>25</b> ℃ 5℃	- -			
Visual	No abnormal	exterior appeara	ince		Visual Inspection	1	
Capacitance	Within The Sp	pecified Tolerand	е		Capacitance	Frequency	Voltage
Dissipation Factor	Char. X7R/X5R Y5V	25V     16V       5%     7.5%       10%     12.5%	10V 15% 20%	6.3V max. 15% 20%	C≤10uF C>10uF Perform a heat to then place at roo		
Insulation Resistance	for rated volta	500/C Ω which ge>10V and gre ge≤10V. (C in	ater 100		Applied Voltage Charge Time : 6 Charge-Discharg 50mA current.	0±5 sec.	
Withstanding Voltage	No dielectric breakdown	breakdown or m	echanic	al	250% of the rate Current is limited		
Temperature Capacitance Coefficient	X7R(X)	emp. Range 55°C ~ +125°C 55°C ~ +85°C 80°C ~ +85°C	± 15 ± 15		(C2-C1)/C1 x 100 C1:Capacitance C2:Capacitance	at Standard Ter	
Adhesive Strength of Termination	No indication terminal elect	of peeling shall or rode.	occur or	n the	5N		Kg·f) pull force lied for 10±1 sec.
Resistance to Flexure of Substrate		al damage or cape following table.  Capacitan $\frac{\pm 12.5\%}{\pm 12.5\%}$ $\pm \pm 30.0\%$	ice Chai of initial of initial	nge value value	The board shall to mm/sec.	R230 C Meter 1.1mm 45±1mm	1
Solderability		% of the termina ly, so metal part e .			Solder Temperar Dip Time: 5 ± 0. Immersing Spee Solder: H63A Flux: Rosin Preheat: At 80	5 sec. d : 25±10% mm	
Resistance to Soldering Heat	Appearance Capacitance	X5R(B) <u>≤±</u> 7	Cap. ch 7.5% of 7.5% of 20% of in	nange initial value initial value nitial value	Capacitor shall be temperature after 150 +0/-10°C be Preheat: at 150: Dip: solder tempoint Time: 10 ± 20 Immersing Speet Solder: H63A Flux: Rosing Speet Rosing Speet Rosing Speet Rosing Rosi	or one hour heat fore initial meas ±10°C for 60~12 perature of 260± Isec. d: 25±10% mm	treatment at sure. 20sec. 5°C
	Insulation Resistance	To satisfy the s	specified	d initial	Measure at room 48 ± 4 Hours	n temperature a	fter cooling for





# VAC Series Specification & Test Condition

Item		Specification	Test Condition
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 ℃ before initial measurement.
	Capacitance		Capacitor shall be subjected to five cycles of the temperature cycle as following:  Step Temp.(°C) Time(min)  Min Rated Temp.+0/-3 30
	Tan $\delta$	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.+3/-0 30
	Insulation Resistance	To satisfy the specified initial value	4 25 3  Measure at room temperature after cooling for 48 ± 4 Hours
Humidity	Appearance Capacitance	No mechanical damage shall occur  Char. Cap. change $X7R(X) \leq \pm 12.5\%$ of initial value $X5R(B) \leq \pm 12.5\%$ of initial value	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measurement.  Temperature: 40±2 °C Relative Humidity: 90 ~95%RH
	$Tan \delta$		Test Time: 500 +12/-0 hr  Measure at room temperature after cooling for 48 ± 4 Hours
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)	
Humidity Loading	Appearance Capacitance	No mechanical damage shall occur  Char. Cap. change  X7R(X) $\leq \pm 15\%$ of initial value  X5R(B) $\leq \pm 15\%$ of initial value  Y5V(Y) $\leq \pm 30\%$ of initial value	Capacitors applied DC voltage of the rated voltage is applied for one hour at maximum operation temperature ±3°C then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage :Rated Voltage
	Tan $\delta$	Type         25V         16V         10V         6.3V           X7R/X5R         7.5%         12.5%         25%         25%           Y5V         13.5%         15%         30%         30%	Temperature : 40±2°C Relative Humidity : 90 ~95%RH Test Time : 500 +12/-0Hr Current Applied : 50 mA Max.
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller for rated voltage>10V and greater 5/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)	Measure at room temperature after cooling for 48 $\pm$ 4 Hours
High Temperature Load	Appearance	No mechanical damage shall occur	Capacitors applied DC testing rated voltage is applied for one hour at maximum operation
(Life Test)	Capacitance	$ \begin{array}{c c} \hline \text{Char.} & \text{Cap. change} \\ \hline X7R(X) & \leqq \pm 15\% \text{ of initial value} \\ \hline X5R(B) & \leqq \pm 15\% \text{ of initial value} \\ \hline Y5V(Y) & \leqq \pm 30\% \text{ of initial value} \\ \hline \end{array} $	temperature ±3°C then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage :Rated Voltage
	Tan $\delta$	Type         25V         16V         10V         6.3V           X7R/X5R         7.5%         12.5%         25%         25%           Y5V         13.5%         15%         30%         30%	Temperature : max. operating temperature Test Time : 1000 +48/-0Hr Current Applied : 50 mA Max.
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)	Measure at room temperature after cooling for $48\pm4$ Hours





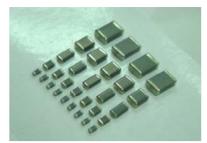
# Multilayer Ceramic Chip Capacitors [ High Cap. NPO ]

# **HCN** Series



### **♦** Features

- ☐ Small Size & High Capacitance
- ☐ Suitable for Wave and Reflow Soldering
- ☐ Excellent Characteristics and Tight Tolerance
- $\hfill \Box$  Excellent Bias,High Temperature Stability & Low Tan  $\,\delta$
- ☐ Replace Film Capacitor
- RoHS compliant



## Application

□ Suitable for ADSL Filter Circuits,
Cable Modem and Coupling Circuits,
general Telecommunications use,
Power (Inverter for oscillation Circuit) and
Audio Circuits

### **♦ Summary of Specification**

Operation Temperature	-55~+125 ℃
Rated Voltage	16V to 50Vdc
Temperature Coefficient	NPO : ≤ 60ppm/°C, -55~+125 °C (EIA Class I )
Capacitance Range	1nF ~ 220nF
Dissipation Factor :	Q ≥1000 at 1KHz 20°C
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller (C in Farad)
Dielectric Strength	250% Rated Voltage for 5 second @ 50mA max. current
Capacitance Tolerance	± 5% (±1%,±2% also available)
Aging	0% per decade hr , Typical

#### ♦ How To Order

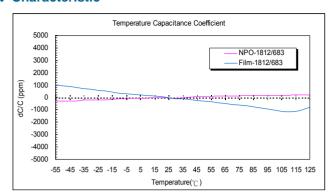
С	1206	N	103	J	025	T
Product Code	Chip Size	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Packaging
C: MLCC (Multilayer Ceramic Chip of Capacitor)	0603: 1.6x0.80 mm 0805: 2.0x1.25 mm 1206: 3.2x1.60 mm 1210: 3.2x2.50 mm 1812: 4.6x3.20 mm	N: NPO	Ex.: 102:10×10 <sup>2</sup> 103:10×10 <sup>3</sup> 124:12×10 <sup>4</sup>	Ex.: F:+/-1% G:+/-2% J:+/-5%	Ex.: 016:16Vdc 025:25Vdc 050:50Vdc	T: Taping & Reel B: Bulk

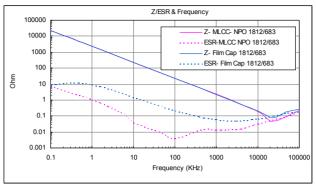




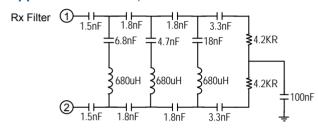
Unit: mm [inches]

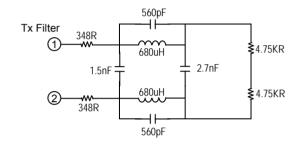
### **♦** Characteristic



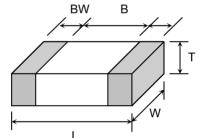


### ◆ Application Example Circuit





### **♦** Dimension



TYPE	L	W	T (max)	B (min)	BW (min)
0603	1.60+/-0.1	0.80+/-0.1	0.90	0.40	0.15
	[.063+/004]	[.031+/004]	[.039]	[.016]	[.006]
0805	2.00±0.2	1.25±0.2	1.40	0.70	0.20
	[.079±.012]	[.049 ±.008]	[.055]	[.028]	[.008]
1206	3.20±0.3	1.60±0.2	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1210	3.20±0.3	2.50±0.2	2.20	1.60	0.30
	[.126±.012]	[.098±.008]	[.087]	[.063]	[.012]
1812	4.60±0.3	3.20±0.3	2.20	4.00	0.20
	[.181±.012]	[.126±.012]	[.087]	[.157]	[.008]

### **◆ Capacitance Range**

-													_				_												
Dielectric	Size	Voltage																nge											
Characteristic	Size	vollage	102	122	152	107	222	332	392	472	295	682	822	103	123	153	183	223	273	333	393	473	263	683	823	104	124	154	224
		16V	В	В	ВЕ	3	ВЕ	В																					
	0603	25V	В	В	ВЕ	3	ВЕ	В																					
		50V	В	В	ВЕ	3	ВЕ	В																					
	16V	В	В	ВЕ	3	CL	D	D	D	D	D	D	О	D	D	D	D	D											
	0805	25V	В	В	ВЕ	3	CL	D	D	D	D	D	D	D	D	D													
		50V	В	В	ВЕ	3 [	CL	D	D	D	D	D	П	D															Ξ
		16V	В	В	ВЕ	3 [	ВЕ	ВВ	В	В	С	D	П	D	C/D	C/D	D	D	Ε	E	Е	Е	Е	Ε					
NPO	1206	25V	В	В	ВЕ	3 [	ВЕ	ВВ	В	В	С	D	П	D	C/D	C/D	D	D	Е	E	Е	Е							
		50V	В	В	ВЕ	3 [	ВЕ	ВВ	В	В	С	D	П	D	C/D	C/D	D	D	Ε	E									
		16V				1													D	E	Е	Е	Е	Ε	귀	F			
	1210	25V	С	С	C		C	C	С	С	С	С	O	С	D	Е	Е	F	F	F	F	F	F	F					
		50V	С	С	C		CC	C	С	С	С	С	O	O	D	Е	Е	F	F	F	F	F							
181		16V																					F	F	F	F	F	F	F
	1812	25V	D	D	DI	) [	DE	) D	D	D	D	D	D	D	D	D	D	Е	Ε	Е	Ε	F	F	F	F	F	F		
		50V	D	D	D [	) [	DE	D	D	D	D	D	D	D	D	D	D	Е	Е	Е	Ε	F	F	F	F	F			
Symbol Code	S	0		-	١	Ī	В			С			С	)			E			F			G			F	1		
Thickness(mm)	0.3±0.03	0.5±0.0	5	0.6	±0.1	(	0.85:	0.1	1	.0±0	0.1	1.:	25±	:0.1	5	1.6	±0.2	2	2.0	0±0.	2	2	.4±(	0.2	2	2.8±	0.2		

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





			rioly stolic
HCN Series Sp	pecification (	& Test Condition	
Item	Spec	ification	Test Condition
Operation Temperature	-55°C∼ +125	$^{\circ}\mathbb{C}$	
Visual	No Abnormal	Exterior Appearance	Visual Inspection
Capacitance	Within The Sp	ecified Tolerance	Frequency Voltage
Quality Factor	Q ≧1000		1KHz±10% 1.0±0.2Vrms
Insulation Resistance	10,000M $\Omega$ or (C in Farad)	500/C $\Omega$ whichever is smaller.	Applied Voltage : Rated Voltage Charge Time : 60±5 sec. Current is limited to less than 50mA
Withstanding Voltage	No dielectric b breakdown	oreakdown or mechanical	250% of the rated voltage for 1~5 sec. Current is limited to less than 50mA.
Temperature Capacitance Coefficient	Temperature -55°C ~ +12		[C2-C1/C1(T2-T1)] × 100% T1:Standard Temperature(25℃) T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance at Test Temperature
Adhesive Strength of Termination	No indication terminal electr	of peeling shall occur on the rode.	A 5N·f ( $\approx$ 0.5Kg·f) pull force shall be applied for 10±1 sec.
Resistance to Flexure of		al damage or change capacitanc following table.	mm/sec.
Substrate	Capacitance (	Change : $\leq \pm 5.0\%$ of initial value	R230 Bending Limit  C Meter  45±1mm  45±1mm
Solderability		% of the terminal surface is to be y, so metal part does not come e .	Solder Temperature : $245\pm5^{\circ}$ C Dip Time : $5\pm0.5$ sec. Immersing Speed : $25\pm10\%$ mm/s Solder : H63A Flux :Rosin Preheat : At 80~120 $^{\circ}$ C For 10~30sec.
Resistance To Soldering Heat	Appearance	No mechanical damage shall occur	Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C
	Capacitance	Cap. change within ±2.5% of initial value	<ul><li>Dip Time: 10 ± 1sec.</li><li>Immersing Speed: 25±10% mm/s</li><li>Solder: H63A</li></ul>
	Q Factor	To satisfy the specified initial value	Flux :Rosin  Measure at room temperature after cooling for  24 ± 2 Hours
	Insulation Resistance	To satisfy the specified initial value	
	Dielectric Strength	To satisfy the specified initial value	





# **HCN Series Specification & Test Condition**

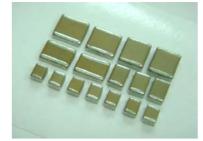
Item	Speci	fication	Test Condition					
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be subjected to five cycles of the temperature cycle as following:					
	Capacitance	Cap. change within ±2.5% of initial value	Step         Temp.(°C)         Time(min)           1         Min Rated Temp.(-55)+0/-3         30           2         25         3					
	Q Factor	To satisfy the specified initial value	3 Max Rated Temp.(+125)+3/-0 30 4 25 3					
	Insulation Resistance	To satisfy the specified initial value	Measure at room temperature after cooling for 24 $\pm 2$ Hours					
Humidity	Appearance	No mechanical damage shall occur	Temperature : $40\pm2~^{\circ}\mathrm{C}$ Relative Humidity : 90 ~95%RH					
	Capacitance	Cap. change within ±5.0% of initial value	Test Time: 500 +12/-0 hr  Measure at room temperature after cooling for					
	Q Factor	Q ≧350	24 ± 2 Hours					
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)						
Humidity Loading	Appearance	No mechanical damage shall occur	Applied Voltage :Rated Voltage Temperature : 40±2°C					
	Capacitance	Cap. change within ±5.0% of initial value	Relative Humidity : 90 $\sim$ 95%RH Test Time : 500 $+$ 12/ $-$ 0Hr Current Applied : 50 mA Max.					
	Q Factor	Q ≧350	Measure at room temperature after cooling for					
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller. (C in Farad)	• 24 ± 2 Hours					
High Temperature Load	Appearance	No mechanical damage shall occur	Applied Voltage :200% of Rated Voltage Temperature : max. operation temperature					
(Life Test)	Capacitance	Cap. change within ±3.0% of initial value	Test Time: 1000 +48/-0Hr Current Applied: 50 mA Max.					
	Q Factor	Q ≧350	Measure at room temperature after cooling for 24 $\pm$ 2 Hours					
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)						
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. board.					
	Capacitance	Within the specified tolerance	Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz					
	Tan $\delta$	To satisfy the specified initial value	in about 1 min.  Repeat this for 2 hours each in 3 perpendicular directions.					





# Multilayer Ceramic Chip Capacitors [ High Cap. X7R ]

# **HCX** Series



### ◆ Features

- ☐ Rated working voltage of 50 to 100Vdc
- ☐ Small size & high capacitance
- $\hfill \Box$  Excellent bias,high temperature stability & low Tan  $\,\delta$
- ☐ Low ESR and excellent ripple current characteristics
- □ RoHS compliant

## Application

- □ DC-DC Converters (filter)
- Industrial Controls
- Power Supplies
- Surge Protection

## **♦ Summary of Specification**

Operation Temperature	-55~+125 ℃
Rated Voltage	50V to 100Vdc
Temperature Coefficient	X7R : $\leq$ ± 15% at -55~+125 $^{\circ}$ C (EIA Class II )
Capacitance Range	100nF ~ 10uF
Dissipation Factor :	2.5% max. at 1KHz 25℃
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller (C in Farad )
Dielectric Strength	50V : 250% rated voltage for 5 second @ 50mA max. current
	100V :200% rated voltage for 5 second @ 50mA max. current
Capacitance Tolerance	± 10% , ± 20%
Aging	2.5% per decade hr , typical

### **♦** How To Order

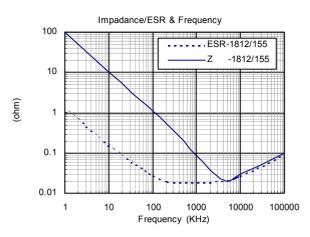
С	1210	Х	225	К	101	Т	Х
Product Code  C:MLCC (Multilayer Ceramic Chip of Capacitor)	Chip Size  Ex.: 1210: 3.2x2.5 mm 1812: 4.6x3.2 mm 1825: 4.6x6.35 mm 2220: 5.7x5.0 mm 2225:	Dielectric X: X7R	Capacitance Unit: pF Ex.: 102:10×10 <sup>2</sup> 224:22×10 <sup>4</sup> 105:10×10 <sup>5</sup>	Ex.: K: +/- 10% M: +/- 20%	Rated Voltage Ex.: 050:50Vdc 101:100Vdc	Packaging T: Taping & Reel B: Bulk	Special Requirement Ex.: O: Arc Prevention Coating X: Cushion Termination (Super Term)
	5.7×6.35 mm						

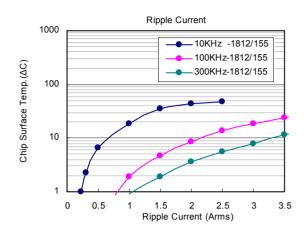




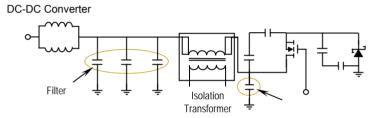
Unit: mm [inches]

### **♦** Characteristic

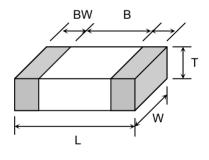




### ◆ Application Example Circuit



### **♦ Dimension**



TYPE	L	W	T (max)	B (min)	BW (min)
1210	3.20±0.3	2.50±0.2	2.60	1.60	0.30
	[.126±.012]	[.098±.008]	[.102]	[.063]	[.012]
1812	4.60±0.3	3.20±0.3	3.00	2.50	0.30
	[.181±.012]	[.126±.012]	[.118]	[.098]	[.012]
1825	4.60±0.3	6.35±0.4	3.00	2.50	0.30
	[. 181±.012]	[.250±.016]	[.118]	[.137]	[.012]
2220	5.70±0.4	5.00±0.4	3.00	3.50	0.30
	[.220±.016]	[.197±.016]	[.118]	[.137]	[.012]
2225	5.70±0.4	6.35±0.4	3.00	3.50	0.30
	[.220±.016]	[.250±.016]	[.118]	[.137]	[.012]

# ◆ Capacitance Range

5	Size	12	210	18	312	18	325	22	220	22	225
Code	WVDC	50V	100V								
104	100nF	С	С	D	D/E	D	D				
154	150nF	С	С	D	D/E	D	D				
224	220nF	С	С	D	D/E	D	D				
334	330nF	С	С	D	D/E	D	D				
474	470nF	D	С	D	E	D	D	E	E	D	D
564	560nF	D	D	D	E	D	D	E	E	D	D
684	680nF	D	E	D	E	D	E	E	E	D	D
105	1uF	E	F	D	E	D	E	F	F	D	Е
155	1.5uF	F	G	Е	F	E	F	F	F	Е	F
225	2.2uF	G	G	F	F	F	F	F	F	F	F
335	3.3uF			F		F		F	F	F	F
475	4.7uF			F		F		F	F	F	F
685	6.8uF							G		F	
106	10uF							H		G	
Symb	ool Code		S		0	Α	١	Е	3	С	;

Thickness(mm) 0.3±0.03 0.5±0.05 0.6±0.1 0.85±0.1 1.0±0.1 1.25±0.15 1.6±0.2 2.0±0.2 2.4±0.2 2.8±0.2

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





TION OCTICS OF		& Test Condition				
Item	Spec	ification	Test Condition			
Operation Temperature	-55℃~ +125℃	2				
Visual	No Abnormal	Exterior Appearance	Visual Inspection			
Capacitance	Within The Sp	ecified Tolerance	Frequency Voltage			
Dissipation Factor	0.025 max.		1KHz±10% 1.0±0.2Vrms			
			Perform a heat treatment at 150±5℃ for 30min then place room temp. for 24±2hr.			
Insulation Resistance	10,000M $\Omega$ or (C in Farad)	500/C $\Omega$ whichever is smaller.	Applied Voltage: Rated Voltage Charge Time: 60±5 sec. Charge-Discharge current shall be less than 50mA current.			
Withstanding Voltage	No dielectric l breakdown	oreakdown or mechanical	50V: 250% Rated Voltage 100V: 200% Rated Voltage for 1~5 sec. Current is limited to less than 50m/			
Temperature Capacitance Coefficient	Temp. R -55°C∼ +1	ange Cap. Change 125℃ ± 15%	(C2-C1)/C1 x 100% C1:Capacitance at Standard Temperature(25°C C2:Capacitance at Test Temperature			
Adhesive Strength of Termination	No indication terminal elect	of peeling shall occur on the rode.	A 5N·f ( $\approx$ 0.5Kg·f) pull force shall be applied for 10±1 sec			
Resistance to Flexure of Substrate		al damage or capacitance change following table.  Capacitance Change  ± 12.5% of initial Value	The board shall be bent 1.0mm with a rate of 1.0mm/sec.  R230  Bending  Limit  A5±1mm  Bending			
Solderability		% of the terminal surface is to be ly, so metal part does not come e.	Solder Temperature : 245±5°C Dip Time : 5 ± 0.5 sec. Immersing Speed : 25±10% mm/s Solder : H63A Flux :Rosin Preheat : At 80~120 °C For 10~30sec.			
Resistance to Soldering Heat	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48± 4 hours a room temperature after one hour heat treatmen			
	Capacitance	within $\pm 7.5\%$ of initial Value	at 150 +0/-10℃ before initial measurement.			
	Tan $\delta$	To satisfy the specified initial value	Preheat : at 150±10°C for 60~120sec. Dip : solder temperature of 260±5°C			
	Insulation Resistance	To satisfy the specified initial value	<ul> <li>Dip Time: 10 ± 1sec.         Immersing Speed: 25±10% mm/s         Solder: H63A         Flux: Rosin         Measure at room temperayure after cooling for Class I: 24 ± 2 Hours         Class II: 48 ± 4 Hours     </li> </ul>			





# **HCX Series Specification & Test Condition**

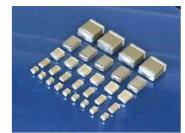
Item	Spec	ification	Test Condition					
Temperature Cycle	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48±4 hours at room temperature after one hour heat					
	Capacitance	Within ±7.5% of initial value	treatment at 150 +0/-10 $^{\circ}\mathrm{C}$ before initial measurement.					
	Tan $\delta$	To satisfy the specified initial value	Capacitor shall be subjected to five cycles of the temperature cycle as following:					
	Insulation	To satisfy the specified initial	Step         Temp.(°C)         Time(min)           1         Min Rated Temp.+0/-3         30					
	Resistance	value						
	110010101100	value	2 25 3 3 Max Rated Temp.+3/-0 30					
			4 25 3					
			Measure at room temperature after cooling for 48 $\pm$ 4 Hours					
Humidity	Appearance	No mechanical damage shall occur	Class ${\rm II}$ capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment					
	Capacitance	Within ±12.5% of initial value	at 150 +0/-10 °C before initial measurement.					
	Tan $\delta$	0.05 max.	Temperature : $40\pm 2 ^{\circ}$ C Relative Humidity : $90 \sim 95\%$ RH					
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Test Time: 500 +12/-0 hr  Measure at room temperature after cooling for 48 ± 4 Hours					
High Temperature Loading	Appearance	No mechanical damage shall occur	For Class II capacitors, DC testing voltage is applied for one hour at maximum operation					
(Life Test)	Capacitance	Within ±15% of initial value	temperature $\pm 3^\circ\mathbb{C}$ then shall set for 48±4 hours room temperature and the initial measurement					
	Tan $\delta$	0.05 max.	shall be conducted.					
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Load/Life Conditions: Caps rated <100V 200% Rated Voltage Caps rated ≥100V 150% Rated Voltage 1210/100V ≥1.0uF 120% Rated Voltage Temperature: max.operating temperature Test Time: 1000 +48/-0Hr Current Applied: 50 mA Max.					
			Measure at room temperature after cooling for $48\pm4\ \text{Hours}$					
Vibration	Appearance	No mechanical damage shall	Solder the capacitor on P.C. board.					
		occur	Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies					
	Capacitance	Within the specified tolerance	from 10Hz to 55Hz and back to 10Hz					
	Tan $\delta$	To satisfy the specified initial value	in about 1 min.  Repeat this for 2 hours each in 3 perpendicular directions.					





# Multilayer Ceramic Chip Capacitors [ Y5U Characteristic Capacitors ]

# **HCY** Series



### ◆ Features

- ☐ Small size & high capacitance
- ☐ Excellent high frequency characteristics due to low ESR
- ☐ Improved temperature stability over Y5V
- Excellent bias and high rated ripple current.
- ☐ Suitable for Wave and Reflow soldering
- ☐ RoHS compliant

### **◆** Application

- □ DC-DC converter for smoothing circuit.
- ☐ Switching power supplies, DC Fans...etc.
- ☐ Noise suppression, by pass and decoupling circuits.
- ☐ Other applications requiring very high capacitance values.

### **♦ Summary of Specification**

Operation Temperature	-30 °C to +85 °C
Rated Voltage	25V to 100Vdc
Temperature Coefficient	Y5U : ≤ +22 /-56 % , -30~+85 °C (EIA Class II )
Capacitance Range	10nF ~ 22uF
Dissipation Factor :	Y5U : D.F.≦4.0% at 1KHz 20 ℃
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller (C in Farad)
Dielectric Strength	250% Rated Voltage for 5 seconds @ 50mA max. current
Aging	Y5U: 4.0 % per decade hr, Typical

### **♦** How To Order

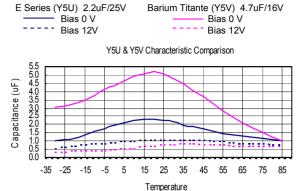
С	1206	Е	106	M	025	T
Product Code C: MLCC	Chip Size	Dielectric Ex.:	Capacitance Unit : pF Ex.:	Tolerance Ex.:	Rated Voltage Ex.: 010:10Vdc	Packaging T: Taping &
(Multilayer Ceramic Chip of Capacitor)	0603: 1.6×0.80 mm 0805: 2.0×1.25 mm	E: Y5U	102:10×10 <sup>2</sup> 473:47×10 <sup>3</sup> 106:10×10 <sup>6</sup>	M: +/- 20% Z:+80/-20%	025:25Vdc 050:50Vdc 101:100Vdc	Reel B: Bulk
,	1206: 3.2×1.60 mm 1210:					
	3.2×2.50 mm 1812 : 4.6×3.20 mm 2220 :					
	5.7×5.00 mm					



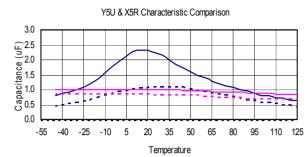


Unit: mm [inches]

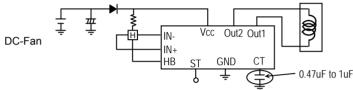
### **♦** Characteristic



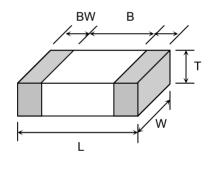




### ◆ Application Example Circuit



#### **♦** Dimension



TYPE	L	W	T (max)	B (min)	BW (min)
0603	1.60±0.1	0.80±0.1	0.90	0.40	0.15
	[.063±.004]	[.031 ±.004]	[.035]	[.016]	[.006]
0805	2.00±0.2	1.25±0.2	1.45	0.70	0.20
	[.079±.012]	[.049 ±.008]	[.057]	[.028]	[.008]
1206	3.20±0.3	1.60±0.2	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1210	3.20±0.3	2.50±0.2	2.60	1.60	0.30
	[.126±.012]	[.098±.008]	[.102]	[.063]	[.012]
1812	4.60±0.3	3.20±0.3	3.00	2.50	0.30
	[.181±.012]	[.126±.012]	[.118]	[.098]	[.012]
2220	5.70±0.4	5.00±0.4	3.00	3.50	0.30
	[.220±.016]	[.197±.016]	[.118]	[.137]	[.012]

### ◆ Capacitance Range

Y5U (I	E) Se	ries																	
Size		0603	,		0805			1206	i	1210			1812				2220		
Code	10V	25V	50V	10V	25V	50V	10V	25V	50V	10V	25V	50V	100V	25V	50V	100V	25V	50V	100V
103		В	В		В	В		В	В		С	С	Е	Е	F	F	F	F	F
153		В	В		В	В		В	В		С	С	E	Е	F	F	F	F	F
223		В	В		В	В		В	В		С	С	LE.	E	Į.F.	F	F	<u>F</u>	F
333		В	В		В	В		В	В		С	C	ᄩ	E	트	트	F	ĻΕ	F
473		В	В		В	В		В	В	$\vdash$	C	C	ᄩ	븓	븓	븓	ᆣ	냳	F
683		В			В	В		В	В		С	C	트	트	ᆣ	ᆣ	ᆣ	ᆣ	F
104		В			В	В	-	В	В	$\vdash$	C	C	늗	늗	냗	냗	냗	늗	F
154		B			B	ВВ		B B	B	$\vdash$	C	C	툳	툳	늗	F	F	F	F
224		В			В	В	-	В	C	$\vdash$	č	C	듵	듣	늗	F	F	F	F
334 474	-	$\vdash$			В		$\vdash$	В	č	$\vdash$	č	$\frac{c}{c}$	늘	듣	늗	듵	듣	<del>\</del> ₽	╁┋╁
564		$\vdash$			В			В	Ď		č	č	늗	늗	늗	늗	F	늗	╁┋┪
684					B			В	Б		č	$\frac{c}{c}$		岸	늗	늗	늗	늗	Ė
105	В				В			В	Ĕ		C	C		F	Ė	Ė	Ė	Ė	F
155								C			Ď	Ď		Ē	宦	Ė	F	盲	F
225								Ď			D			Ē	Ė		Ė	Ė	F
335											D			Ē	F		F	F	G
475				D							E			E	F		F	F	
685											E			F			F	F	
106				D			D			F				F			F	F	
226																	G		
Sym	bol C	ode		S		0		Α		В		С		D		Е		F	(
Thick	ness	(mm)	0.3	±0.03	0.5	±0.0	5 0.	6±0.′	1 0.	.85±0	.1 1	.0±0.	1 1.2	25±0.′	15 1.	.6±0.2	2.	0±0.2	2.4±

<sup>•</sup> Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





Item	S	pecification	Test Cond	lition					
Operation Temperature	-30°C∼ +85°C								
Visual	No abnormal	exterior appearance	Visual Inspection						
Capacitance	Within the spe	cified tolerance	Frequency	Voltage					
Dissipation	4.0% (0.04) M	laximum	1KHz±10%	1.0±0.2Vrms					
Factor			Perform a heat trea then place at room	tment at 150 $\pm$ 5°C for 30min. temp. for 24 $\pm$ 2hr.					
Insulation Resistance	10,000M $\Omega$ or (C in Farad)	500/C $Ω$ whichever is smaller.	Applied Voltage: Rated Voltage Charge Time: 60±5 sec. Charge-Discharge current shall be less than 50mA.						
Withstanding Voltage	No dielectric l breakdown	oreakdown or mechanical	250% of the rated vo Current is limited to						
Temperature Capacitance Coefficient		emp. Range	(C2-C1)/C1 x 100%  C1:Capacitance at S C2:Capacitance at T	Standard Temperature Test Temperature					
Adhesive Strength of Termination	No indication terminal elect	of peeling shall occur on the code.	₹ 5N·f	A 5N·f ( $\approx$ 0.5Kg·f) pull force shall be applied for 10±1 second.					
Resistance to Flexure of Substrate		al damage or change capacitance following table.	The board shall be bomm/sec.	pent 1.0mm with a rate of 1.0					
Substrate	Capacitance (	Change : $\leq \pm 30\%$ of initial value	45±1mm	Bending Limit  Meter  45±1mm					
Solderability		% of the terminal surface is to be y, so metal part does not come e .	Solder Temperature : $245\pm5^{\circ}$ C Dip Time : $5\pm0.5$ sec. Immersing Speed : $25\pm10\%$ mm/s Solder : H63A Flux :Rosin Preheat : At 80~120 $^{\circ}$ C For 10~30sec.						
Resistance to Soldering Heat	Appearance	No mechanical damage shall occur	temperature after on	et for 48± 4 hours at room e hour heat treatment at					
	Capacitance	Cap. change within ±20% of initial value	- 150 +0/-10℃ before Preheat : at 150±10°	initial measurement. C for 60~120sec.					
	$Tan\delta$	To satisfy the specified initial value	Dip : solder tempera Dip Time : 10 ± 1sec	<b>.</b> .					
	Insulation Resistance	To satisfy the specified initial value	Immersion Speed : 25±10% mm/s Solder : H63A Flux : Rosin Measure at room temperature after coolir 48 ± 4 Hours						





# **HCY Series Specification & Test Condition**

Item		Specification	Test Condition							
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at							
	Capacitance	Cap. change within ±20% of initial value	150 +0/-10 $^{\circ}$ C before initial measurement. Capacitor shall be subjected to five cycles of the temperature cycle as follow:							
	Tan δ	To satisfy the specified initial value	Step         Temp.(°C)         Time(min           1         Min Rated Temp.(-30)+0/-3         30							
	Insulation Resistance	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.(+85)+3/-0 30 4 25 3							
			4 25 3  Measure at room temperature after cooling for 48 ± 4 Hours							
Humidity	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 15							
	Capacitance	Cap. change within ±30% of initial value	+0/-10 $^{\circ}$ before initial measurement. Temperature : 40 $^{\pm}$ 2 $^{\circ}$ C Relative Humidity : 90 ~95%RH							
	$Tan\delta$	6.0% Maximum	Test Time : 500 +12/-0 hr							
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Measure at room temperature after cooling for $48\pm4$ Hours							
Humidity Loading	Appearance	No mechanical damage shall occur	Capacitors applied DC voltage of the rated voltage is applied for one hour at maximum							
	Capacitance	Cap. change within ±30% of initial value	operation temperature $\pm 3^{\circ}$ C then shall be set for 48 $\pm$ 4 hours at room temperature and the initial measurement shall be conducted.							
	Tan $\delta$	6.0% Maximum	Applied Voltage : Dated Voltage							
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller. (C in Farad)	Applied Voltage :Rated Voltage Temperature : 40±2°C Relative Humidity : 90 ~95%RH Test Time : 500 +12/-0Hr Current Applied : 50 mA Max.							
			Measure at room temperature after cooling for 48 $\pm$ 4 Hours							
High Temperature Load	Appearance	No mechanical damage shall occur	Capacitors applied DC testing voltage is applied for one hour at maximum operation							
(Life Test)	Capacitance	Cap. change within ±30% of initial value	temperature ±3℃ then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.							
	Tan $\delta$	6.0% Maximum	Applied Voltage :200% Rated Voltage							
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	However: For rated voltage ≥ 100V, applied voltage of 150% rated voltage. Temperature: max. operating temperature Test Time: 1000 +48/-0Hr Current Applied: 50 mA Max.							
			Measure at room temperature after cooling for 48 ± 4 Hours							





# Multilayer Ceramic Chip Capacitors [ Radio Frequency Capacitors ]

# **RFC** Series



### **♦** Features

- ☐ High Q value & Low ESL at high frequency
- ☐ Ultra stable C0G performance
- ☐ Ultra miniature size 0402 and 0201
- ☐ Low capacitance with tight tolerance
- RoHS compliant

## Application

- □ Radio Frequency
- Impedance Matching Circuit
- Resonant Circuit
- Coupling Circuit
  - ◆RF Modules, VCO, BPF, DUP, PA, etc.
  - Cellular Phone, Bluetooth, Wireless LAN etc.

### **♦ Summary of Specification**

Operation Temperature	-55 to +125℃
Rated Voltage	25Vdc
Size	0201 and 0402
Temperature Coefficient	C0G < $\pm$ 30ppm/ $^{\circ}$ C , -55 $^{\circ}$ +125 $^{\circ}$ C (EIA Class $I$ )
Capacitance Range	0.1pF ~ 15pF
Q Value :	Q ≥1000 at 1MHz & ≥ 500. at 1GHz / 1pF
Insulation Resistance	<b>10G</b> Ω
Dielectric Strength	300% Rated Voltage for 5 second @ 50mA max. current
Tolerance	$\pm~0.05$ pF to $\pm~0.1$ pF, C , J
Aging	0 % per decade of time , Typical

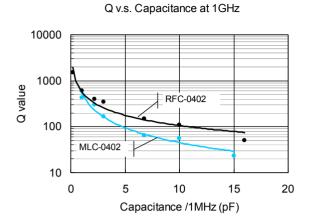
### **♦** How To Order

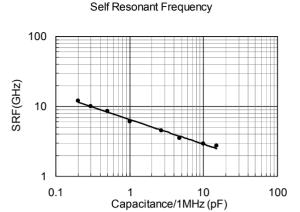
RFC	0402	G	R30	В	025	Т
Product Code	Chip Size	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Packaging
RFC: Radio Frequency of MLCC	Ex.: 0201 : 0.6×0.3 mm 0402 : 1.0×0.5 mm	Ex.: G:C0G	Ex.: R10: 0.1pF 5R0: 5.0pF 120: 12×10 <sup>0</sup>	Ex.: L: ±0.050pF A: ±0.075pF B: ±0.10pF C: ±0.25pF J: ± 5.0 %	Ex.: 025:25Vdc	T: Taping & Reel B: Bulk



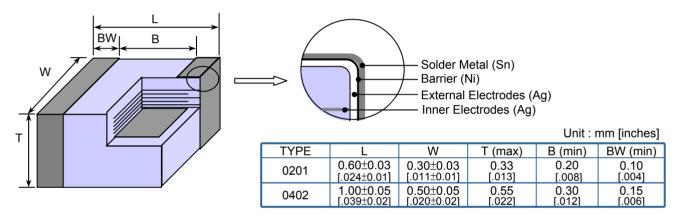


### **♦** Characteristic

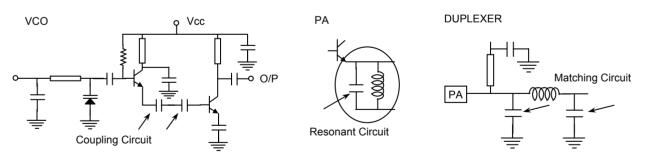




### **♦ Structure & Dimension**



### ◆ **Application** Example Circuit



### **♦** Capacitance Range

Dielectric	Size	Voltage	0000				tange Rang	<u> </u>	m101514		
Characteristic	0.20		R10 R20 R30 R40	R5( R6( R7(	R80 180	1R1 1R2 1R3 1R5	1R6 1R8 2R(	2R4 2R7 3R0	3R3 3R6 4R7	9R2 100	120 150
C0G	0201	25V	SSSS	SSS	S S S	SSSS	SSSS	SSSS	SSS		
COG	0402	25V	0000	0000	000	0000	0000	0000	0000		00
To	olerance		± 0.05pl	±0.0	75pF	±	0.1pF		± 0.2	25pF	±5%
Symbol Code	S	0	Α	В	С	D	Е	F	G	Н	1
Thickness(mm)	0.3±0.03	0.5±0.05	0.6±0.1	0.85±0.1	1.0±0.1	1 1.25±0.15	1.6±0.2	2.0±0.2	2.4±0.2	2.8±0.2	

<sup>■</sup> Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





Specification  -55°C ~ +125°C  No abnormal exterior appearance  Within the specified tolerance  ≥ 1000  More than 10,000M Ω  No dielectric breakdown or mechanical breakdown  Char. Temp. Range Cap. Change ± 30ppm/°C  COG(G) -55°C ~ +125°C ± 30ppm/°C  No indication of peeling shall occur on the terminal electrode.	Visual Inspection  Frequency Voltage  1MHz±10% 1.0±0.2Vrms  Applied Voltage : Rated Voltage Charge Time : 60±5 sec. Charge-Discharge current shall be less than 50mA current.  300% of the rated voltage for 1~5 sec. Current is limited to less than 50mA  [C2-C1/C1(T2-T1)] × 100%  T1:Standard Temperature(20°C) T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance at Test Temperature  A 5N·f (≈ 0.5Kg·f) pull force shall be applied for 10±1						
No abnormal exterior appearance  Within the specified tolerance  ≥ 1000  More than 10,000M Ω  No dielectric breakdown or mechanical breakdown  Char. Temp. Range Cap. Change ± 30ppm/°C  COG(G) -55°C~+125°C ± 30ppm/°C	Frequency Voltage $1MHz\pm10\%$ $1.0\pm0.2Vrms$ Applied Voltage : Rated Voltage Charge Time : $60\pm5$ sec. Charge-Discharge current shall be less than 50mA current. $300\%$ of the rated voltage for 1~5 sec. Current is limited to less than 50mA $[C2-C1/C1(T2-T1)] \times 100\%$ $T1:Standard Temperature(20°C)$ $T2:Test Temperature$ $C1:Capacitance at Standard Temperature$ $C2:Capacitance at Test Temperature$ $A 5N·f (\approx 0.5Kg·f) pull force$						
Within the specified tolerance  ≥ 1000  More than 10,000M Ω  No dielectric breakdown or mechanical breakdown  Char. Temp. Range Cap. Change ± 30ppm/°C  COG(G) -55°C ~ +125°C ± 30ppm/°C	Frequency Voltage  1MHz±10% 1.0±0.2Vrms  Applied Voltage : Rated Voltage Charge Time : 60±5 sec. Charge-Discharge current shall be less than 50mA current.  300% of the rated voltage for 1~5 sec. Current is limited to less than 50mA  [C2-C1/C1(T2-T1)] × 100%  T1:Standard Temperature(20°C) T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance at Test Temperature						
No dielectric breakdown or mechanical breakdown  Char. Temp. Range Cap. Change ± 30ppm/°C  No indication of peeling shall occur on the	Applied Voltage: Rated Voltage Charge Time: 60±5 sec. Charge-Discharge current shall be less than 50mA current.  300% of the rated voltage for 1~5 sec. Current is limited to less than 50mA  [C2-C1/C1(T2-T1)] × 100% T1:Standard Temperature(20°C) T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance at Test Temperature						
More than 10,000MΩ  No dielectric breakdown or mechanical breakdown  Char. Temp. Range Cap. Change ± 30ppm/°C  COG(G) -55°C∼ +125°C ± 30ppm/°C	Applied Voltage: Rated Voltage Charge Time: 60±5 sec. Charge-Discharge current shall be less than 50mA current.  300% of the rated voltage for 1~5 sec. Current is limited to less than 50mA  [C2-C1/C1(T2-T1)] × 100% T1:Standard Temperature(20°C) T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance at Test Temperature						
No dielectric breakdown or mechanical breakdown    Char. Temp. Range Cap. Change   COG(G) -55°C~+125°C ± 30ppm/°C    No indication of peeling shall occur on the	Charge Time: 60±5 sec. Charge-Discharge current shall be less than 50mA current.  300% of the rated voltage for 1~5 sec. Current is limited to less than 50mA  [C2-C1/C1(T2-T1)] × 100%  T1:Standard Temperature(20°C) T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance at Test Temperature						
breakdown  Char. Temp. Range Cap. Change  COG(G) -55°C∼+125°C ±30ppm/°C  No indication of peeling shall occur on the	Current is limited to less than 50mA  [C2-C1/C1(T2-T1)] × 100%  T1:Standard Temperature(20°C)  T2:Test Temperature  C1:Capacitance at Standard Temperature  C2:Capacitance at Test Temperature  A 5N·f (≈ 0.5Kg·f) pull force						
COG(G) $\overline{-55^{\circ}\text{C}}$ $\overline{+125^{\circ}\text{C}}$ $\pm$ 30ppm/ $^{\circ}\text{C}$ No indication of peeling shall occur on the	T1:Standard Temperature(20°C) T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance at Test Temperature  A 5N·f (≈ 0.5Kg·f) pull force						
No mechanical damage shall occur.	The board shall be bent 1.0mm with a rate of 1.0mm/sec.  R230  Bending  Limit  45±1mm  Bending						
More than 90% of the terminal surface is to be soldered newly, so metal part does not come out or dissolve .	Solder Temperature : $245\pm5^{\circ}$ C Dip Time : $2\pm0.5$ sec. Immersion Speed : $25\pm10\%$ mm/s Solder : H63A Flux :Rosin Preheat : At 80~120 $^{\circ}$ C For 10~30sec.						
Appearance No mechanical damage shall occur  Capacitance Cap. change within ±7.5% or ±0.02pF of initial value, whichever is large.	Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C  Dip Time : 10 ± 1sec.  Immersing Speed : 25±10% mm/s  Solder : H63A  Flux : Rosin						
	Appearance Capacitance Cap. change within ±7.5% or ±0.02pF of initial value, whichever						





# RFC Series Specification & Test Condition

Item		Specification	Test Condition						
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be subjected to five cycles of the temperature cycle as follow:						
	Capacitance	Cap. change within $\pm 7.5\%$ or $\pm 0.02$ pF of initial value, whichever is larger.	2 25 3						
	Insulation Resistance	$\geq$ 1,000M $\Omega$	3 Max Rated Temp.(+125)+3/-0 30 4 25 3						
	Resistance		Measure at room temperature after cooling for 24 $\pm$ 2 Hours						
Humidity	Appearance	No mechanical damage shall occur	Temperature : 40± 2 °C Relative Humidity : 90 ~95%RH						
	Capacitance	Cap. change Within 7.5% or ±0.02pF of initial value, Whichever is larger	Test Time: 500 +12/-0 hr  Measure at room temperature after cooling for 24 ± 2 Hours						
	Q	≧200							
	Insulation Resistance	≧1,000MΩ							
Humidity Loading	Appearance	No mechanical damage shall occur	Applied Voltage :Rated Voltage Temperature : 40±2℃						
	Insulation Resistance	≧1,000MΩ	Relative Humidity : 90 ~95%RH Test Time : 500 +12/-0Hr Current Applied : 50 mA Max.						
			Measure at room temperature after cooling for 24 $\pm$ 2 Hours						
High Temperature Load	Appearance	No mechanical damage shall occur	Applied Voltage :200%Rated Voltage Temperature : max. operating temperature						
(Life Test)	Insulation	≧1,000MΩ	Test Time : 1000 +48/-0Hr Current Applied : 50 mA Max.						
	Resistance		Measure at room temperature after cooling for 24 ± 2 Hours						





# Multilayer Ceramic Chip Capacitors [Multilayer Capacitor Arrays]

# MCA Series

The capacitor array combines four separate multilayer ceramic capacitors. It's can reduce PCB space and improve placement efficiency compared to 2×MLCC & 4×MLCC.



#### **♦** Features

- ☐ Small size with 2×MLCC & 4×MLCC capacitor
- ☐ Space saving for high density placing requirement
- ☐ Improve placement efficiency
- ☐ Suitable for Cellular, Pagers, I/O Port, Mother Boards and General Electronic Equipment.
- □ RoHS compliant

### **♦** Summary of Specification

### NPO Dielectric Characteristic

Temperature Coefficient :  $\pm 30$ ppm/°C , -55~+125°C

Capacitance Range 10pF to 470pF

Dissipation Factor: more than 30pF:  $Q \ge 1000 (0.001)$ 

30pF& below:  $Q \ge 400+20C$  C:pF

Insulation Resistance :  $~~10G\,\Omega~$  or 500/C  $\,\Omega~$  whichever is smaller

Dielectric Strength: 250% Rated Voltage

### X7R Dielectric Characteristic

Temperature Coefficient :  $\pm 15\%$ , -55~+125°C Capacitance Range 180pF to 1.0uF See table 1.

Insulation Resistance : 10G  $\Omega$  or 500/C  $\Omega$  whichever is smaller

Dielectric Strength: 250% Rated Voltage

X5R Dielectric Characteristic

Temperature Coefficient :  $\pm 15\%$ , -55~+85°C Capacitance Range 100nF to 2.2uF Dissipation Factor : See table 1.

Insulation Resistance :  $10G\Omega$  or 500/C  $\Omega$  whichever is smaller

Dielectric Strength: 250% Rated Voltage

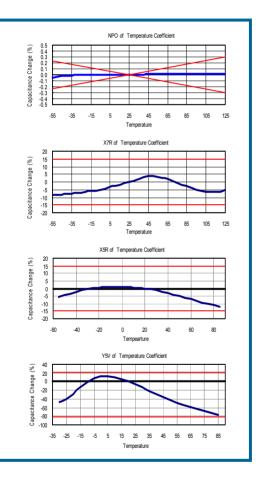
### Y5V Dielectric Characteristic

Temperature Coefficient : +22/ -82 %, -30~+85°C Capacitance Range 10nF to 1.0uF

Capacitance Range 10nF to 1.0uF Dissipation Factor: See table 2.

Insulation Resistance :  $10G\Omega$  or 500/C  $\Omega$  whichever is smaller

Dielectric Strength: 250% Rated Voltage



#### ♦ How To Order

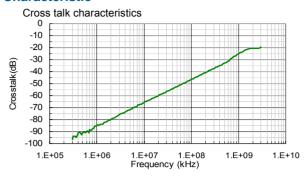
CA 4 B 1C 105 M T

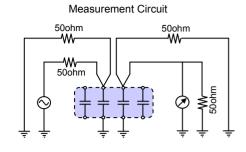
Product Code	Chip Size	Dielectric	Rated Voltage	Capacitance Unit : pF	Tolerance	Packaging
CA: MLCC Array	6: 1206 3.2×1.6 mm 5: 0805 2.0×1.25 mm 4: 0504 1.37×1.0 mm	Ex.: N: NPO X: X7R B:X5R Y: Y5V	Ex.: 1J : 6.3Vdc 1A: 10Vdc 1C: 16Vdc 1E: 25Vdc 1H:50Vdc	Ex.: 102:10×10 <sup>2</sup> 473:47×10 <sup>3</sup> 104:10×10 <sup>4</sup>	Ex.: K : +/- 10% M: +/- 20% Z :+80/-20 %	T: Taping & Reel B: Bulk



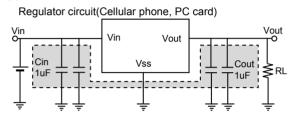
# Holy Stone

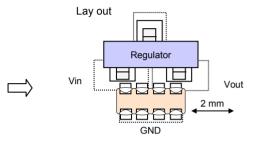
### **♦** Characteristic



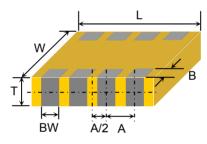


### ◆ **Application** Example Circuit





### **♦** Dimension



					Unit :	mm [inches]
Type	L	W	T (max.)	B (min.)	BW	Α
0504	1.37±0.15	1.00±0.10	0.90	0.10	0.36± 0.10	0.64± 0.10
	[.054±.006]	[.039±.004]	[.035]	[.004]	[.014±.004]	[.025±.004]
0805	2.00±0.15	1.25±0.15	0.95	0.10	0.25± 0.10	0.50± 0.10
	[.079±.006]	[.049±.006]	[.037]	[.004]	[.010±.004]	[.020±.004]
1206	3.20±0.20	1.60±0.20	0.90	0.10	0.40± 0.10	0.80± 0.10
	[.126±.008]	[.063±.008]	[.035]	[.004]	[.016±.004]	[.031±.004]

### **◆** Capacitance Range

Temperature	0.	Rated							Range							
Characteristic	Size	Voltage	100 120 150 180	220 270 330	390 470 560 680	820 101 121	151	221 271 331	391 471 681	102	222	332 472	103	473	104 224	105 125 225
NPO	0805 4 <sub>X</sub> Cap	50V	В	ВВ	В	В		В								
NIO	1206 4 <sub>X</sub> Cap	50V	BBBB	ввв	BBBB	ввв	ВВ	ввв	ВВ							
		10V												В	В	
	0805 4 <sub>×</sub> Cap	16V											В		В	
	0000 4χοαρ	25V										В				
		50V							В	В	В					
X7R		6.3V														В
XIIX	1206 4 <sub>×</sub> Cap	16V					В	ввв	BBE	BE	ВВВ	ВВ	В	3 B	В	
	1200 4x Cap	25V					В	ВВВ	ВВЕ	BE	ВВВ	ВВ	В			
		50V					В	ВВВ	ВВЕ	BE	ВВВ	ВВ	В			
	0504 2×Cap	10V													А	
	0304 Z^Cap	16V													А	
	0805 4 <sub>×</sub> Cap	16V													В	
		10V														В
Y5V	1206 4 <sub>×</sub> Cap	16V											ВП	ВВ	В	
	1200 4xCap	25V											ВП	ВВ	ВВ	
		50V											В		В	
	0805 4×Cap	6.3V														В
	0005 4×Cap	10V													В	
X5R		6.3V														ВЕ
-	0504 2 <sub>X</sub> Cap	10V													А	В
		16V													Α	В
Symbol Code	S	0	A	В	С	D		E	T		G	; [		Н	T	
Thickness(mm)	0.3±0.03 C	0.5±0.05	0.6±0.1	0.85±0.1	1.0±0.1	1.25±0	0.15	1.6±0.2	2.0	£0.2	2.4±	0.2	2.8	±0.2	1	

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





MCA Series Speci	fication & Te	st Condition
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Item		Specification		Tes	t Condition	
Operation Temperature	Char. NPO(N) X7R (X) X5R (B) Y5V (Y)	Operation To -55°C ~ +129 -55°C ~ +129 -55°C ~ +85° -30°C ~ +85°	5°C 5°C C			
Visual	No abnormal	exterior appeara	nce	Visual Inspection	n	
Capacitance	Within The Sp	pecified Toleranc	е	Char.	Frequency	Voltage
Quality Factor		): B0pF : Q ≧1000 bw: Q≧400+20C	(C:Cap., pF)	NPO X7R/X5R/Y5V	1MHz±10% 1KHz±10%	1.0±0.2Vrms 1.0±0.2Vrms
Dissipation Factor	Class	X5R/Y5V): the value in Table	e 1,Table 2		treatment at 15 oom temp. for 24	0±5°C for 30min. ±2hr.
Insulation Resistance		500/C Ω which age>10V and grea age≤10V. (C in		Charge Time :	e : Rated Voltag 60±5 sec. rge current shall	
Withstanding Voltage	No dielectric l breakdown	breakdown or me	echanical		ed voltage for 1 ed to less than 5	
Temperature Capacitance Coefficient	NPO(N) X7R (X) X5R (B)	Temp. Range -55°C ~ +125°C -55°C ~ +125°C -55°C ~ +85°C -30°C ~ +85°C	Cap. Change ± 30ppm/°C ± 15% ± 15% +22/-82%	Class II:  (C2-C1)/C1:  T1:Standard Te  T2:Test Tempe C1:Capacitance	mperature(20°C	mperature
Adhesive Strength of Termination	No indication terminal elect	of peeling shall o	occur on the	1	.0mm 5N·f	

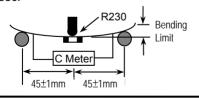
A 5N·f ( $\approx 0.5 Kg\cdot f)$  pull force shall be applied for 10±1 sec.

### Resistance to Flexure of Substrate

No mechanical damage or capacitance change more than the following table.

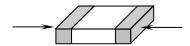
Char.	Capacitance Change
NPO(N)	≦ ± 5.0%
X7R (X)	≦ ± 12.5%
X5R (B)	≦ ± 12.5%
Y5V (Y)	≦ ± 30.0%

The board shall be bent 1.0mm with a rate of 1.0 mm/sec.



### Solderability

More than 90% of the terminal surface is to be soldered newly, so metal part does not come out or dissolve .



Solder Temperature : 245±5°C

Dip Time :  $5 \pm 1$  sec.

Immersing Speed: 25±10% mm/s

Solder : H63A Flux :Rosin

Preheat : At 80~120 ℃ For 10~30sec.





# MCA Series Specification & Test Condition

Item		Specification	Test Condition
Resistance to Soldering Heat	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48± 4 hours at room temperature after one hour heat treatment
	Capacitance	Class I (NPO): Within 2.5% or $\pm 0.25$ pF whichever is larger of initial value Class II: Char.  Cap. change  X7R(X) $\leq \pm 7.5\%$ of initial value  X5R(B) $\leq \pm 7.5\%$ of initial value $\leq \pm 20\%$ of initial value	at 150 +0/-10°C before initial measure.  Preheat: at 150±10°C for 60~120sec.  Dip: solder temperature of 260±5°C  Dip Time: 10 ± 1sec.  Immersing Speed: 25±10% mm/s  Solder: H63A  Flux: Rosin
	Q / Tan $\delta$	To satisfy the specified initial value	Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours
	Insulation Resistance	To satisfy the specified initial value	Class II : 48 ± 4 Hours
Temperature Cycle	Appearance	No mechanical damage shall occur	Class  ☐ capacitor shall be set for 48±4 hours at room temperature after one hour heat
	Capacitance	Class I (NPO): Within 2.5% or ±0.25pF whichever is larger of initial value Class II: Char. Cap. change	the temperature cycle as following:
		$\frac{\text{Criar.}}{\text{X7R(X)}} = \frac{\text{Cap. criarige}}{\leq \pm 7.5\% \text{ of initial value}}$	Step Temp.(°C) Time(min)
		$X5R(B) \le \pm 7.5\%$ of initial value	1 Min Rated Temp.+0/-3 30 2 25 3
		Y5V(Y) $\leq \pm 20\%$ of initial value	3 Max Rated Temp.+3/-0 30
	Q / Tan $\delta$	To satisfy the specified initial value	4 25 3
	Insulation Resistance	To satisfy the specified initial value	Measure at room temperature after cooling for Class I : $24 \pm 2$ Hours Class II : $48 \pm 4$ Hours
Humidity	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment
	Capacitance	Class I (NPO): Within 5.0% or $\pm 0.5$ pF whichever is larger of initial value Class II: Char.  Cap. change  X7R(X) $\leq \pm 12.5\%$ of initial value  X5R(B) $\leq \pm 12.5\%$ of initial value  Y5V(Y) $\leq \pm 30\%$ of initial value	
	Q Class I	30pF & Over : Q ≥350 10 to 30pF : Q≥275+2.5C 30pF & Below: Q≥200+10C	Class II : 48 ± 4 Hours
	Tan δ Class ∐	Shall meet the value in Table 1, Table 2	
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)	





# MCA Series Specification & Test Condition

Item		Specification	Test Condition
Humidity Loading	Appearance	No mechanical damage shall occur	Class II capacitors applied DC voltage of the rated voltage is applied for one hour at
	Capacitance	Class I (NPO): Within 7.5% or ±0.75pF whichever is larger of initial value Class II: Char. Cap. change	maximum operation temperature ±3℃ then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage :Rated Voltage
			Temperature : 40±2°C Relative Humidity : 90 ~95%RH Test Time : 500 +12/-0Hr Current Applied : 50 mA Max.
	Q Class I	30pF & Over : Q ≥350 10 to 30pF : Q≥275+2.5C 30pF & Below: Q≥200+10C	Measure at room temperature after cooling for Class I : 24 ± 2 Hours
	Tan δ Class Ⅱ	Shall meet the value in Table 1, Table 2	Class II : 48 ± 4 Hours
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller for rated voltage>10V and greater 5/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)	
High Temperature Load	Appearance	No mechanical damage shall occur	Class $\scriptstyle \rm II \>\>\> c$ apacitors applied DC testing voltage is applied for one hour at maximum operation
(Life Test)	Capacitance	Class I (NPO): Within 5.0% or ±0.5pF whichever is larger of initial value	temperature ±3°C then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.
		Class II:	Applied Voltage :200%Rated Voltage However:
			The size 0504,applied voltage of 100% rated voltage Temperature : max. operation temperature Test Time : 1000 +48/-0Hr
	Q Class I	30pF & Over : Q ≥350 10 to 30pF : Q≥275+2.5C 30pF & Below: Q≥200+10C	Current Applied : 50 mA Max.  Measure at room temperature after cooling for Class I : 24 ± 2 Hours
	Tan $\delta$ Class ${\rm II}$	Shall meet the value in Table 1, Table 2	Class II : 48 ± 4 Hours
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V. (C in Farad)	
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. board.
	Capacitance	Within the specified tolerance	<ul> <li>Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies</li> <li>from 10Hz to 55Hz and back to 10Hz</li> </ul>
	Q / Tan δ	To satisfy the specified initial value	in about 1 min.  Repeat this for 2 hours each in 3 perpendicular directions.





## X7R/X5R Table 1.

			tan o	∂ (D.F.)
		Capacitance	Initial	Humidity
Size	Rated voltage	Range	Vibration	Humidity loading
		range	Resistance to solder heat	High temperature loading
			Temperature cycle	
	DC 6.3V		15.0 %	25.0 %
0504	DC 10V	All Capacitance	15.0 %	25.0 %
	DC 16V		15.0 %	25.0 %
	DC 10V		7.5 %	12.5 %
0805	DC 16V	All Canacitanas	3.5 %	7.5 %
0000	DC 25V	All Capacitance	3.5 %	7.5 %
	DC 50V		2.5 %	5.0 %
	DC 6.3V	C=1uf	7.5 %	12.5 %
1206	DC 16V	C<1uf	3.5 %	7.5 %
1200	DC 25V	C<1uf	3.5 %	7.5 %
	DC 50V	C<1uf	2.5 %	5.0 %

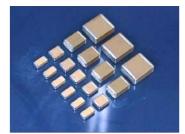
## Y5V Table 2.

			taı	nδ
Size	Rated voltage	Capacitance Range	Initial Vibration Resistance to solder heat Temperature cycle	Humidity Humidity loading High temperature loading
0805	DC 16V	C<1uf	10.0 %	15.0 %
	DC 10V	C=1uf	12.5 %	20.0 %
1206	DC 16V	C<1uf	10.0 %	15.0 %
	DC 25V	C<1uf	7.0 %	10.5 %



# Multilayer Ceramic Chip Capacitors [ Tip & Ring Capacitors ]

# **SAC** Series



In telephone lines the DC voltage is 48 volts and pass the subscriber's AC signal pulse(15 to 25Hz, 70 to 90Vrms).

These MLCC ringer capacitors replace bulk leaded film capacitors and offer excellent frequency response, low ESR, and improved temperature characteristics. Ideal for telecommunication/modem applications.

### ◆ Features

- ☐ Small Size & High Capacitance
- ☐ Suitable for Wave and Reflow Soldering
- Surface Mount
- ☐ Low ESR characteristics & improved temperature performance
- RoHS compliant

### **♦ Summary of Specification**

Operation temperature	X7R : -55~+125 ℃ , Y5U : -30~+85 ℃
Rated Voltage	250Vdc
Temperature Coefficient	Y5U : ≤ +22 /-56 % , -30~+85 °C (EIA Class II )
	X7R : ≤ ± 15% , -55~+125 °C (EIA Class II )
Capacitance Range	Y5U :10nF ~ 2.2uF
	X7R :180pF ~ 2.2uF
Dissipation Factor :	Y5U: D.F. ≦4.0%; X7R: D.F. ≦2.5%
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller
Dielectric Strength	200% Rated Voltage for 5 second @ 50mA max. current
Aging	Y5U: 4.0 % ; X7R: 2.5 % per decade hr , Typical

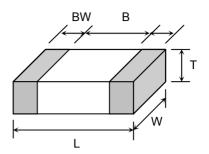
### **♦ How To Order**

С	1812	X	474	М	251	T
Product Code	Chip Size	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Packaging
C: MLCC (Multilayer Ceramic Chip of Capacitor)	Ex.: 0805 : 2.0×1.25 mm 1206 : 3.2×1.60 mm 1210 : 3.2×2.50 mm 1812 : 4.6×3.20 mm 2220 : 5.7×5.00 mm	Ex.: X : X7R E : Y5U	Ex.: 103:10×10 <sup>3</sup> 474:47×10 <sup>4</sup>	Ex.: K: +/- 10% M: +/- 20%	Ex.: 251:250Vdc	T: Taping & Reel B: Bulk



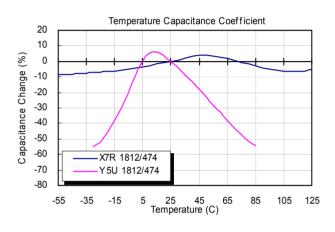


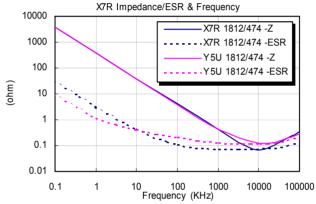
### **♦ Dimension**



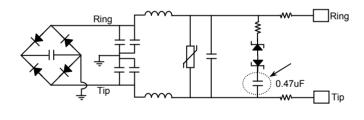
				Unit	: mm [inches]
TYPE	L	W	T (max)	B (min)	BW (min)
0805	2.00±0.2	1.25±0.2	1.45	0.70	0.20
	[.079±.012]	[.049 ±.008]	[.043]	[.028]	[.008]
1206	3.20±0.3	1.60±0.2	1.80	1.50	0.30
	[.126±.012]	[.126±.012]	[.071]	[.059]	[.012]
1210	3.20±0.3	2.50±0.2	2.60	1.60	0.30
	[.126±.012]	[.098±.008]	[.102]	[.063]	[.012]
1812	4.60±0.3	3.20±0.3	3.00	2.50	0.30
	[.181±.012]	[.126±.012]	[.118]	[.098]	[.012]
2220	5.70±0.4	5.00±0.4	3.00	3.50	0.30
	[.220±.016]	[.197±.016]	[.118]	[.137]	[.012]

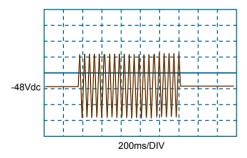
### **♦** Characteristic





### ◆ Application Example Circuit





## **♦ Capacitance Range**

Dielectric							Capac	itance Ran	ige			
Characteristic	Size	Voltage	181	221 271 331 471	681 102 152 182	332 472	562 682 103 153	223 273 333 393	473 563 683 823	104 154 224	334 474 564 684	824 105 155 225
	0805	250V		CCC	CCCC	CCCC	CCCC	CDDD	D			
	1206	250V	С	CCCC	CCCC	CCCC	CCCC	CCCC		E DE		
X7R	1210	250V					DD	DDDD	DDDC	DDD		
	1812	250V					DD	DDDD	EEE	EEE	EEEE	F G
	2220	250V								EEE	EEEE	E F F G
Y5U	1812	250V					EE	EEEE	EEEE	EEE	EEEF	FF
Symbol Code	S	C	)	Α	В	С	D	E	F	G	Н	
Thickness(mm)	0.3±0	.03 0.5±0	0.05	0.6±0.1	0.85±0.1	1.0±0.1	1.25±0.15	1.6±0.2	2.0±0.2	2.4±0.2	2.8±0.2	

<sup>■</sup> Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





<b>SAC Series Specification &amp; Test Condition</b>
--

Item	Specification	Test Condition
Operation Temperature	Char.         Operation Temp.           X7R(X)         -55°C ~ +125°C           Y5U(E)         -30°C ~ +85°C	
Visual	No Abnormal Exterior Appearance	Visual Inspection
Capacitance	Within The Specified Tolerance	Frequency Voltage
Dissipation Factor	Char.         D.F. (max.)           X7R(X)         2.5%           Y5U(E)         4.0%	1KHz±10% 1.0±0.2Vrms  Perform a heat treatment at 150±5℃ for 30min then place room temp. for 24±2hr.
Insulation Resistance	10,000M $\Omega$ or 500/C $\Omega$ whichever is smalle (C in Farad)	er. Applied Voltage : Rated Voltage Charge Time : 60±5 sec. Charge-Discharge current shall be less than 50mA current.
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	200% of the rated voltage for 1~5 sec. Current is limited to less than 50mA.
Temperature Capacitance Coefficient	Char.         Temp. Range         Cap. Chan           X7R(X)         -55°C ~ +125°C         ± 15%           Y5U(E)         -30°C ~ +85°C         +22/-56%	C1:Capacitance at Standard Temperature
Adhesive Strength of Termination	No indication of peeling shall occur on the terminal electrode.	A 5N·f ( $\approx$ 0.5Kg·f) pull force shall be applied for 10±1 section 10±
Resistance to Flexure of Substrate	No mechanical damage or change capacitate more than the following table.	The board shall be bent 1.0mm with a rate of 1.0 mm/sec.  R230  Bending Limit  45±1mm  Bending Limit
Solderability	More than 90% of the terminal surface is to soldered newly, so metal part does not comout or dissolve .	•
Resistance to Soldering Heat	Appearance No mechanical damage sha occur	Capacitor shall be set for 48± 4 hours at room temperature after one hour heat treatment at 150 +0/-10°C before initial measurement.
	$\begin{tabular}{c c} Capacitance & Char. & Cap. change \\ \hline $X7R(X)$ & $\leq \pm 7.5\%$ of initial value \\ \hline $Y5U(E)$ & $\leq \pm 20\%$ of initial value \\ \hline $Tan  \delta$ & To satisfy the specified initial value \\ \hline \end{tabular}$	alue Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C  Dip Time : 10 ± 1sec.
	value  Insulation To satisfy the specified initial resistance value	Immersing Speed : 25±10% mm/s Solder : H63A



48  $\pm$  4 Hours



# SAC Series Specification & Test Condition

Item		Specification	Test Condition		
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at		
	Capacitance	$\begin{tabular}{ll} Char. & Cap. change \\ \hline X7R(X) & $\leq \pm 7.5\%$ of initial value \\ \hline Y5U(E) & $\leq \pm 20\%$ of initial value \\ \hline \end{tabular}$	150 +0/-10 ℃ before initial measurement. Capacitor shall be subjected to five cycles of the temperature cycle as following:		
	Tan $\delta$	To satisfy the specified initial value	Step         Temp.(°C)         Time(min)           1         Min Rated Temp.+0/-3         30           2         25         3		
	Insulation Resistance	To satisfy the specified initial value	3 Max Rated Temp.+3/-0 30 4 25 3		
			Measure at room temperature after cooling for 48 $\pm$ 4 Hours		
Humidity	Appearance	No mechanical damage shall occur	Capacitor shall be set for $48\pm4$ hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measurement.  Temperature: $40\pm2$ °C Relative Humidity: $90 \sim 95\%$ RH Test Time: $500 +12/-0$ hr  Measure at room temperature after cooling for $48\pm4$ Hours		
	Capacitance				
	Tan $\delta$	Char.         D.F. (max.)           X7R(X)         5.0%           Y5U(E)         5.0%			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)			
High Temperature Load	Appearance	No mechanical damage shall occur	Capacitors applied DC voltage of 120% the ra voltage is applied for one hour at maximum		
(Life Test )	Capacitance		operation temperature $\pm 3^{\circ}\mathbb{C}$ then shall be set for 48 $\pm 4$ hours at room temperature and the initial measurement shall be conducted.		
	Tan $\delta$	Char.         D.F. (max.)           X7R(X)         5.0%           Y5U(E)         5.0%	Applied Voltage :120%Rated Voltage Temperature : max. operating temperature Test Time : 1000 +48/-0Hr Current Applied : 50 mA Max.		
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	··		
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. board.		
	Capacitance	Within the specified tolerance	Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz in about 1 min.  Repeat this for 2 hours each in 3 perpendicular directions.		
	Tan $\delta$	To satisfy the specified initial value			





# Molding Style Capacitors [High Voltage Capacitors]

# MMC Series



### **Excellent Reliability: Bending and Arcing Prevention**

#### **♦** Features

- ☐ High reliability: molded package improves arc over and flexure strength characteristics
- ☐ Surface mount suited for reflow soldering
- lue High temperature stability & low tan  $\delta$
- ☐ RoHS compliant

### Application

☐ Suitable for ballast circuit of back-lighting Inverter, DC-DC converters, modems & snubber circuits of switching power supply

### **♦ Summary of Specification**

Operation Temperature	-55~+125 ℃
Rated Voltage	3KVdc and 5KVdc
Temperature Coefficient	NPO : $\leq$ ± 30ppm/ $^{\circ}$ C , -55~+125 $^{\circ}$ C (EIA Class $I$ )
Capacitance Range	2pF to 150pF
Dissipation Factor :	NPO : Q≥1000
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller
Aging	0%
Dielectric Strength	120% Rated Voltage; is applied less than 50mA current.

### **♦** How To Order

MMC	С	N	150	К	502	T
Product Code	Style & Size	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Packaging
MMC: Molding Style Capacitors	Ex.: A: 1810 4.9×2.6×2.6 C: 2816 7.0×3.2×3.2	Ex.: N: NPO	Ex.: 5R0:5.0pF 100:10x10 <sup>0</sup> 101:10x10 <sup>1</sup>	Ex.: C:+/- 0.25pF D:+/- 0.5pF J:+/- 5% K:+/- 10% M:+/- 20%	Ex.: 302: 3KVdc 502: 5KVdc	T: Taping & Reel B: Bulk

### ◆ Capacitance Range

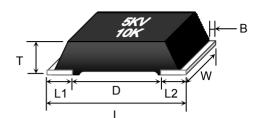
Temperature C: Ra		Rated	Capacitance Range (pF)		
Characteristic	Size	Voltage	2220 388 388 388 388 388 380 380 580 580 580 580 580 580 580 580 580 5		
	Α	3KV			
NPO	_	3KV			
	٥	5KV			

■ Other capacitance values and voltages rating are available. Please contact HEC.



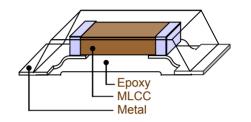


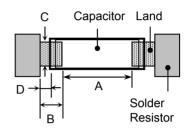
### **♦** Sharp & Dimension



		Unit : mm [inches]
Style	SMA-L	SMC-L
L	4.90±0.2 [.193±.008]	7.00±0.2 [.276±.008]
W	2.60±0.2 [.102±.008]	3.20±0.2 [.126±.008]
T	2.60±0.2 [.102±.008]	3.20±0.2 [.126±.008]
L1=L2	0.45±0.2 [.018±.008]	0.75±0.2 [.030±.008]
В	0.30±0.2 [.012±.008]	0.30±0.3 [.012±.008]
D	4.0 +0.2/-0 [.157 +.008/-0]	5.5 +0.2/-0 [.216 +.008/-0]

### **♦ Construction & Recommend Land Dimension**



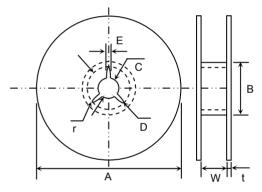


		Unit :mm
Style	SMA-L	SMC-L
Α	3.2~3.4	5.1~5.3
В	1.4~1.6	1.4~1.6
С	2.6~2.8	3.2~3.4
D	0.4~0.6	0.4~0.6

Unit: mm

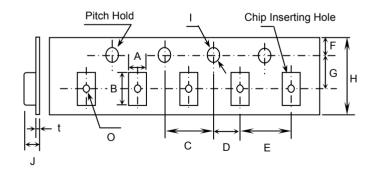
### **◆ Packing Specification**

### **Reel Dimension**



	Unit: mm
	SMA-L / SMC-L
Α	¢ 178±0.2
В	¢ 60±0.2
С	¢ 13±0.5
D	¢ 21±0.8
Е	¢ 2.0±0.5
W	13±0.3
t	17±1.4
<u>r</u>	1.0

### **Embossed Tape**



	SMA-L	SMC-L
Α	2.85±0.1	3.45±0.1
В	5.20±0.1	7.30±0.1
С	4.00±0.1	4.00±0.1
<u>D</u>	2.0±0.05	2.0±0.05
Ε	4.0±0.10	8.0±0.10
F	1.75±0.1	1.75±0.1
G	5.50±0.1	5.50±0.1
Н	12.0±0.1	12.0±0.1
<u> </u>	¢1.55±0.05	¢1.55±0.05
J	2.80±0.1	3.40±0.1
t	0.3 max.	0.3 max.
0	1.55±0.05	1.55±0.05
	-	

### Material And Quantity (¢180mm)

Style	¢180mm reel
SMA-L 1000pcs/reel	
SMC-L	700pcs/reel





MMC Series Sp	pecification & Test Condition				
Item	Specification	Test Condition			
Operation Temperature	-55 to +125℃				
Visual	No abnormal exterior appearance	Visual Inspection			
Capacitance	Within The Specified Tolerance	Cap. Frequency Voltage			
Quality Factor	More Than 30pF : Q $\geq$ 1000 30pF & Below: Q $\geq$ 400 + 20C (C:Cap., pF)	C≤100pF 1MHz±10% 1.0±0.2Vrms C>100pF 1KHz±10%			
Insulation Resistance	10,000M $\Omega$ or 500/C $\Omega$ whichever is smaller. (C in Farad)	Applied 500Vdc Charge Time : 60sec. Is applied less than 50mA current.			
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	Applied Voltage:120% Rated Voltage for 1~5 sec. Current is limited to less than 50mA.			
Temperature Capacitance Coefficient	Char.     Temp. Range     Cap. Change       NPO(N)     -55°C∼+125°C     ± 30ppm/°C	[C2-C1/C1(T2-T1)] × 100% T1:Standard Temperature(25℃) T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance at Test Temperature			
Adhesive Strength of Termination	No indication of peeling shall occur on the terminal electrode.	A 5N·f(≈0.5Kg·f) pull force shall be applied for 10±1 sec.			
Resistance to Flexure of Substrate	No mechanical damage or capacitance change more than the following table.	The board shall be bent 1.0mm with a rate of 1.0 mm/sec.  R230  Bending Limit  C Meter  45±1mm  Bending Limit			
Solderability	More than 90% of the terminal surface is to be soldered newly, so metal part does not come out or dissolve .	Solder Temperature : $245\pm5^{\circ}$ C Dip Time : $5\pm0.5$ sec. Immersing Speed : $25\pm10\%$ mm/s Solder : H63A Flux :Rosin Preheat : At 80~120 °C For 10~30sec.			
Resistance to Soldering Heat	Appearance No mechanical damage shall occur  Capacitance Within 2.5% or ±0.25pF whichever	Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C  Dip Time : 10 ± 1sec.			
	Capacitance Within 2.5% or ±0.25pF whichever is larger of initial value  Q To satisfy the specified initial value	Immersing Speed : 25±10% mm/s Solder : H63A Flux : Rosin  Measure at room temperature after cooling for			
	Insulation To satisfy the specified initial Resistance value	24 ± 2 Hours			





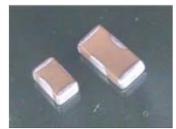
Item		Specification	Test Condition			
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be subjected to five cycles of the temperature cycle as following:			
	Capacitance	Within 2.5% or $\pm 0.25$ pF whichever is larger of initial value	Step         Temp.(°C)         Time(min)           1         Min Rated Temp.+0/-3 (-55)         30			
	Q	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.+3/-0 (125) 30 4 25 3			
	Insulation Resistance	To satisfy the specified initial value	Measure at room temperature after cooling for 24 ± 2 Hours			
Humidity	Appearance	No mechanical damage shall occur	Capacitor shall be set for 24±4 hours at room temperature after one hour heat treatment at 150			
	Capacitance	Within 5% or ±0.5pF whichever is larger of initial value	+0/-10 °C before initial measurement.  Temperature : 40± 2 °C  Relative Humidity : 90 ~95%RH			
	Q	More Than 30pF : Q ≧350 30pF & Below: Q≧275+2.5C	Test Time: 500 +12/-0 hr  Measure at room temperature after cooling for			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad) 24 $\pm$ 2 Hours				
High Temperature Load	Appearance	No mechanical damage shall occur	Capacitors applied DC voltage of 100% the r			
(Life Test)	Capacitance	Within 3% or ±0.3pF whichever is larger of initial value	operation temperature $\pm 3^{\circ}$ C then shall be set for 48 $\pm$ 4 hours at room temperature and the initial measurement shall be conducted.			
	Q	More Than 30pF : Q ≧350 30pF & Below: Q≧275+2.5C	Applied Voltage : 100%Rated Voltage Temperature : max. operating temperature Test Time : 1000 +12/-0Hr			
	Insulation	1,000M $\Omega$ or 50/C $\Omega$ whichever is	Current Applied : 50 mA Max.			
	Resistance	smaller. (C in Farad)	Measure at room temperature after cooling for 24 $\pm$ 2 Hours			
Vibration	Appearance	No mechanical damage shall	Solder the capacitor on P.C. board.			
		occur	Vibrate the capacitor with amplitude of			
	Capacitance	Within the specified tolerance	1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz in about 1 min.			
	Q	To satisfy the specified initial value	Repeat this for 2 hours each in 3 perpendicular directions.			





# Multilayer Ceramic Chip Capacitors [Feed Thru' EMI Filters]

## FTC Series



The FTC series is a three terminal structure component. This product is capable of handling currents up to 2A and is suitable for use on DC power lines, preventing noise suppression from high speed signal lines and IC's.

### Features

- ☐ Suitable for power line ripple voltage stabilization
- □ Ultra low inductance
- ☐ Supply in MEC function
- ☐ RoHS compliant

### Application

☐ For high speed digital integration circuit and decoupling of CPU power lines.

### **♦ Summary of Specification**

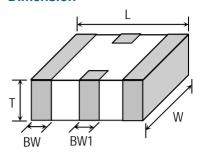
Operation Temperature	-55 to +125℃
Rated Voltage	50Vdc
Current Rating	2A
Size	0805 and 1206
Temperature Coefficient	C0G < $\pm$ 30ppm/°ℂ , -55~+125 °ℂ (EIA Class I )
	X7R < ± 15%, , -55∼+125 ℃ (EIA Class II )
Capacitance Range	NPO : 22pF ~1.0nF
	X7R: 1.0nF ~100nF
Tolerance	± 20%
DC Resistance	600m $Ω$ max.
Insulation Resistance	10G $\Omega$ or 500/C whichever is smaller
Dielectric Strength	250% Rated Voltage for 5 second @ 50mA max. current

FTC	1206	X	332	M	050	T	20
Product Code FTC: Feed Thru' EMI Filter	Ex.: 0805: 2.0×1.25 mm 1206: 3.2×1.6 mm	Dielectric  Ex.: N: NPO X: X7R	Capacitance Unit: pF Ex.: 100:10×10 <sup>0</sup> 471:47×10 <sup>1</sup> 182:18×10 <sup>2</sup>	Tolerance Ex.: M:+/-20%	Rated Voltage Ex.: 050: 50VDC	Packaging T: Taping &Reel B: Bulk	Rated Current  Ex.: 10: 1A 20: 2A



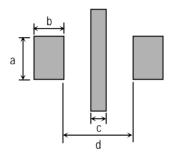


### **♦ Dimension**



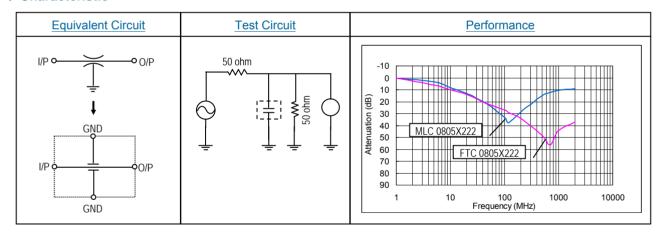
Unit : mm [inches								
TYPE	L	W	T (max)	B W(min)	BW1			
0805	2.00 ±0.2	1.25±0.2	1.00	0.20	0.50±0.2			
	[.079±.008]	[.049±.008]	[.039]	[.008]	[.020±.008]			
1206	3.20±0.02	1.60±0.2	1.25	0.20	0.95±0.3			
	[.126±.008]	[.063±.008]	[.049]	[.008]	[.037 ±.012]			

### **♦ Recommend Solder Lands**



		Unit : mm
TYPE	0805	1206
а	0.9~1.0	1.2~1.3
b	0.9~1.0	0.9~1.0
С	0.4~0.5	0.8~0.9
d	1.5	1.5

### **♦** Characteristic



### **◆ Capacitance Range**

Dielectric Characteristic	Size	Rated Voltage	Rated Current	100 150 330 470	680 680 151 221		itance Ran	0	333 333 473 104	154 224 334
NPO	0805	50V	2A	BBBB	BBBE	ВВВВ				
NEO	1206	50V	2A	BBBB	ВВВВ	ВВВВ	3			
X7R	0805	50V	2A				ВВВВЕ	ВВВ		
XIIX	1206	50V	2A			E	ВВВВ	ВВВВЕ	ВВВВ	3
Symbol Code	S	0	Α	В	С	D	E	F	G	Н
Thickness(mm)	0.3±0.03	0.5±0.05	0.6±0.1	0.85±0.1	1.0±0.1	1.25±0.15	1.6±0.2	2.0±0.2	2.4±0.2	2.8±0.2

<sup>•</sup> Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





Item	Specification	Test Condition								
Operation Temperature	-55 to +125℃									
Visual	No abnormal exterior appearance	Visual Inspection								
Capacitance	Within The Specified Tolerance	Class Frequency Voltage								
Quality Factor	Class I (NPO): More Than 30pF : $Q \ge 1000$ 30pF & Below: $Q \ge 400 + 20C$ (C:Cap., pF)	Class I (NPO) 1MHz±10% 1.0±0.2Vrms 1KHz±10% 1KHz±10% Perform a heat treatment at 150±5°C for 30min.								
Dissipation Factor	Class ∏ (X7R): Maximum 0.025	then place room temp. for 24±2hr.								
Insulation Resistance	1,000M $\Omega$ or 100/C $\Omega$ whichever is smaller. (C in Farad)	Rated Voltage Charge Time : 60sec. Current is limited to less than 50mA.								
RDC (L,S)	C< 10,000pF : 600m $\Omega$ max. C≥ 10,000pF : 300m $\Omega$ max.	Rated Current 100mA Max.  RDC S  RDC L  RDC S								
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	Applied Voltage : 250% Rated Voltage for 1~5 sec. Current is limited to less than 50mA								
Temperature Capacitance Coefficient	Char.         Temp. Range         Cap. Change           NPO(N)         -55°C∼+125°C         ± 30ppm/°C           X7R (X)         -55°C∼+125°C         ± 15%	Class I:  [C2-C1/C1(T2-T1)] × 100%  Class II:  (C2-C1)/C1 × 100%  T1:Standard Temperature(25°C)  T2:Test Temperature  C1:Capacitance at Standard Temperature  C2:Capacitance at Test Temperature								
Solderability	More than 90% of the terminal surface is to be soldered newly, so metal part does not come out or dissolve .	Solder Temperature : $245\pm5^{\circ}$ C Dip Time : $5\pm0.5$ sec. Immersing Speed : $25\pm10\%$ mm/s Solder : H63A Flux :Rosin Preheat : At 80~120 $^{\circ}$ C For 10~30sec.								





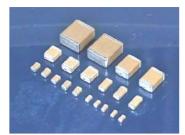
<u>Item</u>		Specification	Test Condition								
Temperature Cycle	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial								
	Capacitance	Class I (NPO): Within 2.5% or $\pm 0.25$ pF whicheve is larger of initial value Class II (X7R): Within $\pm 7.5\%$ of initial value	measurement.  Capacitor shall be subjected to five cycles of the temperature cycle as following:  Step Temp.(°C) Time(min)  Min Rated Temp.+0/-3 (-55) 30								
	Q / Tan $\delta$	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.+3/-0 (125) 30								
	Insulation Resistance	500M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	4 25 3  Measure at room temperature after cooling for								
	DCR(L,S)	1.0 $\Omega$ Maximum	Class I : 24 ± 2 Hours Class II : 48 ± 4 Hours								
Humidity	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment								
	Capacitance	Class I (NPO): Within 5% or $\pm 0.5$ pF whichever is larger of initial value Class II (X7R): Within $\pm 10\%$ of initial value	at 150 +0/-10 °C before initial measurement.  Temperature: 40± 2 °C  Relative Humidity: 90 ~95%RH  Test Time: 500 +12/-0 hr  Measure at room temperature after cooling for								
	$Q$ / $Tan\delta$	Class I (NPO): More Than 30pF : Q $\geq$ 350 30pF & Below: Q $\geq$ 275 + 2.5C	Class I : 24 ± 2 Hours Class II : 48 ± 4 Hours								
High Temperature ∟oad		Class II (X7R): Maximum ±5.0%									
	Insulation Resistance	500M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)									
	DCR(L,S)	1.0 Ω Maximum									
High Temperature Load	Appearance	No mechanical damage shall occur	Class II capacitors applied DC voltage (following table) is applied for one hour at maximum								
	Capacitance	Class I (NPO): Within 5% or ±0.5pF whichever is larger of initial value Class II (X7R): Within ±15% of initial value	operation temperature ±3°C then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage :200% of rated voltage Applied Current : rated current Temperature : max. operating temperature								
	${\sf Q}$ / ${\sf Tan}\delta$	Class I (NPO):  More Than 30pF : Q ≥350 30pF & Below: Q≥275+2.5C  Class II (X7R):	Test Time : 1000 +12/-0Hr Current Applied : 50 mA Max. Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours								
	Insulation Resistance	Maximum $\pm 5\%$ $500M \Omega \text{ or } 50/C \Omega \text{ whichever is smaller.} \qquad \text{(C in Farad)}$	Class II: 48 ± 4 Hours								
	DCR(L,S)	1.0Ω Maximum									





# Multilayer Ceramic Chip Capacitors [High Temperature Capacitor]

## **HTC** Series



### ◆ Features

- ☐ Rated working voltage of 25 to 50Vdc
- $\hfill \Box$  Excellent bias,high temperature stability & low Tan  $\, \delta \,$
- □ RoHS compliant

### **◆** Application

- ☐ Suitable for oil exploration, automotive and avionics engine, and other harsh environments.
- ☐ Other high temperature circuit design

### **♦ Summary of Specification**

Operation Temperature	-55~+200 ℃								
Rated Voltage	25V and 50Vdc								
Temperature Coefficient	Cap drop ≤ + 4.7%~ -65% at -55~+200 °C								
Capacitance Range	1nF ~ 270nF								
Dissipation Factor :	2.0% max. at 1KHz 25°C								
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller								
	$\geq$ 1G $\Omega$ or 10/C $\Omega$ at 200 °C Which is smaller								
Dielectric Strength	250% Rated Voltage for 5 second @ 50mA max. current								
Capacitance Tolerance	± 10% , ± 20%								
Aging	1.0% per decade hr , Typical								

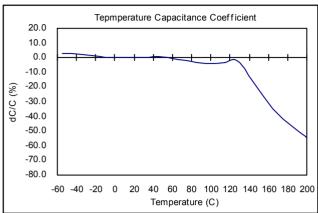
HTC	1812	Х	104	К	050	Т
Product Code	Chip Size	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Packaging
HTC: High Temperature Capacitor	Ex.: 0603: 1.6x0.80 mm 0805: 2.0x1.25 mm 1206: 3.2x1.60 mm 1210: 3.2x2.50 mm 1812: 4.6x3.20 mm 2220: 5.7x5.00 mm	X: X7R	Ex.: 102:10×10 <sup>2</sup> 224:22×10 <sup>4</sup>	Ex.: K: +/- 10% M: +/- 20%	Ex.: 025:25Vdc 050:50Vdc	T: Taping & Reel B: Bulk

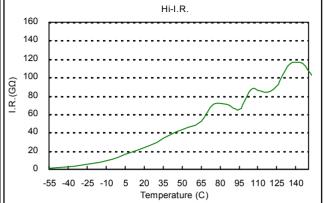




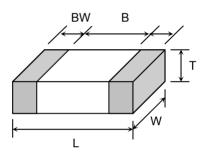
Unit: mm [inches]

### **♦** Characteristic





### **♦** Dimension



TYPE	L	W	T (max)	B (min)	BW (min)
0603	1.60±0.1	0.80±0.1	0.90	0.40	0.15
	[.063±.004]	[.031 ±.004]	[.035]	[.016]	[.006]
0805	2.00±0.2	1.25±0.2	1.45	0.70	0.20
	[.079±.012]	[.049 ±.008]	[.057]	[.028]	[.008]
1206	3.20±0.3	1.60±0.2	1.50	0.30	
	[.126±.012]	[.126±.012]	[.059]	[.012]	
1210	3.20±0.3	2.50±0.2	1.80	1.60	0.30
	[.126±.012]	[.098±.008]	[.071]	[.063]	[.012]
1812	4.60±0.3	3.20±0.3	2.20	2.50	0.30
	[.181±.012]	[.126±.012]	[.087]	[.098]	[.012]
2220	5.70±0.4	5.00±0.4	2.20	3.50	0.30
	[.220±.016]	[.197±.016]	[.087]	[.137]	[.012]

### **♦ Capacitance Range**

Dielectric Characteristic	Size	Rated Voltage	102 122 152	2222 2722 3322 332		pacitance F		583 563 683	104 154 224 274	t / 2
	0603	50V	ВВВ	ВВВВ	ВВВВ	ВВ				
	0805	50V		C	CICICICI	CCCC	CC			
	1206	25V				CCC	CICICICI	CICICICI	CC	
X7R		50V				CCC	CICICICI	CICICICI	CC	
	1210	50V						CC	CCCC	
	1812	50V						DDI	DDDD	
	2220	50V								D
Symbol Code	S	0	Α	В	С	D	Е	F	G	Н
Thickness(mm)	0.3±0.03	0.5±0.05	0.6±0.1	0.85±0.1	1.0±0.1	1.25±0.15	1.6±0.2	2.0±0.2	2.4±0.2	2.8±0.2

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.



HTC Series Sp	ecification 8	& Test Condition	
Item	Speci	ification	Test Condition
Operation Temperature	-55 to +125℃		
Visual	No Abnormal I	Exterior Appearance	Visual Inspection
Capacitance	Within The Sp	ecified Tolerance	Frequency Voltage
Dissipation Factor	Rated Voltage D.F. (max.)	25V 1.2% 2.0%	1KHz±10% 1.0±0.2Vrms
Insulation Resistance	10,000M $\Omega$ or (C in Farad)	500/C $\Omega$ whichever is smaller.	Applied Voltage : Rated Voltage Charge Time : 60sec. Current is limited to less than 50mA
Dielectric Strength	No dielectric b breakdown	oreakdown or mechanical	250% of the rated voltage for 1 to 5 sec. Current is limited to less than 50mA.
Temperature Capacitance Coefficient	Temperature I  -55°C ~ +12  -55°C ~ +20	<u>5°C</u> <u>≤ ± 15%</u>	(C2-C1)/C1 × 100% C1:Capacitance at Standard Temperature(25°ℂ) C2:Capacitance at Test Temperature
Adhesive Strength of Termination	No indication of terminal electron	of peeling shall occur on the rode.	A 5N·f ( $\approx$ 0.5Kg·f) pull force shall be applied for 10±1 sec.
Resistance to Flexure of Substrate	more than the	al damage or change capacitanc following table. Change : $\leq \pm 12.5\%$ of initial value	1.0 mm/sec. ■ R230 , ★ Rending
Solderability		% of the terminal surface is to be y, so metal part does not come e .	Solder Temperature : 245±5°C  Dip Time : 5± 0.5 sec.  Immersing Speed : 25±10% mm/s  Solder : H63A  Flux :Rosin  Preheat : At 80~120 °C For 10~30sec.
Resistance To Soldering Heat	Appearance	No mechanical damage shall occur	Preheat : at 150±10°C for 60~120sec.  Dip : solder temperature of 260±5°C
	Capacitance	Cap. change within ±7.5% of initial value	<ul> <li>Dip Time: 10 ± 1sec.</li> <li>Immersing Speed: 25±10% mm/s</li> <li>Solder: H63A</li> </ul>
	Tan $\delta$ (D.F.)	To satisfy the specified initial value	Flux :Rosin  Measure at room temperature after cooling for  48 ± 4 Hours
	Insulation Resistance	To satisfy the specified initial value	_
	Dielectric Strength	To satisfy the specified initial value	





Item	Speci	fication	est Condition										
Temperature Cycle	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour deage at 150 +0/-10 °C before initial measurement.										
	Capacitance	Cap. change within $\pm 7.5\%$ of initial value	Capacitor shall be subjected to five cycles of the temperature cycle as following:										
	Tan $\delta$ (D.F.)	To satisfy the specified initial value	Step         Temp.(°C)         Time(min           1         Min Rated Temp.(-55)+0/-3         30										
	Insulation Resistance	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.(+125)+3/-0 30 4 25 3										
			Measure at room temperature after cooling for 48 $\pm 4$ Hours										
Humidity	Appearance	No mechanical damage shall occur	Capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measure.										
	Capacitance	Cap. change within ±12.5% of initial value	Temperature : 40 $\pm$ 2 $^{\circ}$ C Relative Humidity : 90 ~95%RH										
	Tan $\delta$ (D.F.)	50V         25V           max. 3.5%         max. 5.0%	Test Time : 500 +12/-0 hr										
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Measure at room temperature after cooling for $48 \pm 4$ Hours										
Humidity Loading	Appearance	No mechanical damage shall occur	Capacitors applied DC voltage of the rated voltage is applied for one hour at maximum										
_	Capacitance	Cap. change within ±12.5% of initial value	operation temperature±3℃ then shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.										
	Tan $\delta$ (D.F.)	50V 25V max. 3.5% max. 5.0%	Applied Voltage :Rated Voltage Temperature : 40±2°C Relative Humidity : 90 ~ 95%RH										
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller. (C in Farad)	Test Time: 500 +12/-0Hr Current Applied: 50 mA Max.										
			Measure at room temperature after cooling for 48 $\pm$ 4 Hours										
High Temperature Load (Life Test)	Appearance	No mechanical damage shall occur	Capacitors applied DC voltage of 200% the rated voltage is applied for one hour at maximum operation temperature±3℃ then										
(Life rest)	Capacitance	Cap. change within $\pm 15\%$ of initial value	shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.										
	Tan $\delta$ (D.F.)	50V 25V max. 3.5% max. 5.0%	Applied Voltage :200% of Rated Voltage Temperature : 125 $^{\circ}$ C										
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Current Applied : 60 mil ( max.										
			Measure at room temperature after cooling for 48 $\pm$ 4 Hours										





## Ceramic Disc Capacitors [ High Voltage Disc Capacitor ]

## **HDC** Series – 1KVdc to 6KVdc



HDC Series (ceramic disc capacitors) are ideal for use in general electronic products with voltage ratings from 1KV to 6KV.

### **♦** Features

- Wide operation temperature
- Low loss at wide range of frequency
- High reliability
- RoHS compliant

### Applications

- Suitable for LAN/WLAN interface
- Ballast circuit of back-lighting inverter
- DC-DC converters,
- Snubber circuit of switching power supplies
- Modems & communication

### **♦** Summary of Specification

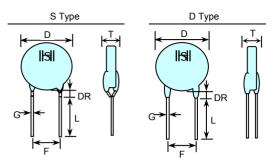
Operation Temperature	NPO/SL : -55~+125 °C										
Operation remperature											
	X7R/Y5P/Y5S : -55~+125°C										
	Y5U/Y5V : -25~+105°C										
Capacitance Range	2pF to 47nF										
Rated Voltage	1KVdc to 6KVdc										
Temperature Coefficient	NPO : ≤ ± 30ppm/ °C , -55~+125 °C (EIA Class I )										
	SL: +350 ~ -1000ppm/ °C , -25~+85 °C (EIA Class I)										
	Y5S :( N3300 ) ≤ ± 22% , -25~+85 °C										
	X7R ∶≤ ± 15% , -55~+125 °C (EIA Class II )										
	Y5P:≤ ± 10% ;Y5U:+22%/-56% ;Y5V:+22%/-82% ,-25~+85 °C(EIA Class II)										
Dissipation Factor :	Please see HEC specification data sheet										
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller										
Aging	NPO:0%; SL:1.5% per decade of time										
	X7R, Y5P, Y5S: 3.5 % per decade of time										
	Y5U: 5.0 %; Y5V:7.5% per decade of time										
Dielectric Strength	V≤ 2KV : 200% Rated Voltage										
	3KV : 175% Rated Voltage										
	6KV : 150% Rated Voltage										

HDC	S	3R0	С	602	7	Α	Α
Product Code  HDC: Ceramic Disc Capacitor	Ex.: N:NPO S:SL L:Y5S X:X7R P:Y5P	Capacitance Unit: pF Ex.: 2R0:2pF 100:10x10° 151:15x10¹	Tolerance  Ex.: C:+/-0.25pF D:+/-0.5pF H:+/- 3% J: +/- 5% K: +/- 10%	Ex.: 102:1000Vdc 202:2000Vdc 302:3000Vdc 602:6000Vdc	Ex.: 5:5.00mm 6:6.35mm 7:7.50mm A:10.0mm B:12.5mm	Packaging  Ex.: H:3.1mm C:3.5mm S:5.0mm M:10.0mm L:25.0mm min.	Lead Shape Style Ex.: S Type 1: $\varphi$ =0.50mm 2: $\varphi$ =0.60mm 3: $\varphi$ =0.65mm 4: $\varphi$ =0.80mm
	Y:Y5V E:Y5U		M: +/- 20%			T: Taping Reel A: Ammo Box	D Type 9: $\varphi$ =0.50mm A: $\varphi$ =0.60mm B: $\varphi$ =0.65mm C: $\varphi$ =0.80mm



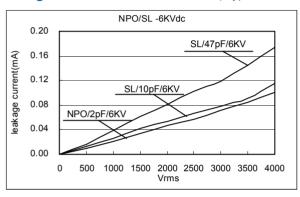


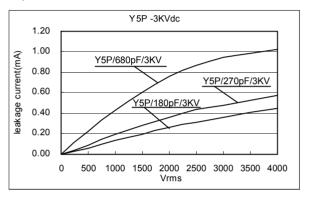
### **♦ Dimension**



Code		Dimension												
D		Ф20.5mm max.												
F	5.0±1.0 mm	7.50±1.5 mm	10.0±2.0 mm	12.5±2.0 mm										
G	0.5±0.	1mm / 0.6±0	0.8±	±0.1mm										
Т		8.0mr	m max.											
DR		4.0mr	m max.											

### ◆ Leakage Current Characteristic (Typical Reference)





### ◆ Capacitance Range

Dielectric .															Ca	pac	itar	nce	Rai	nge	!												$\Box$
Characteristic	Voltage	1R5	2R0	3R0	4R0	5R0	6R0	7R0	8R0	9R0	100	120	150	180	220	270	330	390	470	560	680	820	101	121	151	181	221	271	331	391	471	561	681
NPO	3KV																																
NEO	6KV																																
	2KV																																
SL	3KV																																
	6KV																																
Y5S	3KV																																
133	6KV																																
Dielectric	\		Capacitance Range												T																		
Characteristic	Voltage	101	121	151	181	221	271	331	391	471	561	681	821	102	122	152	182	222	272	332	392	472	562	682	822	103	153	183	223	273	333	393	473
X7R	2KV																																
A/K	3KV																																
	1KV																																
Y5P	2KV																																
	3KV																																
	1KV																																
Y5U	2KV																																
	3KV																																
	1KV																																
Y5V	2KV																																
	3KV																																

■ Other capacitance and voltage rating are available. Please contact HEC.





Item		Specification		Test (	Condition		
Operating Temperature Range	Char. NPO(N) SL(S) Y5S(L) X7R(X) Y5P(P) Y5U(E) Y5V(Y)	Operation -55°C ~ +12 -25°C ~ +10 -25°C ~ +10	25°C 25°C 25°C 25°C 25°C				
Capacitance	Within specifie	d tolerance.	-	Char.	Frequer	ncy V	oltage
Quality Factor	Class I (NPO More Than 30 30pF & Below		(C:Capacitance)	NPO/SL Y5S/X7R/Y5P Y5U/Y5V	1MHz±10 1KHz±10 1KHz±10	0%	Vrms max
Dissipation Factor		)/Y5P(P):D.F.≦ ′):D.F.≦5.0%	2.5%	The measurement $25~^{\circ}\mathrm{C}$ .	ent at referenc	e temper	ature
Insulation Resistance	10,000M $\Omega$ or	500/C $\Omega$ whichev	rer is smaller (C: in Farad)	Applied Voltage Charge Time : ( Is applied less t	60±5sec.	rent.	
Dielectric Strength	Between Lead Wires	No Failure		V≤2KV:200% of V≤3KV 175% of V≤6KV 150% of For 1~5 sec. Current is limite	Rated Voltag Rated Voltag	e e	
	Body Insulation	No Failure		The capacitor is balls of diamete short circuited is AC1250Vrms (N (Y5S/X7R/Y5P/between capacit Current is limited	r 1mm so that kept about 2 (PO/SL) [DC1 (Y5U/Y5V)] is a or lead wires	each leamm off th .3KV applied fo and smal	d wire, e ball and or1 to 5s.
Temperature Capacitance Coefficient	NPO(N)         -55           SL(S)         -30           Y5S(L)         -30           X7R(X)         -55           Y5P(P)         -30           Y5U(E)         -30	0: C ~ + 125 ° C	ap.Change ±30ppm/ °C 350~ -1000 ppm 22% 15% 10% 22 ~ -56% 22 ~ -82%	Class I (NPO/SI [C2-C1/C1(T Class II (X7R/Y5 (C2-C1)/C1 > T1:Standard Tel T2:Test Temper C1:Capacitance C2:Capacitance	2-T1)] × 100% P/Y5U/Y5V):  100% mperature(25° ature at Standard	்ட) Гemperat	ure
Strength of Terminal		ad wire shall not be declarated and the declarated		Nominal cross section area (mm)	Wire Diameter (mm)	Tensile Force (N)	Holding Time (s)
				0.07-0.2 Over 0.2-0.5	0.3-0.5 over0.5-0.8	<u>5</u>	10 ±1
	•	ad wire shall not b d capacitor shall r		Nominal cross section area (mm)	Wire Diameter (mm)	Tensile Force (N)	Mass of Weight (Kg)
				0.07-0.2 Over 0.2-0.5	0.3-0.5 over0.5-0.8	2.5 5	10 ±1





Item		Specification	Test Condition
Solderability of leads		5% of the circumferential surface older shall be covered with new	Solder Temperature : 235±5°C Dip Time : 2 ± 0.5 sec. Solder: H60A or H63A Flux: Ethanol solution of Rosin (25wt%) Immersion depth: 1.5 to 2mm Immersion speed: 25±2.5mm/s
Resistance to Soldering Heat	Appearance  Capacitance  Withstand Voltage (Between Terminal)	No mechanical damage shall occur  Class I (NPO/SL): Within $\pm 2.5\%$ or $\pm 0.25$ pF whichever is larger of initial value Class II (Y5S/X7R/Y5P/Y5U/Y5V): Char. Cap.Change Y5S(L) $\leq \pm 5\%$ of initial value X7R(X) $\leq \pm 5\%$ of initial value Y5P(P) $\leq \pm 5\%$ of initial value Y5U(E) $\leq \pm 20\%$ of initial value No dielectric breakdown or abnormality	The lead wire shall be immersed into the melted solder of $350\pm10^{\circ}\mathbb{C}$ (body diameter 5.0mm max $260\pm5^{\circ}\mathbb{C}$ ) up to about 1.5 to 2.0mm from the main body for $3.5\pm0.5$ sec. (body diameter 5.0mm max $5\pm0.5$ sec.) Class I:  Measurement under room temperature after test for 1 to 2Hr Class II:  The capacitor shall be pre-treatment stored at $85\pm2^{\circ}\mathbb{C}$ for 1hr, then placed at room temperature for $24\pm2$ hr before initial measurements.  The capacitor shall stored for $24\pm2$ hr at room temperature.
Temperature and Dipping Cycle	Appearance Capacitance $ Q / \operatorname{Tan} \delta $ Insulation Resistance	No mechanical damage shall be occur  Class I (NPO/SL): Within 5.0% or $\pm 0.5$ pF whichever is larger of initial value  Class II (Y5S/X7R/Y5P/Y5U/Y5V): Char. Cap.Change  Y5S(L) $\leq \pm 10\%$ of initial value  X7R(X) $\leq \pm 10\%$ of initial value  Y5P(P) $\leq \pm 10\%$ of initial value  Y5U(E) $\leq \pm 30\%$ of initial value  V5V(Y) $\leq \pm 30\%$ of initial value  Class I (NPO/SL): More Than 30pF : Q $\geq$ 350 30pF & Below : Q $\geq$ 275+2.5C  Class II: Y5S/X7R/Y5P : D.F. $\leq$ 5.0% Y5U/Y5V : D.F. $\leq$ 7.5%  1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C: in Farad)	Capacitor shall be subjected to five cycles of the temperature cycle as following:
	Withstand Voltage (Between Terminal)	No dielectric breakdown or abnormality	temperature.





Item		Specification	Test Condition
Humidity (Under Steady State)	Appearance	No mechanical damage shall occur	Temperature : 40 $\pm$ 2 $^{\circ}$ C Relative Humidity : 90 ~95%RH
	Capacitance	Class I (NPO/SL): Within 5.0% or $\pm$ 0.5pF whichever is larger of initial value Class II (Y5S/X7R/Y5P/Y5U/Y5V): Char. Cap.Change $\frac{Y5S(L)}{X7R(X)} \stackrel{\leq \pm 10\% \text{ of initial value}}{\leq \pm 10\% \text{ of initial value}}$ $\frac{Y5P(P)}{Y5U(E)} \stackrel{\leq \pm 10\% \text{ of initial value}}{\leq \pm 30\% \text{ of initial value}}$ $\frac{Y5V(Y)}{\leq \pm 30\% \text{ of initial value}}$	Test Time: 500 +24/-0 hr  Class I:  Measurement under room temperature after test for 1 to 2Hr  Class II:  The capacitor shall be pre-treatment stored at 85±2°C for 1hr, then placed at room temperature for 24±2hr before initial measurements.  The capacitor shall stored for 24±2hr at room
	Q / Tan $\delta$	Class I (NPO/SL):  More Than 30pF : $Q \ge 350$ 30pF & Below : $Q \ge 275+2.5C$ Class II:  Y5S/X7R/Y5P : D.F. $\le 5.0\%$ Y5U/Y5V : D.F. $\le 7.5\%$ 1,000M $\Omega$ or 50/C $\Omega$ whichever is	temperature
	Resistance	smaller. (C: in Farad)	
Humidity Loading	Appearance	No mechanical damage shall occur	Temperature : 40± 2 °C Relative Humidity : 90 ~95%RH
	Capacitance	Class I (NPO/SL): Within 7.5% or $\pm 0.75pF$ whichever is larger of initial value Class II (Y5S/X7R/Y5P/Y5U/Y5V): Char. Cap.Change $\frac{Y5S(L)}{X7R(X)} \leq \pm 10\% \text{ of initial value}$ $\frac{X7R(X)}{Y5P(P)} \leq \pm 10\% \text{ of initial value}$ $\frac{Y5P(P)}{Y5U(E)} \leq \pm 30\% \text{ of initial value}$ $\frac{Y5V(Y)}{Y5V(Y)} \leq \pm 30\% \text{ of initial value}$	Test Time: 500 +24/-0 hr  Applied Voltage: 100% of Rated Voltage Is applied less than 50mA current.  Class I:  Measurement under room temperature after test for 1 to 2Hr  Class II:  The capacitor shall be pre-treatment stored at 85±2℃ for 1hr, then placed at room temperature for 24±2hr before initial measurements.
	Q / Tan δ	Class I (NPO/SL): More Than 30pF : $Q \ge 200$ 30pF & Below : $Q \ge 100 + (10/3)C$ Class II : Y5S/X7R/Y5P : D.F. $\le 5.0\%$ Y5U/Y5V : D.F. $\le 7.5\%$	The capacitor shall stored for 24±2hr at room temperature
	Insulation Resistance	500M $\Omega$ or 25/C $\Omega$ whichever is smaller. (C: in Farad)	





Item		Specification	Test Condition
High Temperature Load	Appearance	No mechanical damage shall occur	Applied Voltage: 150% of rated voltage However:
(Life Test)	Capacitance ${\bf Q}  /  {\sf Tan}  \delta$	Class I (NPO/SL): Within 5.0% or $\pm 0.5$ pF whichever is larger of initial value  Class II (Y5S/X7R/Y5P/Y5U/Y5V): Char. Cap.Change  Y5S(L) $\leq \pm 20\%$ of initial value X7R(X) $\leq \pm 20\%$ of initial value Y5P(P) $\leq \pm 20\%$ of initial value Y5U(E) $\leq \pm 20\%$ of initial value Y5U(E) $\leq \pm 20\%$ of initial value Class I (NPO/SL): More Than 30pF: Q $\geq 350$ 30pF & Below: Q $\geq 275+2.5$ C Class II:	The rated voltage is more than 5KVDC, applied voltage of 120% rated voltage.  Temperature: max. operation temperature Test Time: 1000 +48/-0 Hr Is applied less than 50mA current.  Class I:  Measurement under room temperature after test for 1 to 2Hr.  Class II:  The capacitor shall be pre-treatment stored at 85±2℃ for 1hr, then placed at room temperature for 24±2hr before initial measurements  The capacitor shall stored for 24±2hr at room temperature.
	Insulation Resistance	Y5S/X7R/Y5P: D.F. $\leq$ 5.0% Y5U/Y5V: D.F. $\leq$ 7.5% 1000M $\Omega$ or 50/C whichever is smaller.	temperature.
Vibration	Appearance	No mechanical damage shall occur	The capacitor shall firmly be solded to the supporting terminal and vibration which is 10 to
	Capacitance	To satisfy the specified initial value	55Hz in the vibration frequency range 1.5mm in total amplitude and about 1mm in the rate of vibration change from 10Hz to 55Hz and back to
	Q / Tan $\delta$	To satisfy the specified initial value	10Hz is applied for a total of 6 hours;
			2 hours each in three mutually perpendicular directions.





# Ceramic Disc Capacitors [ High Voltage Disc Capacitor ]

## **HDC** Series – 10KVdc to 20KVdc



HDC Series (ceramic disc capacitors) are ideal for use in general electronic products with voltage ratings from 10KV to 20KV.

•		- 4	
•	-e:	atu	res

- Wide operation temperature
- ☐ Low loss at wide range of frequency
- ☐ High reliability
- RoHS compliant

### Applications

- ☐ Suitable for LAN/WLAN interface
- ☐ Ballast circuit of back-lighting inverter
- □ DC-DC converters,
- ☐ Snubber circuit of switching power supplies
- Modems & communication
- ☐ High voltage power supply

### **♦** Summary of Specification

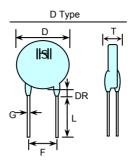
Operation Temperature	NPO/SL : -55~+125 ℃
	X7R/Y5P/Y5S : -55~+125°C
	Y5U/Y5V : -25~+105°C
Capacitance Range	10pF to 10,000pF
Capacitance	1KHz ± 20% /osc: 1 to 5Vrms ,and 20 ℃
Rated Voltage	10KVdc to 20KVdc
Temperature Coefficient	NPO : ≤ ± 30ppm/ °C , -55~+125 °C (EIA Class I )
	SL: +350 ~ -1000ppm/ °C , -25~+85 °C (EIA Class I)
	Y5S (N3300) ±22% , -25~+85 ℃
	X7R : ≤ ± 15% , -55~+125 °C (EIA Class II )
	Y5P:≤ ± 10% ;Y5U:+22%/-56% ;Y5V:+22%/-82% ,-25~+85 °C(EIA Class II)
Dissipation Factor	Please see HEC specification data sheet
Insulation Resistance	10GΩ at 500VDC 1minute
Aging	NPO:0%; SL:1.5% per decade of time
	X7R, Y5P, Y5S: 3.5 % per decade of time
	Y5U: 5.0 %; Y5V:7.5% per decade of time
Dielectric Strength	150% Rated Voltage

HDC	L	102	M	123	В	L	С
Product Code	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Lead Space	Packaging	Lead Shape Style
HDC: Ceramic Disc	Ex.: N:NPO	Ex.: 102:10x10 <sup>2</sup>	Ex.: C:+/-0.25pF	Ex.: 103:10KVdc	Ex.: A: 10.0mm	Ex.: H:3.1mm	Ex.: D Type
Capacitor	S:SL L:Y5S	103:10x10 <sup>3</sup>	D:+/-0.25pf D:+/-0.5pF J: +/- 5%	123:12KVdc 153:15KVdc	B: 12.5mm	C:3.5mm S:5.0mm	9: $\varphi$ =0.50mm A: $\varphi$ =0.60mm
	X:X7R P:Y5P		K: +/- 10% M: +/- 20%	203:20KVdc		M:10.0mm L:25.0mm min.	B: $\varphi$ =0.65mm C: $\varphi$ =0.80mm
	E:Y5U Y:Y5V						



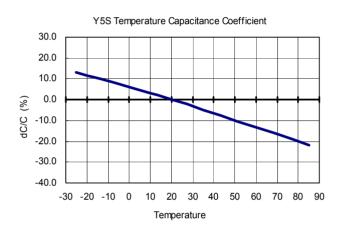


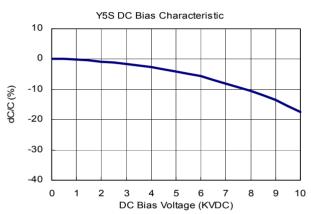
### **♦** Dimension



Code		Dime	ension	
Code		DT	ape	
D		Ф20.5n	nm max.	
F	10.0±2 mm	า		12.5±2 mm
G	0.6±0.1mm max.	0.65±0.1	mm max.	0.8±0.1mm max.
Т		10.0m	m max.	
DR		5.0mr	n max.	

### ◆ Leakage Current Characteristic (Typical Reference)





### **♦** Capacitance Range

Dielectric															Ca	pac	itar	псе	Ra	nge	:												$\neg$
Characteristic	Voltage	100	120	150	180	220	270	330	390	470	560	680	820	101	121		181	221				471	561	681	821	102	152	222	332	472	682	103	123
	10KV																																
NPO	15KV																																
	20KV																																
	10KV																																
SL	15KV																																
	20KV																																
	10KV																																
Y5S	12KV																																
	15KV																																
	10KV																																
Y5P	12KV																																
	15KV																																
	10KV																																
Y5U	12KV																																
	15KV																																
	10KV																																
Y5V	12KV																																
	15KV																																

■ Other capacitance and voltage rating are available. Please contact HEC.





## Ceramic Disc Capacitors [ Safety Disc Capacitors – X1Y1& X1Y2]

### **SDC** Series





This specification applies to the following Safety Standards that are recognized for Ceramic Capacitors used in Electronic Appliances.

These parts are compliant to EN60384-14, IEC60384-14, UL 1414, and C22.2 No.1 standards.

### ◆ Features

- ☐ Operating temperature range guaranteed up to 125°C(UL/CSA:85°C)
- Safety capacitors specially designed for use in Modem, Facsimile, Telephone and other electronic equipment for lighting and surge protection, EMI filter and isolation.
- ☐ The series is recognized by UL / CSA / TUV
- ☐ Coated with Flame-retardant epoxy resin (conforming to UL 94-0 standards)
- ☐ Suitable for automatic insertion
- □ RoHS compliant

### **◆** Application

- □ Safety capacitors specially designed for use in Modem, Facsimile, Telephone and other electronic equipment for lighting and surge protection, EMI filter and isolation.
- ☐ Interference suppressor for AC line of electronic equipment

### ◆ Related Standards and Certificate Numbers

Certificated Body	Relation Standard	Number	Rated Voltage
TUV	IEC 60384-14 : 2005 (3 <sup>nd</sup> Edition) EN 60384-14 : 2005	R50101887	X1:400 VAC Y2:250 VAC
	EN 132400 : 1994+A2:1998+A3:1998+A4:2001	R50101887	X1:440 VAC Y1:250 VAC
		R50101887	X1:440 VAC Y2:400 VAC
UL	UL 1414	E300818	SDC-Y2 250 VAC
	Edition 5		SDC-Y1L 250 VAC
			SDC-Y1H 250 VAC
CUL/CSA	CSA :C22.2 NO.1	E300818/1686156	250 VAC
ENEC Report	EN 60384-14 : 2005	28203507 002	

SDC	Р	101	K	50	2	7	Α	2

Product Code	Dielectric	Capacitance Unit : pF	Tolerance	Class	Rated Voltage	Lead Space	Lead Length	Lead Shape Style
SDC: Safety Disc Ceramic Capacitor	Ex.: N: NPO S: SL X: X7R P: Y5P Y: Y5V E: Y5U	Ex.: 100 : 10x10º 151 : 15x10¹	Ex.: J: +/-5.0% K: +/- 10% M: +/- 20%	Ex.: 10 : X1/Y1 50 : X1/Y2	Ex.: 2:     Y Cap:250V     X Cap:400V  3:     Y Cap:250V     X Cap:440V  4:     Y Cap:440V     X Cap:440V	Ex.: 5: 5.00mm 6: 6.35mm 7: 7.50mm A: 10.0mm B: 12.5mm	Ex.: H:3.1mm C:3.5mm S:5.0mm M:10mm L:25mm min T:Tape Reel A:Ammo Box	S Type 1: $\varphi$ =0.50mm 2: $\varphi$ =0.60mm 3: $\varphi$ =0.65mm 4: $\varphi$ =0.80mm K Type 5: $\varphi$ =0.50mm 6: $\varphi$ =0.60mm 7: $\varphi$ =0.65mm 8: $\varphi$ =0.80mm D Type 9: $\varphi$ =0.50mm B: $\varphi$ =0.65mm C: $\varphi$ =0.65mm

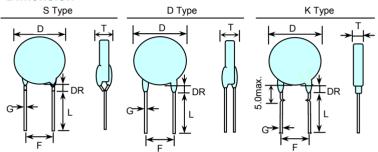




### Summary of Specification

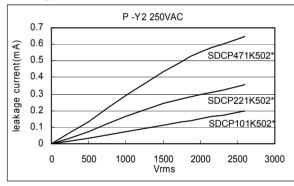
Operation Temperature	-25~+125 °C
Dielectric Strength	X1:440 VAC / Y1:250 VAC : 4000VAC for 1 minute
	X1:440 VAC / Y1:400 VAC : 4000VAC for 1 minute
	X1:400 VAC / Y2:250 VAC : 2600VAC for 1 minute
Capacitance Range	X1:440 VAC / Y1:250 VAC : 2pF to 4700pF
	X1:440 VAC / Y1:400 VAC : 2pF to 4700pF
	X1:400 VAC / Y2:250 VAC : 2pF to 10,000pF
Dissipation Factor	Class I , NPO/SL : Q ≥ 300 at 1MHz/1Vrms
	Class II , Y5P :DF ≤ 2.5% ; Y5U/Y5V :DF ≤ 5.0% at 1KHz/1Vrms
Insulation Resistance	10,000MΩ min. at 500VDC

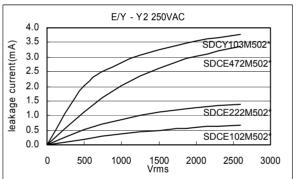
### **♦ Dimension**



Code	Dimension							
D	Ф16.0mm max.							
F	5.0±1.0 7.50±1.5 10.0±2.0 12.5±2.0 mm mm							
G	0.5±0.	0.5±0.1mm / 0.6±0.1mm / 0.8±0.1mm						
Т	8.0mm max.							
DR		4.0mm max.						

### ◆ Leakage Current Characteristic (Typical Reference)





### **♦** Capacitance Range

		1	Capacitance Range																														
01	L		,											Ca	Jac	ılan	ce	Ran	ge								_						
Class	TC	2R0	3R0	5R0	8R0	100	150	220	330	470	089	101	121	151	181	221	271	331	391	471	561	681	102	152	182	202	222	332	392	472	682	822	103
	NPO	8/5	8/5	8/5	95	10/5																											
X1: 400VAC	SL				8/5	8/5	85	8/5	85	8/5	85																						
Y2: 250VAC	Y5P				8/5	8/5	8/5	8/5	8/5	8/5	8/5	8/7	8/7	8/7	87	8/7	8/7	8/7	8/7	8/7	97	97	107										
	Y5U																						8/7	97	107	107	107	12/7	13/7	14/7			
	Y5V																						8/7	8/7			97	107		12/7	14/7	15/7	16/7
	NPO	8/8	8/8	8/8																													
X1: 440VAC	SL				8/8	8/8	8/8	9/8	9/8	9/8	10/8																						
Y1: 250VAC	Y5P											8/8		8/8		8/8		9/8	9/8	9/8		10/8	12/8										
	Y5U																						8/8	9/8	10/8	10/8	11/8	13.5/8	14:5/8	15.5/8			
	NPO	8/8	8/8	8/8																													
X1: 440VAC	SL				8/8	8/8	8/8	9/8	9/8	9/8	10/8																						
Y1: 400VAC	Y5P											8/8		8/8		8/8		9/8	9/8	9/8		10/8	12/8										
	Y5U																						8/8	9/8	10/8	10/8	11/8	13.5/8	14.5/8	15.5/8			

Body Diameter(max.) / Body Thickness (max.)





Item	Specificatio	n	Test	Condition	
Operation Temperature	Char.  NPO(N)/SL(S)/Y5P(P)  Y5U(E)/Y5V(Y)	Operation Temp. -25°C ~ +125°C -25°C ~ +105°C			
Capacitance	Within specified tolerance.		Char.	Frequency	Voltage
Quality Fact/or & Dissipation Factor	Char. NPO(N)/SL(S) Y5P(P)	Q / D.F.(max.) Q≥300 D.F. ≤2.5%	NPO/SL Y5P/Y5U/Y5V The measurement	1MHz±10% 1KHz±10% ent at reference te	5.0Vrms max
	Y5U(E) /Y5V(Y)	D.F. ≦5.0%	<b>25</b> ℃.		'
Insulation Resistance(I.R.)	10,000M $\Omega$ min.		Applied Voltage Charge Time : Is applied less t		t.
Dielectric Strength	Between lead No wires	o failure	AC2.6KV(for Y2 Class) are appli	shall not be dama 2 Class) and AC40 ed between the le ed less than 50mA	000V (for Y1 ad wires for
	Body insulation No	o failure	connected toge to the right, a m around the bod of about 3 to 4r capacitor shall with metal balls VAC 2600Vrms	als of the capacito other. Then, as sho netal foil shall be control of the capacitor of about 1 mm diactics is applied for 60s wires and metal back current.	own in the figur losely wrapped to the distance ninal. Then, the container filled ameter. Finally sec. between the
Temperature Characteristic	Char.       Temp. Ran         NPO(N)       -55 °C ~+12€         SL(S)       -55 °C ~+85         Y5P(P)       -25 °C ~+85         Y5U(E)       -25 °C ~+85         Y5V(Y)       -25 °C ~+85	5 °C 0±60ppm/°C °C +350~-1000% °C ±10% °C +22%~ -56%	at each step sp Step.	e measurement sl ecified as followin Temperatu _/Y5P/Y5U/Y5V) +25±2 -25±2 +25±2 +85±2 +25±2	g
Robustness of Termination		not separate from the hall not be broken.	specimen is he that the axis of tensile force of termination in the	ation in its normal ld by its body in so the termination is 10N shall be appl he direction of its action away from the	position the uch a manner vertical the ied to the axis and
	Bending Lead wire shall capacitor shall	not separate from the not be broken.	specimen is he that the axis of mass applying from the end of specimen is the 3 sec., through in the vertical pinitial position coperation const	ation in its normal ld by its body in su the termination is a force of 5N is the termination. The inclined within a an angle of a appulane and then return the same perititutes one bend. Colowed by a second on.	uch a manner vertical: a en suspended The body of the a period of 2 to proximately 90 urned to its od of time; this one bend



Item		Specification	Test Condition				
Solderability of leads		eall be soldered uniformly and e axial direction over 3/4 of the ce direction.	Solder temperature: $235 \pm 5^{\circ}$ C Immersion time: $2 \pm 0.5$ sec The depth of immersion : $1.5 \sim 2.0$ mm				
Soldering	Appearance	No marked defect.	Solder temperature: 350±10℃ or 260±5℃				
Effect	Capacitance	Within±10%	Immersion time:3.5±0.5sec(10±1sec.for 260±5°C				
	I.R.	1000M $\Omega$ min.	The depth of Thermal Capacitor immersion is Insulating				
	Dielectric Strength	Per Item 5.	up to about  1.5~2.0mm from the root of lead wires.  Pre-treatment:  Capacitor shall be stored at 85±2°C for 1 hour then placed at room condition for 24±2 hours before initial measurements.  Post-treatment:				
			Capacitor shall be stored for 1 to 2 hours at room condition.				
Humidity (Under	Appearance	No marked defect	Set the capacitor for $500\pm12$ hours at $40\pm2^{\circ}$ C, in 90 to 95% humidity.				
Steady State)	Capacitance	$\begin{array}{ll} \text{Char.} & \text{Cap. change} \\ \hline \text{NPO(N)} & \leq \pm 5\% \text{ of initial value} \\ \hline \text{SL(S)} & \leq \pm 5\% \text{ of initial value} \\ \hline \text{Y5P(P)} & \leq \pm 10\% \text{ of initial value} \\ \hline \text{Y5U(E)} & \leq \pm 15\% \text{ of initial value} \\ \hline \text{Y5V(Y)} & \leq \pm 30\% \text{ of initial value} \\ \hline \end{array}$	Pre-treatment: Capacitor shall be stored at 85±2℃ for 1 hour, then placed at room condition for 24±2 hours before initial measurements.  Post-treatment: Capacitor shall be stored for 1 to 2 hours at room condition.				
	Q / Tan $\delta$	Class I (NPO/SL) $Q \ge 135$ Class II $Y5P: DF \le 5.0\%$ $Y5U/Y5V: DF \le 7.5\%$					
	Insulation Resistance	3,000M $\Omega$ min.					
	Dielectric Strength	Pre Item 5.					
Humidity	Appearance	No marked defect	Apply the rated voltage for 500±12 hours				
Loading	Capacitance	$ \begin{array}{c c} \hline \text{Char.} & \text{Cap. change} \\ \hline \hline \text{NPO(N)} & \leq \pm 5\% \text{ of initial value} \\ \hline \text{SL(S)} & \leq \pm 5\% \text{ of initial value} \\ \hline \hline \text{Y5P(P)} & \leq \pm 10\% \text{ of initial value} \\ \hline \text{Y5U(E)} & \leq \pm 15\% \text{ of initial value} \\ \hline \text{Y5V(Y)} & \leq \pm 30\% \text{ of initial value} \\ \hline \end{array} $	at 40±2°C, in 90 to 95% humidity.  Pre-treatment: Capacitor shall be stored at 85±2°C for 1 hour, then placed at room condition for 24±2 hours before initial measurements.  Post-treatment:				
	Q / Tan $\delta$	Class I (NPO/SL) $Q \ge 135$ Class II $Y5P: DF \le 5.0\%$ $Y5U/Y5V: DF \le 7.5\%$	Capacitor shall be stored for 1 to 2 hours at room condition.				
	Insulation Resistance	3,000M $\Omega$ min.					
	Dielectric Strength	Pre Item 5.					

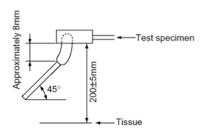




Item	Specification	Test Condition
Endurance (Life Test)	Appearance No marked defect.  Capacitance $\frac{NPO(N)}{SL(S)} \stackrel{\leq \pm 5\% \text{ of initial valu}}{\stackrel{\leq \pm 20\% \text{ of initial valu}}{\stackrel{\leq \pm 30\% \text{ of initial valu}}{$	times below. After impulse testing the capacitors are applied to life test.  90  T1=1.2 µ s=1.67T
Flame Test	The capacitor flame discontinue as follows  Cycle Time 1~4 30sec. Max. 5 60sec. max.	The capacitor shall be subjected to the flame below for 15 sec. then removed for 15 sec, for 5 cycles.  Capacitor Flame  Gas Burner
Passive Flammability	The burning time shall not be exceeded the 30sec. The tissue paper shall not ignite.	The capacitor under test shall be held in the flame in the position shown, which best promotes burning. Each specimen shall only be exposed once to the flame.

be exposed once to the flame.

Length of flame :12±1mm Gas burner: Length 35mm min. Inside Dia.: 0.5±0.1mm Outside Dia.: 0.9mm max. Gas: Butane gas Purity 95% min. Time of exposure to flame: 30 sec.







Specification **Test Condition** Item Active The cheese-cloth shall not catch fire The specimens shall be individually wrapped in **Flammability** at least one but not more than two complete layers of cheese-cloth The specimens shall be subjected to 20 discharges. The interval between successive discharges shall be 5 sec. The Uac shall be maintained for 2 min. after the last discharge. C1,2:1 $\mu$ F L1-4:1.5mH±20% 16A Rod core choke R :  $100 \Omega \pm 2\%$ , Uac: Ur±5% Cx: Capacitor U<sub>1</sub>: Voltage applied to Ct C3:0.33 µ F±5% 10KV Ct: 3 µ F±5% 10KV Ur : Rated working voltage F: Fuse, Rated 10A **Vibration** Solder the capacitor on P.C. board. Appearance No mechanical damage shall Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies Within the specified tolerance Capacitance from 10Hz to 55Hz and back to 10Hz in about 1 min. To satisfy the specified initial  ${\sf Q}$  /  ${\sf Tan}\,\delta$ value Repeat this for 2 hours each in 3

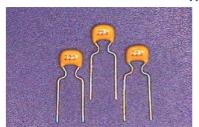


perpendicular directions.



### Radial Dipped Ceramic Capacitors [General Used Capacitor – 6.3V-1KV]

## **RDC** Series



Capacitors with voltage ratings from 6.3V to 1KV

### **♦** Features

- □ Advanced process technology produces thinner layers of ceramic dielectric and offers higher voltage rating and capacitance values
- ☐ Provides good frequency response
- ☐ High reliability
- ☐ RoHS compliant

### Applications

- ☐ Suitable for Automotive Electronics, Power supplies
- ☐ Inverter and Converter
- ☐ Fuel pump , Water pump , Hybrid engine , Door lock , Wiper

### **♦** Summary of Specification

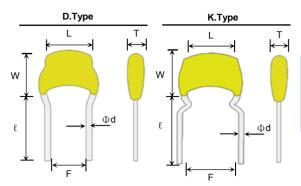
Operation Temperature	NPO,X7R : -55~+125 ℃ ; X5R : -55~+85 ℃ ; Y5V : -30~+85 ℃				
Rated Voltage	6.3Vdc to 1KVdc				
Temperature Coefficient	NPO : $\leq$ ± 30ppm/ $^{\circ}$ C , -55~+125 $^{\circ}$ C (EIA Class $I$ )				
	X7R : ≤ $\pm$ 15% , -55~+125 $^{\circ}$ C (EIA Class ${                                  $				
	X5R : ≤ ± 15% , -55~+85 °C (EIA Class Ⅱ )				
	Y5V : ≤ +22~ -82% , -30~+85 °C (EIA Class Ⅱ )				
Capacitance Range	NPO: 10pF to 220nF				
	X7R : 1000pF to 22uF				
	X5R : 330nF to 100uF				
	Y5V : 0.1uF to 100uF				
Dissipation Factor	Please see RDC specification data sheet				
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller				
Aging	NPO:0%; X7R,X5R: 2.5 % Y5V: 6% per decade of time				
Dielectric Strength	V ≤ 50 : 250% Rated Voltage				
	V<500V :200% Rated Voltage				
	500V ≤ V < 1000V: 150% Rated Voltage				
	1000 ≤ V :120% Rated Voltage				

Product Code	Dielectric	Capacitance Unit : pF	Tolerance	Rated Voltage	Leader Style	Packaging
RDC: Radial Ceramic Chip Capacitor	Ex.: N: NPO X: X7R B: X5R Y: Y5V	Ex.: 2R0:2.0pF 100:10x10 <sup>0</sup> 471:47x10 <sup>1</sup> 102:10x10 <sup>2</sup>	Ex.: C:+/-0.25pF D:+/-0.50pF J :+/- 5% K :+/-10% M:+/-20%	Ex.: 007:6.3Vdc 010:10Vdc 025:25Vdc 050:50Vdc 101:100Vdc 251:250Vdc 631:630Vdc 102:1000Vdc	EX: Size DD:5.5x4.0 ED:5.5x4.5 FD:5.5x4.0 DK:5.5x4.0 EK:5.5x4.5 FK:5.5x4.0	T: Taping &Reel B: Bulk





### **Dimension**



						L	Jnit : mn	n [inches]
TYPE	L (max)	W (max)	T (max)	F	=	-{	)	Φd
D□	4.0 [0.157]	5.5 [0.216]	2.5 [0.098]	2.5±0.8 [0.098]	5.0±1 [0.196]	5.0 [0.196]	25 [0.982]	0.5±0.1 [0.196]
E□	5.5 [0.216]	7.0 [0.275]	4.0 [0.157]	2.5±0.8 [0.098]	5.0±1 [0.196]	5.0 [0.196]	25 [0.982]	0.5±0.1 [0.196]
F□	7.5 [0.294]	8.0 [0.314]	4.0 [0.157]		5.0±1 [0.196]	5.0 [0.196]	25 [0.982]	0.5±0.1 [0.196]

### **♦** Capacitance Range

Capacitain	cc ita		
Dielectric	Туре	Rated	Capacitance Range (pF)
Characteristic	Type	Voltage	7222222222111211211222222222222112112112
	D	50V	
NPO	E	50V	
	F	50V	
Dielectric		Datad	Capacitance Range (pF)
Characteristic	Type	Rated Voltage	70108
		16V	
	D□	25V	
		50V	
		16V	
X7R	ΕΠ	25V	
7,77		50V	
		16V	
	F□	25V	
		50V	
	_	6.3V	
	D	10V	
		6.3V	
X5R	EΠ	10V	
		16V	
		6.3V	
	F	10V	
		6.3V	
		10V	
	D	16V	
		25V	
		50V	
		6.3V	
Y5V		10V	
	EΠ	16V	
		25V	
		50V	
		10V	
	F	16V	
	' 🗆	25V	
		50V	

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





RDC Series Specification & Test Cond	ition
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Item	Specification	Test Condition			
Operation Temperature	Please see HEC specification data sheet for details				
Visual	No abnormal exterior appearance	Visual Inspection			
Capacitance	Within The Specified Tolerance	Class Frequency Voltage			
Quality Factor	Class I (NPO): More Than 30pF : Q $\geq$ 1000 30pF & Below: Q $\geq$ 400+20C (C:Cap., pF)	NPO			
Dissipation Factor	Class II (X7R,X5R,Y5V): Please see HEC specification data sheet for details	$\begin{array}{c cccc} C \leqq 10 uF & 1 KHz \pm 10\% & 1.0 \pm 0.2 Vrms \\ \hline C > 10 uF & 120 Hz \pm 20\% & 0.5 \pm 0.2 Vrms \\ \hline Perform a heat treatment at 150 \pm 5^{\circ}C for 30min. then place room temp. for 24 \pm 2 hr.$			
Insulation Resistance	10,000M $\Omega$ or 500/C $\Omega$ whichever is smaller for rated voltage>10V and greater 100/C $\Omega$ for rated voltage≤10V	Applied Voltage: Rated Voltage Charge Time: 60±5 sec. Charge-Discharge current shall be less than 50mA current			
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	V $\leq$ 50 : 250% Rated Voltage V $<$ 500V : 200% Rated Voltage 500V $\leq$ V $<$ 1000V: 150% Rated Voltage 1000 $\leq$ V :120% Rated Voltage for 1~5 sec. Current is limited to less than 50mA			
Temperature Capacitance Coefficient	Char.         Temp. Range         Cap. Change           NPO (N)         -55°C ~ +125°C         ± 30ppm/°C           X7R (X)         -55°C ~ +125°C         ± 15%           X5R (B)         -55°C ~ +85°C         ± 15%           Y5V (Y)         -30°C ~ +85°C         +22% ~ -82%	Class I:     [C2-C1/C1(T2-T1)] × 100%  Class II:     (C2-C1)/C1 × 100%  T1:Standard Temperature(25°C)  T2:Test Temperature C1:Capacitance at Standard Temperature C2:Capacitance a Test Temperature			
Lead Strength	Tensile No mechanical damage such as lead Strength breakage and loosing.	Pulling strength: 5N Holding time: 10±1s Hold the capacitors to keep the axis			
	Bending No mechanical damage such as lead Strength . breakage or loosening.	<ul> <li>vertical, bend it 90 degrees as shown below and bend back to the original position. This operation shall be done for 2~3s. and repeated for the following times.</li> <li>Bending force: 5N(weight:0.51kg)</li> <li>Test time: 2 times</li> </ul>			
Solderability	Leads shall be covered by new solder more than 75% of its surface	Completely immerse both terminations in solder at 235± 5°C for 2±0.5s Solder : H63A Flux :Rosin Dipping :By 1.5~2.0mm form the root of lead			
Resistance to	Appearance No mechanical damage shall occur	Completely soak both terminations in solder at 250± 5°C for 5±1s			
Soldering Heat	Capacitance Class I (NPO): Within 2.5% or $\pm 0.25$ pF whicheve is larger of initial value Class II	-			
	Q / Tan $\delta$ To satisfy the specified initial value	<u> </u>			
	Insulation To satisfy the specified initial value Resistance	<del>-</del>			



Item		Specification	Test Condition			
Temperature Cycle	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for $48\pm4$ hours at room temperature after one hour heat treatment at $150 + 0/-10$ °C before initial measurement.  Capacitor shall be subjected to five cycles of the temperature cycle as following:  Step Temp.(°C) Time(min)  1 Min Rated Temp.+0/-3 (-55) 30  2 25 3			
	Capacitance	Class I (NPO): Within 2.5% or $\pm 0.25$ pF whichever is larger of initial value Class II X7R,X5R: $\leq \pm 7.5\%$ of initial value Y5V: $\leq \pm 20\%$ of initial value				
	$\overline{Q}$ / $Tan\delta$	see RDC specification data sheet	3 Max Rated Temp.+3/-0 (125) 30			
	Insulation	To satisfy the specified initial	4 25 3			
	Resistance	value	Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours			
Humidity	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment			
	Capacitance	Class I (NPO): Within 5% or $\pm 0.5$ pF whichever is larger of initial value Class II X7R,X5R: $\leq \pm 15\%$ of initial value Y5V: $\leq \pm 30\%$ of initial value	at 150 +0/-10 $^{\circ}$ before initial measurement. Temperature : $40\pm2$ $^{\circ}$ C Relative Humidity : $90 \sim 95\%$ RH Test Time : $500 + 12/-0$ hr Measure at room temperature after cooling for Class I : $24\pm2$ Hours Class II : $48\pm4$ Hours			
	Q / Tan $\delta$	see RDC specification data sheet				
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10	0V			
High Temperature Load	Appearance	No mechanical damage shall occur	Class II capacitors applied DC testing voltage is applied for one hour at maximum operation			
(Life Test)	Capacitance	Class I (NPO): Within 5% or ±0.5pF whichever is larger of initial value	temperature ±3°C then shell be set for 48± 4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage:			
		Class II X7R,X5R : $\leq \pm 15\%$ of initial value Y5V : $\leq \pm 30\%$ of initial value	V≤50Vdc 200%Rated Voltage V≤250Vdc 150%Rated Voltage V< 1KVdc 120%Rated Voltage			
	Q / Tan δ	Class I (NPO): More Than 30pF : $Q \ge 350$ 30pF & Below: $Q \ge 275 + 2.5C$ Class II (X7R,X5R,Y5V): see RDC specification data sheet	V≥1KV 100%Rated Voltage  However:  The rated voltage is 6.3V/10V,applied voltage of 100% Rated voltage.  150% Rated Voltage for C≥1.0uF and 200% Rated Voltage for C < 1.0uF.			
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller for rated voltage>10V and greater 10/C $\Omega$ for rated voltage $\leq$ 10V	Temperature: max. operating temperature Test Time: 1000 +48/-0 Hr Current Applied: 50mA Max Measure at room temperature after cooling for Class I: 24 ± 2 Hours Class II: 48 ± 4 Hours			
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. Board Vibrate the capacitor with amplitude of 1.5mm P-			
	Capacitance	Within the specified tolerance	changing the frequencies from 10Hz to 55Hz and			
	Q / Tan $\delta$	To satisfy the specified initial value	<ul> <li>back to 10Hz in about 1min.</li> <li>Repeat this for 2 hours each in 3perpendicular directions.</li> </ul>			





## Radial Dipped Ceramic Capacitors [Ultra High Voltage Radial Capacitor – 2KV-5KV]

## **RDH** Series



### ◆ Features

- □ Advanced process technology produces thinner layers of ceramic dielectric and offers higher voltage rating and capacitance values
- ☐ Provides good frequency response
- ☐ High reliability
- ☐ RoHS compliant

### **◆** Applications

☐ Suitable for Power supplies, Surge protection Industrial control circuits, Voltage multipliers, Data isolation

### **♦** Summary of Specification

Operation Temperature	-55~+125 ℃
Rated Voltage	2KV to 5KV
Temperature Coefficient	NPO : $\leq$ ± 30ppm/ $^{\circ}$ C , -55~+125 $^{\circ}$ C (EIA Class $I$ )
	X7R : $\leq \pm 15\%$ , -55~+125 $^{\circ}$ C (EIA Class ${\rm II}$ )
Capacitance Range	NPO :10pF to 56nF ; X7R :330pF to 470nF
Dissipation Factor :	NPO : Q≧1000 ; X7R : D.F.≤2.5%
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller
Aging	NPO:0% ; X7R: 2.5 %
Dielectric Strength	1000≦V :120% Rated Voltage

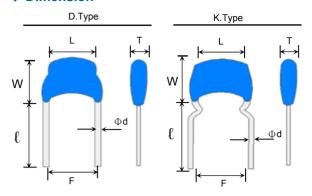
RDH	X	102	К	202	НК	Т
Product Code RDH: Radial Dipped Ultra High Voltage Capacitor	Dielectric  Ex.: N: NPO X: X7R	Capacitance Unit: pF Ex.: 100:10×10° 471:47×10¹ 102:10×10²	Tolerance  Ex.: C:+/-0.25pF D:+/-0.50pF J:+/-5% K:+/-10% M:+/-20%	Ex.: 102:1000Vdc 202:2000Vdc 302:3000Vdc 402:4000Vdc 502:5000Vdc	Leader Style  EX: Size GD:5.5x4.0 HD:5.5x4.5 I D:5.5x4.0 GK:5.5x4.0 HK:5.5x4.5 I K:5.5x4.0	Packaging T: Taping &Reel B: Bulk



## RDH Series-Radial Dipped Ultra High Voltage Capacitor



### **♦ Dimension**



Unit : mm [inches]								
TYPE	L (max)	W (max)	T (max)	I	=		l	
G□	6.35	5.59	6.86	5.08	5.0	25	0.5±0.1	
	[0.250]	[0.220]	[0.270]	[0.199]	[0.196]	[0.982]	[0.196]	
Н□	9.40	7.62	6.86	7.55	5.0	25	0.5±0.1	
	[0.370]	[0.300]	[0.270]	[0.296]	[0.196]	[0.982]	[0.196]	
Ι□	12.0	10.2	8.13	10.2	5.0	25	0.5±0.1	
	[0.470]	[0.400]	[0.320]	[0.400]	[0.196]	[0.982]	[0.196]	
J	14.5	12.7	8.13	12.8	5.0	25	0.5±0.1	
	[0.570]	[0.500]	[0.320]	[0.503]	[0.196]	[0.982]	[0.196]	
K□	17.0	15.2	8.13	15.36	5.0	25	0.5±0.1	
	[0.670]	[0.600]	[0.320]	[0.603]	[0.196]	[0.982]	[0.196]	
L	19.6	18.3	8.13	17.86	5.0	25	0.5±0.1	
	[0.770]	[0.720]	[0.320]	[0.701]	[0.196]	[0.982]	[0.196]	
М□	22.1	19.1	8.13	20.46	5.0	25	0.5±0.1	
	[0.870]	[0.750]	[0.320]	[0.804]	[0.196]	[0.982]	[0.196]	

### Capacitance Range

Capacitance	Range	9	
Dielectric	_	/pe Rated Voltage	Capacitance Range (pF)
Characteristic Type	Туре		88333333333333333333333333333333333333
		2KV	
		3KV	
	G	4KV	
		5KV	
		2KV	
		3KV	
	Н	4KV	
		5KV	
		2KV	
		3KV	
	I	4KV	
		5KV	
		2KV	
		3KV	
	J□	4KV	
NPO		5KV	
NPO		2KV	
	Κ□	_ 3KV	
	<b>K</b>	4KV	
		5KV	
		2KV	
	L	3KV	
	L [	4KV	
		5KV	
		2KV	
	М	3KV	
	IVI	4KV	
		5KV	
		2KV	
	N□	3KV	
	IN .	4KV	
		5KV	

■ Other dimensions, capacitance values and voltages rating are available. Please contact HEC.





Dielectric	Tuno	Rated	Capacitance Range (pF)
Characteristic	Туре	Voltage	333 4391 1102 1102 1102 1103 1103 1104 1104 1104 1104 1104 1104
	<u> </u>	2KV	
	G	3KV	
		2KV	
	ш	3KV	
	Н	4KV	
		5KV	
		2KV	
		3KV	
	I	4KV	
		5KV	
		2KV	
	J	3KV	
		4KV	
		5KV	
X7R	К	2KV	
AIR		3KV	
		4KV	
		5KV	
	_ [	2KV	
		3KV	
	L	4KV	
		5KV	
		2KV	
	МП	3KV	
	IVI	4KV	
		5KV	
		2KV	
	NI 🗔	3KV	
	N□	4KV	
		5KV	

<sup>■</sup> Other dimensions, capacitance values and voltages rating are available. Please contact HEC.



RDH Series	Specification & Test Condition				
Item	Specification	Test Condition			
Operation Temperature	-55 to +125°C				
Visual	No abnormal exterior appearance	Visual Inspection			
Capacitance	Within The Specified Tolerance	Class Frequency Voltage			
Quality Factor	Class I (NPO): More Than 30pF : $Q \ge 1000$ 30pF & Below: $Q \ge 400 + 20C$ (C:Cap., pF)	NPO C≤100pF 1MHz±10% 1.0±0.2Vrms C>100pF 1KHz±10%			
Dissipation Factor	Class II (X7R):  Maximum 0.025	X7R 1KHz $\pm$ 10% 1.0 $\pm$ 0.2Vrms  Perform a heat treatment at 150 $\pm$ 5 $^{\circ}$ C for 30min. then place room temp. for 24 $\pm$ 2hr.			
Insulation Resistance	10,000M $\Omega$ or 500/C $\Omega$ whichever is smaller. (C in Farad)	V≦500V, Rated Voltage V> 500V, Applied 500Vdc Charge Time : 60sec. Is applied less than 50mA current.			
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	1000 ≦ V :120% Rated Voltage for 1~5 sec. Current is limited to less than 50mA. Withstand voltage testing requires immersion of the part in an isolation fluid prevent to arcing on the chip surface, at voltages over 1000Vdc.			
Temperature Capacitance Coefficient	Char.         Temp. Range         Cap. Change           NPO(N)         -55°C ~ +125°C         ± 30ppm/°C           X7R (X)         -55°C ~ +125°C         ± 15%	Class I:  [C2-C1/C1(T2-T1)] × 100%  Class II:  (C2-C1)/C1 × 100%  T1:Standard Temperature(25°C)  T2:Test Temperature  C1:Capacitance At Standard Temperature  C2:Capacitance At Test Temperature			
Lead Strength	Tensile No mechanical damage such as lead Strength breakage and loosing.	Holding the body of the part, apply the pulling force to the lead as indicated below. Pulling strength: 5N Holding time: 10±1s			
	Bending No mechanical damage such as lead Strength . breakage and loosing.	Hold the capacitors to keep the axis vertical, bend it 90 degrees as shown below and bend back to the original position. This operation shall be done for 2~3s. and repeated for the following times.  Bending force: 5N(weight:0.51kg)  Test time: 2 times			
Solderability	Leads shall be covered by new solder more than 75% of its surface	Completely immerse both terminations in solder at 235± 5°C for 2±0.5s Solder: H63A Flux: Rosin Dipping: By 1.5~2.0mm from the root of lead			





Item		Specification	Test Condition			
Resistance to Soldering Heat	Appearance	No mechanical damage shall occur	Completely immerse both terminations in solder at 250± 5°C for 5±1s			
	Capacitance	Class I (NPO): Within 2.5% or ±0.25pF whichever is larger of initial value	Solder: H63A Flux: Rosin Dipping: By 1.5~2.0mm from the root of lead			
		Class II (X7R): Within ±10% of initial value	5			
	Q / Tan $\delta$	To satisfy the specified initial value				
	Insulation Resistance	To satisfy the specified initial value				
Temperature Cycle	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial			
	Capacitance	Class I (NPO): Within 2.5% or ±0.25pF whichever is larger of initial value	measurement.  Capacitor shall be subjected to five cycles of the temperature cycle as following:			
		Class II (X7R): Within ±7.5% of initial value	Step         Temp.(°C)         Time(min)           1         Min Rated Temp.+0/-3 (-55)         30			
	Q / Tan $\delta$	To satisfy the specified initial value	2 25 3 3 Max Rated Temp.+3/-0 (125) 30			
	Insulation Resistance	To satisfy the specified initial value	$\frac{4}{\text{Measure at room temperature after cooling for}}$ $\frac{25}{\text{Class I}} : 24 \pm 2 \text{ Hours}$ $\frac{25}{\text{Class II}} : 48 \pm 4 \text{ Hours}$			
Humidity	Appearance	No mechanical damage shall occur	Class ${\rm II}$ capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 ${\rm ^{\circ}C}$ before initial measurement.			
	Capacitance	Class I (NPO): Within 5% or ±0.5pF whichever is larger of initial value	Temperature : $40\pm 2$ °C Relative Humidity : $90 \sim 95$ %RH Test Time : $500 + 12/-0$ hr			
		Class $\rm II$ (X7R): Within $\pm 15\%$ of initial value				
	$\mathbf{Q}$ / $\mathbf{Tan}$ $\delta$	Class I (NPO): More Than 30pF : Q $\geq$ 350 30pF & Below: Q $\geq$ 275+2.5C	Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours			
		Class II (X7R): Maximum ±5.0%				
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)				





Item		Specification	Test Cond	dition	
High Temperature Load (Life Test)	Appearance No mechanical damage occur  Capacitance Class I (NPO):  Within 3% or ±0.3pF which		<ul> <li>2. before testing.</li> <li>Apply the voltage below at 125±2°C for 1,000 +48/-0h</li> </ul>		
		is larger of initial value Class II (X7R): Within ±15% of initial value	Rated Voltage V≤250Vdc 250Vdc < V< 1KVdc	Applied Voltage 150%Rated Voltage 120%Rated Voltage	
	Q / Tan $\delta$ Class I (NPO): More Than 30pF : Q $\geq$ 350 30pF & Below: Q $\geq$ 275+2.5C Class II (X7R): Maximum $\pm$ 5%		More Than 100%Rated Voltage 1KVdc(include 1KV)  Temperature: max. operating temperature Test Time: 1000 +12/-0Hr Current Applied: 50 mA Max.		
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)	Class I: 24 ± 2 Hours Class II: 48 ± 4 Hours	erature after cooling for	
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. Board shown in Fig 2. before testing. Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz in about 1 min. Repeat this for 2 hours each in 3perpendicular directions.		
	Capacitance	Within the specified tolerance			
	Q / Tan $\delta$	To satisfy the specified initial value			



## Axial Leader Ceramic Capacitors [General Capacitor – NPO,X7R,X5R,Y5V]

## **AXC** Series



#### **♦** Features

- ☐ Special internal electrode design offers the highest voltage rating
- ☐ Surface mount suited for wave and reflow soldering
- ☐ High reliability
- □ RoHS compliant

### Applications

- ☐ For EIA Class I can be used in stabilize frequency circuits
- ☐ For EIA Class Ⅱ can be used in by pass circuits

### **♦** Summary of Specification

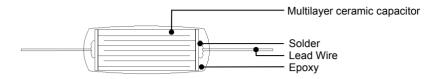
- Odiffinary of Opecification			
Operation Temperature	NPO,X7R : -55~+125 ℃		
	X5R : -55~+85 ℃		
	Y5V : -30~+85 ℃		
Rated Voltage	6.3Vdc to 50Vdc		
Temperature Coefficient	NPO : $\leq$ ± 30ppm/ $^{\circ}$ C , -55~+125 $^{\circ}$ C (EIA Class I )		
	X7R : $\leq \pm 15\%$ , -55~+125 $^{\circ}$ C (EIA Class ${\hspace{.1em} \mathbb{I} \hspace{.1em}}$ )		
	X5R : ≤ $\pm$ 15% , -55~+85 $^{\circ}$ C (EIA Class $^{\circ}$ II )		
	Y5V : ≤ $\pm$ 22~-82% , -30~+82 $^{\circ}$ C (EIA Class ${ { m II} }$ )		
Capacitance Range	NPO :0.5pF to 1nF		
	X7R :1.2nF to 6.8nF		
	X5R : 1.2nF to 10uF		
	Y5V :10nF to 1uF		
Dissipation Factor :	NPO: Q≥1000;		
	X7R,X5R,Y5V : Please see AXC specification data sheet		
Insulation Resistance	10G $\Omega$ or 500/C $\Omega$ whichever is smaller		
Aging	NPO:0%; X7R,X5R: 2.5 % Y5V: 6% per decade of time		
Dielectric Strength	250% Rated Voltage		

AXC	Х	103	К	050	D	А
Product Code AXC: Axial Leader Ceramic Capacitors	Dielectric  Ex.: N: NPO X: X7R B: X5R Y: Y5V	Capacitance Unit: pF Ex.: 2R0:2.0pF 100:10×10° 471:47×10¹ 102:10×10² 105:10×10⁵	Tolerance  Ex.: C:+/-0.25pF D:+/-0.50pF J:+/- 5% K:+/-10% M:+/-20% Z:+80/-20%	Rated Voltage Ex.: 007:6.3Vdc 016:16Vdc 025:25Vdc 050:50Vdc	Dimension (max.) EX: Size C: 5.5x4.0 mm D: 5.5x4.5 mm	Packaging  EX: H: Pitch 5.0mm C: Pitch 7.5mm A: Pitch 10mm S: 26mm Lead Ammo L: 56mm Lead Ammo

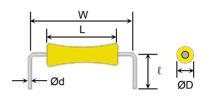




#### **♦** Dimension

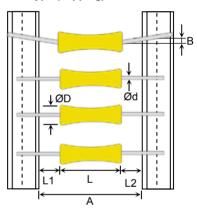


#### H,C,A. type (Bulk)



H,C,	I,C,A Unit:mm (inches)									
Type										
Туре	ØD	L		W		Ød	l			
С	2.0max	2.3max	5.0±0.5	7.5±0.5	10±0.5	0.45±0.05	20.0min			
	(0.079)	(0.09)	(0.197±0.020)	(0.295±0.020)	(0.394±0.020)	(0.018±0.002)	(0.787)			
D	2.2max	3.2max	5.0±0.5	7.5±0.5	10±0.5	0.45±0.05	20.0min			
	(0.087)	(0.126)	(0.197±0.020)	(0.295±0.020)	(0.394±0.020)	(0.018±0.002)	(0.787)			

#### S,L. type (Tapping)



	S						Un	it:mm (inches)
ſ	Туре			insertion pitch				
L		ØD	L	Α	В	L1-L2	Ød	L
ſ	С	2.0max	2.3max	26±0.5	0.8 max	0.5 max	0.45±0.05	5.0 mm
L		(0.079)	(0.09)	(1.024±0.02)	(0.03max)	(0.02max)	(0.018±0.002)	(0.197)
ſ	D	2.2max	3.2max				0.45±0.05	
L		(0.087)	(0.126)				(0.018±0.002)	

L						Ur	nit:mm (inches)
Type			insertion pitch				
	ØD	L	Α	В	L1-L2	Ød	L
С	2.0max	2.3max	52±0.5	1.2 max	1.0 max	0.45±0.05	5.0 mm
	(0.079)	(0.09)	(2.047±0.02)	(0.047 less)	(0.03max)	(0.018±0.002)	(0.197) min
D	2.2max	3.2max	,	,		0.45±0.05	
	(0.087)	(0.126)				(0.018±0.002)	

## **♦** Capacitance Range

		1	ı									_	<b></b>	- 14		- D		- /-											
Dielectric	Tuno	Rated											Capa	acita	anc	e R	ang	e (p	)F)										
Characteristic	Type	Voltage	0R5 1R0	2R0	3R0	4R0	6R0	0Y/	8R0	100	120	150	220	270	330	390	260	089	820	101	121	181	221	271	331	391	47.1 561	681	102 122
NPO	C,D	50V			П															I									
Dielectric	_	Rated										(	Capa	acita	anc	e R	ang	e (p	F)										
Characteristic	Туре	Voltage	102 122 152	182	222	332	392	472	562	822	103	123	183	223	273	333	473	563	683	823	104	724	334	474	684	105	335	475 685	106 226
	C,D	16V																											
X7R	C,D	25V																											
	C,D	50V																											
		6.3V							I																				
X5R	C,D	10V																				I							
, AOIX	0,0	16V																			I								
		50V																											
Y5V	C,D	50V																											

■ Other capacitance values and voltages rating are available. Please contact HEC.





# **AXC Series Specification & Test Condition**

Item	Specification	Test Condition
Operation Temperature	Char.         Operation Temp.           NPO(N)         -55°C ~ +125°C           X7R (X)         -55°C ~ +125°C           X5R (B)         -55°C ~ +85°C           Y5V (Y)         -30°C ~ +85°C	
Visual	No abnormal exterior appearance	Visual Inspection
Capacitance	Within The Specified Tolerance	Class Frequency Voltage NPO
Quality Factor	Class I (NPO): More Than 30pF : Q $\geq$ 1000 30pF & Below: Q $\geq$ 400+20C (C:Cap., p	C≤100pF 1MHz±10% 1.0±0.2Vrms <u>C&gt;100pF</u> 1KHz±10% F) X7R,X5R,Y5V
Dissipation Factor	Class II (X7R,X5R,Y5V): Please see AXC specification data shee	t $ \frac{ \text{C} \leq 10 \text{uF}  1 \text{KHz} \pm 10\% \qquad 1.0 \pm 0.2 \text{Vrms} }{ \text{C} > 10 \text{uF}  120 \text{Hz} \pm 20\% \qquad 0.5 \pm 0.2 \text{Vrms} } $ Perform a heat treatment at $150 \pm 5^{\circ} \text{C}$ for 30min. then place room temp. for $24 \pm 2 \text{hr}$ .
Insulation Resistance	10,000M $\Omega$ or 500/C $\Omega$ whichever is small for rated voltage>10V and greater 100/C $\Omega$ rated voltage≤10V	er Applied Voltage: Rated Voltage
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	V≦50 : 250% Rated Voltage for 1∼5 sec. Current is limited to less than 50mA
Temperature Capacitance Coefficient	Char.       Temp. Range       Cap. Chang         NPO (N) $-55^{\circ}$ C ~ +125 °C $\pm$ 30ppm/°C         X7R (X) $-55^{\circ}$ C ~ +125 °C $\pm$ 15%         X5R (B) $-55^{\circ}$ C ~ +85 °C $\pm$ 15%         Y5V (Y) $-30^{\circ}$ C ~ +85 °C       +22% ~ -82%	[C2-C1/C1(T2-T1)] × 100% Class II : (C2-C1)/C1 × 100%
Lead Strength	Tensile No mechanical damage suc Strength lead breakage and loosing.	drawing direction gradually. Pulling strength: 5N
	Bending No mechanical damage suc Strength . lead breakage and loosing.	With holding the capacitors to keep the axis vertical, bend it 90 degrees with weighting and put it back to the original position. This operatio shall be done for 2~3s. and repeat the following times.  Bending forth: 5N(weight :0.51kg) / 2 times
Solderability	Leads shall be covered by new solder mor than 75% of its surface	e Completely soak both terminations in solder at 235± 5℃ for 2±0.5s Solder : H63A Flux :Rosin Dipping :By 1.5~2.0mm form the root of lead
Resistance to Soldering Heat	Appearance No mechanical damage sha occur  Capacitance Class I (NPO): Within 2.5% or ±0.25pF wh is larger of initial value Class II (X7R,X5R,Y5V) see AXC specification data	250± 5°C for 5±1s  ichever Solder : H63A Flux :Rosin Dipping :By 1.5~2.0mm form the root of lead
	Q / Tan $\delta$ To satisfy the specified initial	
	Insulation To satisfy the specified initial Resistance	al value



# **AXC Series Specification & Test Condition**

Item		Specification	Test Condition				
Temperature Cycle	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat				
	Capacitance	Class I (NPO): Within 2.5% or ±0.25pF whichever is larger of initial value Class II (X7R,X5R,Y5V):	the temperature cycle as following:				
		Char. Cap. change $X7R(X) = \pm 7.5\%$ of initial value					
		$X7R(X)$ $\leq \pm 7.5\%$ of initial value $X5R(B)$ $\leq \pm 7.5\%$ of initial value $Y5V(Y)$ $\leq \pm 20\%$ of initial value	2 25 3 3 Max Rated Temp.+3/-0 (125) 30				
	$\overline{Q}$ / $Tan\delta$	To satisfy the specified initial value	4 25 3				
	Insulation Resistance	To satisfy the specified initial value	Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours				
Humidity	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment				
	Capacitance	Class I (NPO): Within 5% or $\pm$ 0.5pF whichever is larger of initial value Class II (X7R,X5R,Y5V): Char. Cap. change  X7R(X) $\leq \pm 15\%$ of initial value  X5R(B) $\leq \pm 15\%$ of initial value  Y5V(Y) $\leq \pm 30\%$ of initial value	at 150 +0/-10 $^{\circ}$ before initial measurement. Temperature : $40\pm2$ $^{\circ}$ C Relative Humidity : $90 \sim 95\%$ RH Test Time : $500 + 12/-0$ hr Measure at room temperature after cooling for Class I : $24\pm2$ Hours Class II : $48\pm4$ Hours				
	${\sf Q}$ / ${\sf Tan}\delta$	see AXC specification data sheet					
	Insulation Resistance	see AXC specification data sheet					
High Temperature Load	Appearance	No mechanical damage shall occur	Class  ☐ capacitors applied DC testing voltage is applied for one hour at maximum operation				
(Life Test)	Capacitance	Class I (NPO): Within 5% or $\pm$ 0.5pF whichever is larger of initial value Class II (X7R,X5R,Y5V): Char.  Cap. change	temperature ±3°C then shell be set for 48± 4 hours at room temperature and the initial measurement shall be conducted.  Applied Voltage: 200% Rated Voltage for C < 1.0uF and 150% Rated Voltage for C≥1.0uF.  However: The rated voltage is 6.3V/10V,applied voltage of 100% rated voltage.				
	Q / Tan $\delta$	see AXC specification data sheet	Temperature: max. operating temperature Test Time: 1000 +48/-0 Hr				
	Insulation Resistance	see AXC specification data sheet	Current Applied : 50mA Max Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours				
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. Board shown in Fig 2. before testing.				
	Capacitance	Within the specified tolerance	Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55H.				
	Q / Tan $\delta$	To satisfy the specified initial value	and back to 10Hz in about 1 min. Repeat this for 2 hours each in 3perpendicular directions.				

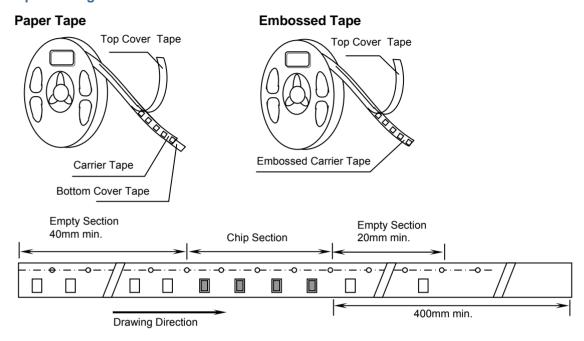


## **◆ Multilayer Ceramic Chip Capacitor**

## Bulk Packing

Standard packing 10Kpcs/pack, others according to customers' request.

## • Tape Packing



## Material And Quantity (¢180mm)

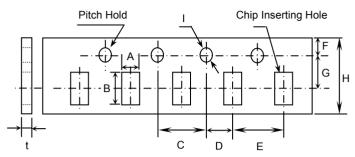
Chip Size	D	imension (mm)		¢180m	m reel
(EIA Code)	L	W	T	Paper Tape	Plastic Tape
0201	0.6	0.3	T≤0.33	15,000 pcs/reel	N/A
0402	1.0	0.5	T≤0.55	10,000 pcs/reel	N/A
0603	1.6	0.8	T≤0.90	4,000 pcs/reel	N/A
0805	2.0	1.25	T≤0.90	4,000 pcs/reel	N/A
			0.9< T≤1.25	N/A	3,000 pcs/reel
1206	3.2	1.6	T≤0.90	4,000 pcs/reel	N/A
			0.9< T≤1.25	N/A	3,000 pcs/reel
			T>1.25	N/A	2,000 pcs/reel
1210	3.2	2.5	T≤1.25	N/A	3,000 pcs/reel
			T>1.25	N/A	2,000 pcs/reel
1808	4.6	2.0	T≤1.25	N/A	3,000 pcs/reel
			T>1.25	N/A	2,000 pcs/reel
1812	4.6	3.2	T≤2.20	N/A	1,000 pcs/reel
			T>2.20	N/A	700 pcs/reel
1825	4.6	6.35	T≤2.20	N/A	700 pcs/reel
			T>2.20	N/A	400 pcs/reel
2208	5.7	2.0	T≤2.20	N/A	1,000 pcs/reel
2211	5.7	2.8	T≤2.20	N/A	1,000 pcs/reel
			T>2.20	N/A	700 pcs/reel
2220	5.7	5.0	T≤2.20	N/A	1,000 pcs/reel
			T>2.20	N/A	700 pcs/reel
2225	5.7	6.35	T≤2.20	N/A	700 pcs/reel
			T>2.20	N/A	400 pcs/reel

NA: Not Available



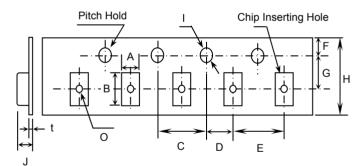
## • Dimension of Tape Specification

## Paper Tape



						Unit: mm
	0201	0402	0603	0805	1206	1210
Α	0.37±0.1	0.61±0.1	1.10±0.2	1.50±0.2	1.90±0.2	2.90±0.2
В	0.67±0.1	1.20±0.1	1.90±0.2	2.30±0.2	3.50±0.2	3.60±0.2
С	4.00±0.1	>				
D	2.0±0.05	>				
E	2.00±0.1	>	4.00±0.1	>		
F	1.75±0.1	>	-			
G	3.5±0.05	>			_	
H	8.00±0.3	>			_	
Π	¢1.5+0.1/-0	>				
t	1.1 max.	>				

## **Embossed Tape**

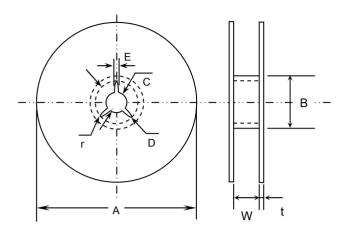


Unit: mm

	0805	1206	1210	1808	2208	1812	1825	2211	2220	2225
Α	1.5±0.1	1.9±0.2	2.9±0.2	2.5±0.2	2.5±0.2	3.6±0.2	6.9±0.2	3.2±0.2	5.4±0.2	6.9±0.2
B	2.3±0.2	3.5±0.2	3.6±0.2	4.9±0.2	6.1±0.2	4.9±0.2	4.9±0.2	6.1±0.2	6.1±0.2	6.1±0.2
С	4.0±0.1	<b>→</b>								
D	2.0±0.05	<del>→</del>								
E	4.0±0.1	<del>→</del>				8.0±0.1	<b>→</b>			
F	1.75±0.1	<del>→</del>								
G	3.5±0.05	<del></del>		5.5±0.05	<del></del>					
<u>H</u>	8.0±0.3	<b>→</b>		12.0 +3/-0	<b>→</b>					
<u> </u>	¢1.5+0.1/-0	<b>→</b>								
J	3.0 max.	<b>→</b>		4.0 max.	<b>→</b>					
t	0.3 max.	<del>→</del>								
0	0.15 min.	<del>→</del>								

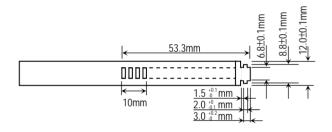


## **Reel Dimension**

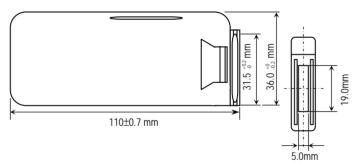


		Unit: mm
	0402 to 1210	1808 to 2220
<u>A</u>	¢ 382 max.	¢ 178±0.2
<u>B</u>	¢ 50 min.	¢ 60±0.2
<u>C</u>	¢ 13±0.5	<u>¢ 13±0.5</u>
<u>D</u>	<u>¢ 21±0.8</u>	<u>¢ 21±0.8</u>
<u>E</u>	¢ 2.0±0.5	¢ 2.0±0.5
W	10±0.15	13±0.3
t	2.0±0.5	17±1.4
r	1.0	1.0

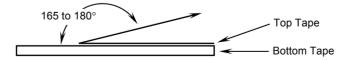
## **Bulk Cassette Packing**



Cassette Pa	acking		Unit: mm
Chip Size	0402	0603	2012
Length	1.00±0.05	1.60±0.10	2.00±0.20
Width	0.50±0.05	0.80±0.10	1.25±0.20
Thickness	0.50±0.05	0.80±0.10	0.60±0.10
Quantity	50,000pcs	15,000pcs	10,000pcs



## • Cover Tape Peel Off Force



The peel off force of cover tape is 5 to 70 grams in the direction of arrow.



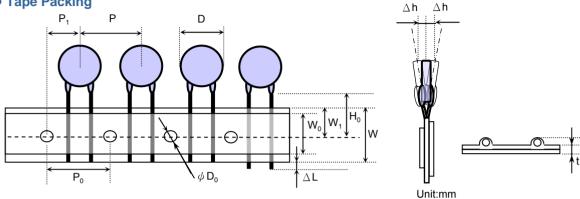


## **♦** Ceramic Disc Capacitors Packing Information (SDC,HDC Series)

## Bulk Packing

Standard packing 500pcs&1,000pcs/pack, others according to customers' request.

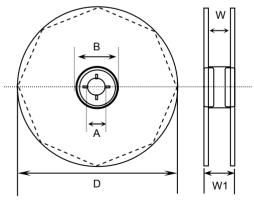
## • Tape Packing



	Symbol		Lea	ad Space
	•	5.00mm	6.35mm	7.50mm
Pitch of component	Р	12.7±1.0		
Feed Hole Pitch	$P_0$	12.7±0.3		
Hole center to component center	P₁	6.35±1.3		
Body diameter	D	11.0 max		
Hold position	W1	8+1.0-0.5		
Hold tape width	$W_0$	10 min		
Hold position	$W_1$	9±0.5		
Lead wire clinch	H₀	16+1.5-0.5		
Total tape thickness	t1	0.6±0.3		
Total thickness, tape& lead wire	t2	1.5 max		
Feed hold diameter	$\phi D_0$	4.0±0.2		
Deviation across tape	∧h	2.0 max		
Protrusion Length	$\triangle L$	1.0 max		

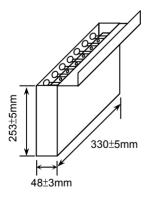
## Packing Dimension

#### **Reel Dimension:**



	Unit: mm
Code	Dimension
W1	56
W	44
D	340
Α	30
В	84

## **Ammo Dimension:**



## Packing Quantity

Unit:mm

Package	One Box / One Reel	Carton Box
Taping Reel Pack	1,500 / 2,000 pcs	15,000 / 20,000 pcs
Ammo Box Pack	1,000 / 1,500 pcs	10,000 / 15,000 pcs

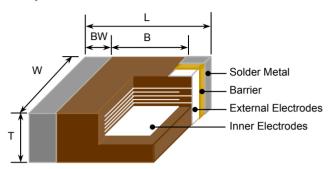




The Multilayer Ceramic Chip of Capacitors supplied in bulk, cassette or taped & reel package are ideally suitable for thick-film Hybrid circuits and automatic surface mounting on printed circuit boards.

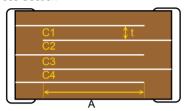
Mainly use in electric circuit for by-pass, filtering and smoothing circuit.

#### **♦** Shapes and Dimension



EIA style	L	W	Tmax.	BWmin	Bmin.
0201	0.60±0.03	0.30±0.03	0.33	0.10	0.20
	[.024±.002]	[.011±.002]	[.013]	[.004]	[.008]
0402	1.00±0.05	0.50±0.05	0.55	0.15	0.30
	[.039±.002]	[.020±.002]	[.022]	[.006]	[.012]
0603	1.60±0.10	0.80±0.10	0.90	0.15	0.40
	[.063±.004]	[.031±.004]	[.035]	[.006]	[.016]
0805	2.00±0.20	1.25±0.25	1.45	0.20	0.70
	[.079±.008]	[.049±.008]	[.057]	[.008]	[.028]
1206	3.20±0.30	1.60±0.20	1.80	0.30	1.50
	[.126±.012]	[.063±.008]	[.071]	[.012]	[.059]
1210	3.20±0.30	2.50±0.20	2.60	0.30	1.60
	[.126±.012]	[.098±.008]	[.102]	[.012]	[.063]
1808	4.60±0.30	2.00±0.20	2.20	0.30	2.50
	[.181±.012]	[.079±.008]	[.087]	[.012]	[.098]
1812	4.60±0.30	3.20±0.30	3.00	0.30	2.50
	[.181±.012]	[.126±.012]	[.118]	[.012]	[.098]
1825	4.60±0.30	6.35±0.40	2.60	0.30	2.50
	[.181±.012]	[.250±.016]	[.102]	[.012]	[.098]
2208	5.70±0.40	2.00±0.20	2.20	0.30	3.50
	[.220±.016]	[.197±.008]	[.087]	[.012]	[.137]
2211	5.70±0.40	2.80±0.40	3.00	0.30	3.50
	[.220±.016]	[.110±.016]	[.118]	[.012]	[.137]
2220	5.70±0.40	5.00±0.40	3.00	0.30	3.50
	[.220±.016]	[.197±.016]	[.118]	[.012]	[.137]
2225	5.70±0.40	6.35±0.40	3.00	0.30	3.50
	[.220±.016]	[.250±.016]	[.118]	[.012]	[.137]

#### Cross Section



$$C = \varepsilon_0 \cdot \varepsilon \qquad A \cdot N$$

C : Capacitance

 $\varepsilon$   $_{\rm 0}$  : Dielectric constant in the air  $\varepsilon$  : Proportional dielectric constant

A : Overlap Area t : Dielectric Thickness

N: Layers

## **◆ Nominal Capacitance and Tolerance**

1. Standard Combination of Nominal Capacitance and Tolerance Class ΕIΑ Tolerance **Nominal Capacitor** Symbol NPO J (±5%),K (±10%) E-12 ,E-24 Series П X7R K(±10%), M(±20%) E-3,E-6 Series X7E K(±10%), M(±20%) E-3,E-6 Series X5R K(±10%), M(±20%) E-3,E-6 Series Y5U M(±20%),Z(+80/-20 %) E-3 Series Y5V M(±20%),Z(+80/-20 %) E-3 Series

M(±20%),Z(+80/-20 %)

2. E Series (Standard Number)

E- Series		Application Capacitance				
E-3	<u>1</u>	.0	2	.2	<u>4.</u>	7
E-6	1.0	<u>1.5</u>	2.2	3.3	<u>4.7</u>	6.8
E12	1.0 1.2	<u>1.5</u> <u>1.8</u>	2.2 2.7	3.3 3.9	4.7 5.6	6.8 8.2
E24	<u>1.0</u> <u>1.2</u>	<u>1.5</u> <u>1.8</u>	<u>2.2</u> <u>2.7</u>	3.3 3.9	<u>4.7</u> <u>5.6</u>	<u>6.8</u> <u>8.2</u>
	<u>1.1</u> <u>1.3</u>	<u>1.6</u> <u>2.0</u>	<u>2.4</u> <u>3.0</u>	<u>3.6</u> <u>4.3</u>	<u>5.1</u> <u>6.2</u>	<u>7.5</u> <u>9.1</u>
						-



Z5U

E-3 Series



## **♦EIA Designations**

For Class | Dielectrics

Coefficie capacitai (ppm/ °C	nce	Multiplier a to column			e of temp. m/ °ℂ )
0.0	С	-1.0	0	30	G
1.0	M	-10	1	60	Н
1.5	Р	-100	2	120	J
2.2	R	-1000	3	250	K
3.3	S	-10000	4	500	L
4.7	Т	+1	5	1000	M
7.5	U	+10	6	2500	N
		+100	7		
		+1000	8		
		+10000	9		

For Class ∏ Dielectrics

Low Ter Symbol		High Tem Symbol	ıp.	Max. %△C Symbol	
-55℃	Х	+45°C	3	±1.0%	Α
-30℃	Υ	+65℃	4	±1.2%	В
+10℃	Z	+85°C	5	±2.2%	С
		+105℃	6	±3.3%	D
		+125℃	7	±4.7%	Е
		+150 ℃	8	±7.5%	F
l		+200 ℃	9	±10.0%	Р
l				±15.0%	R
l				±22.0%	S
				+22% /-33%	Т
				+22% /-56%	U
l				+22% /-82%	V

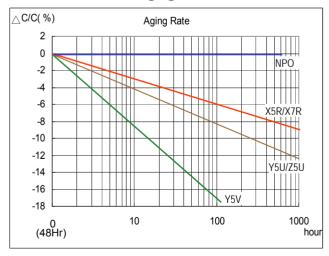
Ex.: C0G Negative U2J Negative

0±30ppm/ °C 750±120ppm/ °C Ex.: X7R  $-55 \sim +125 \,^{\circ}\text{C} \quad \pm 15\%$ Y5V  $-30 \sim +85 \,^{\circ}\text{C} \quad +22\%/-82\%$ 

## ◆ Operation Temperature Range

Class	EIA Symbol	Dielectric Code	Temperature Range(°ℂ)	Capacitance Change	Reference Temperature
I	NPO	N	-55℃ ~ +125 ℃	0±30 ppm/°C	20℃
П	X7R	X	-55℃ ~ +125℃	±15%	<b>20</b> ℃
	X7E	С	-55℃ ~ +125℃	±4.7%	25℃
	X5R	В	-55°C ~ +85°C	±15%	20℃
	Y5V	Υ	-30℃ ~ +85℃	+22/-82 %	20℃
	Y5U	E	-30°C ~ +85°C	+22/-56 %	<b>25</b> ℃
	Z5U	Z	+10°C ~ +85°C	+22/-56 %	<b>25</b> ℃

## ◆ Dielectric Material – Aging Rate



Aging Rate NPO: 0

X7R/X5R : 2 ~ 4 % /decade Y5U/Z5U : 4~6% / decate Y5V : 6~10 % /decade

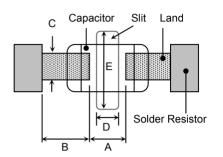
After performing De-Aging at 150 $\pm$ 5  $^{\circ}$ C for 30 minutes and placement room temperature for 48 hours.



#### Construction of Board Pattern

Improper circuit layout and pad/land size may cause excessive or not enough solder amount on the PC board. Not enough solder may create weak joint, and excessive solder may increase the potential of mechanical or thermal cracks on the ceramic capacitor. Therefore we recommend the land size to be as shown in the following table:

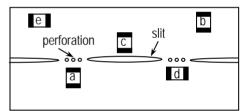
1. Size and recommend land dimensions for reflow soldering



EIA Code Chip (mm)		Land (mm)					
Lirt Gode	L	W	Α	В	С	D	E
0201	0.60	0.30	0.2~0.3	0.2~0.4	0.2~0.4		
0402	1.00	0.50	0.3~0.5	0.3~0.5	0.4~0.6	-	
0603	1.60	0.80	0.4~0.6	0.6~0.7	0.6~0.8	-	
0805	2.00	1.25	0.7~0.9	0.6~0.8	0.8~1.1	-	
1206	3.20	1.60	2.2~2.4	0.8~0.9	1.0~1.4	1.0~2.0	3.2~3.7
1210	3.20	2.50	2.2~2.4	1.0~1.2	1.8~2.3	1.0~2.0	4.1~4.6
1808	4.60	2.00	2.8~3.4	1.8~2.0	1.5~1.8	1.0~2.8	3.6~4.1
1812	4.60	3.20	2.8~3.4	1.8~2.0	2.3~3.0	1.0~2.8	4.8~5.3
1825	4.60	6.35	2.8~3.4	1.8~2.0	5.1~5.8	1.0~4.0	7.1~8.3
2208	5.70	2.00	4.0~4.6	2.0~2.2	1.5~1.8	1.0~4.0	3.6~4.1
2211	5.70	2.80	4.0~4.6	2.0~2.2	2.0~2.6	1.0~4.0	4.4~4.9
2220	5.70	5.00	4.0~4.6	2.0~2.2	3.5~4.8	1.0~4.0	6.6~7.1
2225	5.70	6.35	4.0~4.6	2.0~2.2	5.1~5.8	1.0~4.0	7.1~8.3

2. Mechanical strength varies according to location of chip capacitors the P.C. board.

Design layout of components on the PC board such a way to minimize the stress imposed on the components, upon flexure of the boards in depanelization or other processes.



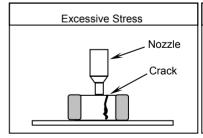
Component layout close to the edge of the board or the "depanelization line" is not recommended.

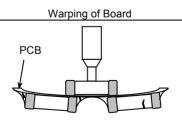
Susceptibility to stress is in the order of: a>b>c and d>e

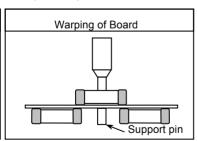
### Mounting

1. Sometimes crack is caused by the impact load due to suction nozzle in pick and place operation.

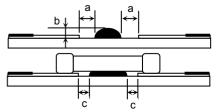
In pick and place operation, if the low dead point is too low, excessive stress is applied to component. This may cause cracks in the ceramic capacitor, therefore it is required to move low dead point of a suction nozzle to the higher level to minimize the board warp age and stress on the components. Nozzle pressure is typically adjusted to 1N to 3N (static load) during the pick and place operation.







#### 2. Amount of Adhesive



Example: 0805 & 1206

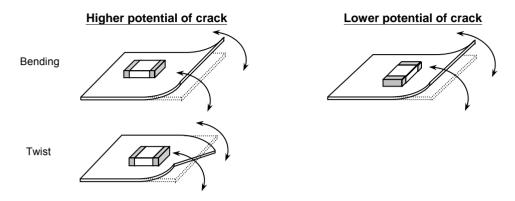
а	0.2mm min.
b	70 ~ 100 μm
С	Do not touch the solder land





#### ◆ Handling after chip mounted

1. Proper handling is recommended, since excessive bending and twist of the board, depends on the orientation of the chip on the board, may induce mechanical stress and cause internal crack in the capacitor.

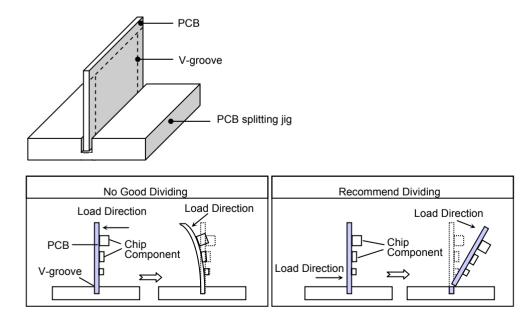


2. There is a potential of crack if board is warped due to excessive load by check pin



3. Examples of PCB dividing/breaking jigs:

The outline of PCB breaking jig is shown below. It is recommended when dividing or breaking PCB that they are held near the jig where no bending will occur, this way there will be no compressive stress applied to the components or varistors on the PCB. Do not hold the PCB at a position which is far away from the jig, tensile stress to the varistors may cause them to crack.



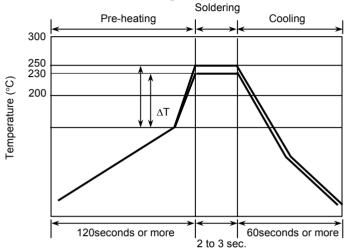


### **♦**Soldering

#### 1. Wave Soldering

Most of components are wave soldered with solder at 230 to 250°C. Adequate care must be taken to prevent the potential of thermal cracks on the ceramic capacitors. Refer to the soldering methods below for optimum soldering benefits.

#### **Recommend flow soldering temperature Profile**



Soldering Method	Change in Temp.(°ℂ)
1206 and Under	ΔT ≤100~130°C max.

To optimize the result of soldering, proper preheating is essential:

- 1) Preheat temperature is too low
  - a. Flux flows to easily
  - b. Possibility of thermal cracks
- 2) Preheat temperature is too high
  - a. Flux deteriorates even when oxide film is removed
  - b. Causes warping of circuit board
  - c. Loss of reliability in chip and other components

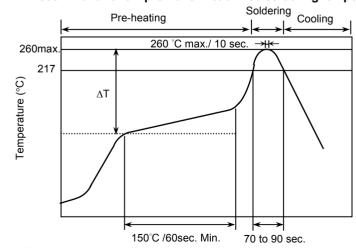
#### Cooling Condition:

Natural cooling using air is recommended. If the chips are dipped into a solvent for cleaning, the temperature difference ( $\Delta T$ ) between the solvent and the chips must be less than 100°C.

#### 2. Reflow Soldering

Preheat and gradual increase in temperature to the reflow temperature is recommended to decrease the potential of thermal crack on the components. The recommended heating rate depends on the size of component, however it should not exceed 3°C/Sec.

#### Recommend reflow profile for Lead-Free soldering temperature Profile (MIL-STD-202G #210F)



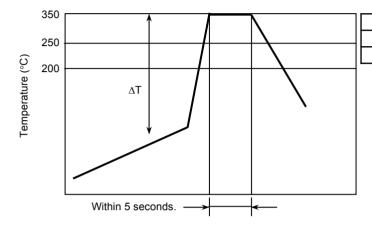
Soldering Method	Change in Temp.(℃)
1206 and Under	ΔT ≤190°C
1210 and Over	ΔT ≤130°C

The cycles of soldering : Twice (Max.)



#### 3. Hand Soldering

Sudden temperature change in components, results in a temperature gradient recommended in the following table, and therefore may cause internal thermal cracks in the components. In general a hand soldering method is not recommended unless proper preheating and handling practices have been taken. Care must also be taken not to touch the ceramic body of the capacitor with the tip of solder Iron.



Soldering Method	Change in Temp.(°ℂ)		
1206 and Under	ΔT ≤150°C		
1210 and Over	ΔT ≤130°C		

## How to Solder Repair by Solder Iron

1) Selection of the soldering iron tip

The required temperature of solder iron for any type of repair depends on the type of the tip, the substrate material, and the solder land size.

- 2) recommended solder iron condition
  - a.) Preheat the substrate to (60°C to 120°C) on a hot plate. Note that due to the heat loss, the actual setting of the hot plate may have to be higher. (For example 100°C to 150°C)
  - b.) Soldering iron power shall not exceed 30 W.
  - c.) Soldering iron tip diameter shall not exceed 3mm.
  - d.) Temperature of iron tip shall not exceed 350°C of Value,and the process should be finished within 5 seconds. **(refer to MIL-STD-202G)**
  - e.) Do not touch the ceramic body with the tip of solder iron. Direct contact of the soldering iron tip to ceramic body may cause thermal cracks.
  - f.) After soldering operation, let the products cool down gradually in the room temperature.

#### **♦**Storage

Store the capacitors where the temperature and relative humidity don't exceed 40°C and 70%RH. We recommend that the capacitors be used within 6 months from the date of manufacturing. Store the products in the original package and do not open the outer wrapped, polyethylene bag, till just before usage. If it is open, seal it as soon as possible or keep it in a desiccant with a desiccation agent.



Internal MLCC cracking can result in serious failure modes. If ceramic capacitors are subjected to severe mechanical stress, a bending crack may occur. This crack can run through two or more electrodes of opposing polarity and result in a short circuit. Typical bending cracks are shown below. In the worst case scenario. these short circuits may lead to the MLCC overheating and catastrophic failure.



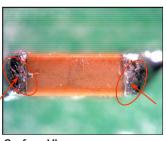
Typical Applications are power circuit input and output filtering, smoothing...



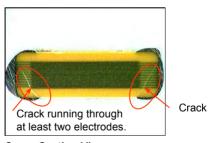
Standard termination construction may result in cracking during PCB bending, vibration, Depanelizing, etc.

## **Actual Examples:**

Failure Mode Type 1



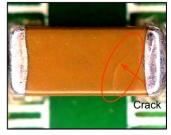
**Surface View** 



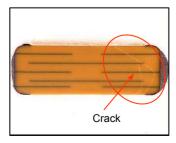
**Cross Section View** 

The failure mode results from PCB bending forces. These cracks may not be visible on the MLCC surface. Cross sectional analysis is required to determine these internal cracks.

Failure Mode Type 2 (wetting greater than 2/3 of thickness)



Top View



**Cross Section View** 

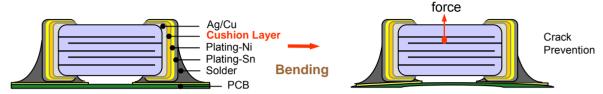
MLCC cracking frequently occurs during the circuit board depanelizing process. The root cause is knife (blade) vibration during the process.





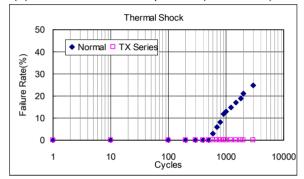
<u>Holy Stone</u> has developed the "Super Term" Series (TX suffix in the part number), which incorporates a "cushion layer" in the termination structure. This construction effectively absorbs external forces, reduces the incidence of cracking and improve overall product reliability. SuperTerm product applications include: high temperature automotive, power circuits and other critical end products with extreme processing conditions.

#### **TX Product**



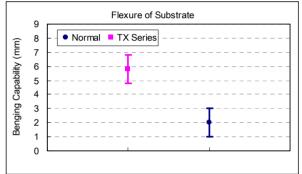
#### Reliability/Durability Comparison

#### (a) Thermal Shock Comparison (0805/X7R)

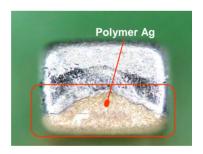


Thermal shock test on standard termination results of inception of failure at 500 cycles. SuperTermTX Series reliability improves to over 3000 cycles.

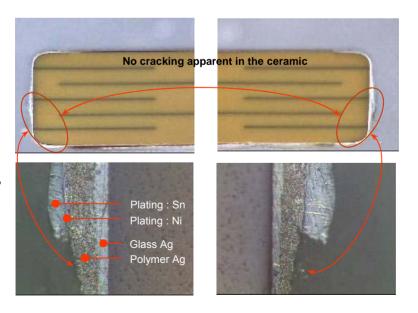
#### (b) Substrate Flexure Comparison (0805/X7R)



Bending test on Superterm shows an improvement of about 5.0 mm bend vs. an average of about 2.0 mm. for standard termination.



During destructive bending test, the PCB is subjected to bending until capacitor failure. With superterm there is no cracking damage in the ceramic. Superterm effectively prevents ceramic body cracking during extreme mechanical stress as simulated by this test.



Superterm failures resulting from destructive bending test occur in the OPEN mode and not the short circuit mode typical of standard termination failures. The SuperTerm cushion layer material is a "polymer silver" material and can be seen in the above photo.

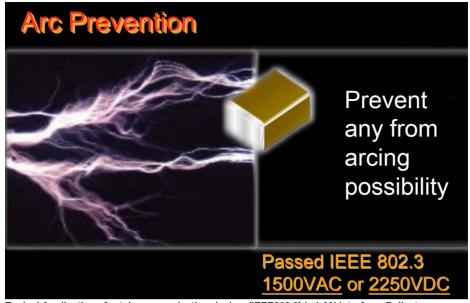




## MLCC Arc Prevention – for Hi-Pot Testing

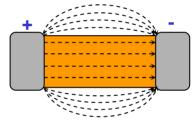
Base on the ceramic material a relativity air or vacuum that electric conductivity is higher. And are differences ambient environment as temperature, moisture, termination creep age distance, and PCB layout...etc. all to effective arcing when Hi-Pot tests. The especially is a high dielectric constant (ex. X7R, Y5V...).

Holy stone developed to possess arc prevention solution on the MLCC product and to meet application and enactment criteria.



Typical Applications for telecommunication devices(IEEE802.3) in LAN interface, Ballast...

#### Surface arcing a phenomenon



Dielectric flux is generated upon applying voltage to the capacitor as show Fig.



The typical surface arcing on MLCC that is termination-to-termination (show in polarized lighting)

#### NPO & X7R Material Content & Characteristic Comparison

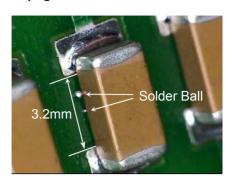
Item	NPO	X7R
Dielectric Constant	30 ~ 100	2000 ~ 4000
I. Resistance	>10 <sup>13</sup> Ω	>10 <sup>11</sup> Ω
B.D. Voltage	70~80 Vdc/um	40~50 Vdc/um
Grain Size	< 500nm	900nm ~ 1500nm
Grain Size (x8000)	o dan dang Pagga Odan U ayunu dang Kandan Sa	u iliku Amerika Amerika Amerika Amerika iliku iliku U ulikuka Amerika iliku iliku
Porosity (x1000)	ar goosay (జరగు అరిశివి ఉమోది మేదికి	to open to control to a to the section of

- The different grain sharp will lead to different grain density after sintering
- Because the NPO thinner & longer grain, so grow more tight & dense grain structure than X7R.Especially cause the porosity different between NPO & X7R.
- Much surface porosity will trap more dust & moisture.
- When add a voltage(especially high voltage), the porosity on the surface will gather the electric charge easily, and when the additional voltage reach the rouse voltage then the electric arc will occur.



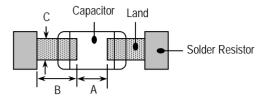


#### Creepage distance v.s. Arc effect



Exist the residual solder will be reduce creepage distance and Insulation resistance.

#### **Recommend Land Requirement**



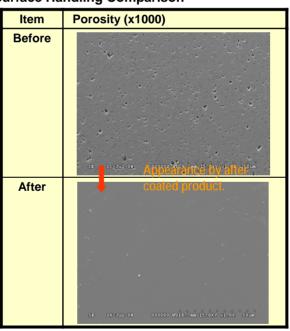
EIA Code	Chip (mm)		Land (mm)		
EIA Code	L	W	Α	В	С
1808	4.6±0.3	2.0 ±0.2	3.2~3.6	1.2~2.4	1.5~1.8
1812	4.6±0.3	3.2 ±0.2	3.2~3.6	1.2~2.4	2.3~3.0
2208	5.7±0.4	2.0 ±0.2	4.0~4.6	1.2~2.4	1.5~1.8
2211	5.7±0.4	2.0 ±0.3	4.0~4.6	1.2~2.4	2.0~2.6
2220	5.7±0.4	5.0 ±0.4	4.0~4.6	1.2~2.4	3.5~4.8

The metal-to-metal distance can to effect arcing too. It the more wide the more well. Therefore, we need to consideration by high voltage capacitors that pad-to-pad layout design. Above is a recommend land design.

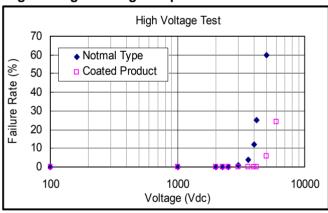
#### Coated for arcing prevent solution.

For preventing form arcing because of much surface porosity in X7R, the insulated gel(high insulated material) was used for filling the surface porosity and provide the smooth & less porosity surface. The following tests descript the different between coating & non-coating effect in X7R component.

#### **Surface Handling Comparison**



#### **High Voltage Testing Comparison**



- The coating will filling the porosity of the X7R surface and provide a smooth surface to against hi-voltage charge.
- The Hi-pot endurance level will increase about 1000Vdc after coating in single & on-board hi-pot test.

The against hi-pot ability will increase 1000Vdc after coating product. Although NPO could provide better against hi-pot arcing ability but the capacitance was limited lower because of material characteristic and the X7R could provide higher capacitance but much porosity surface will reduce the ability to against arcing. So HEC provide a coating process solution will be the total solution in X7R against hi-pot arcing issue.



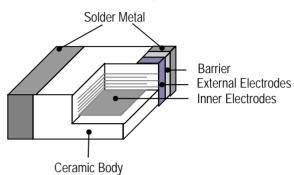


## • Description:

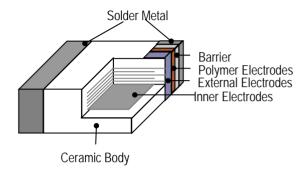
Multi-layer Ceramic Capacitor include: NPO 、X7R 、X5R 、X6S 、X7E 、Y5V 、Y5U & Z5U dielectrics.

## • Basic Construction/Homogenous Material:





(b) "X" Type: Super Termination(Option)



- Multi-layer Ceramic Chip are Homogenous devices and a material that cannot be mechanically disjointed into different materials.
- Multi-layer Ceramic Chip products: Standard sizes are fully RoHs Compliant.

Group Series		RoHS Status	Cadmium	Hexavalent Chromium	Lead *	Mercury	PBBs	PBDE	
			Limit	<0.01%	<0.01%	<0.1%	<0.01%	<0.01%	0.01%
MLC Family	NCC,HCC, VAC,LSC RFC,MCA, HCX		Available	<b>V</b>	<b>V</b>	√	√	1	√
Surface mount	TCX,LDC,	нтс	Available	$\checkmark$	√	$\sqrt{}$	$\checkmark$	<b>√</b>	$\checkmark$
1	HCN,HCY,	SAC	Available	<b>V</b>	<b>V</b>	√*	<b>V</b>	√	√
	HVC MMC	NPO	Available	√	√	√ / √*	√	<b>V</b>	<b>√</b>
		X7R	Available	√	√	√*	√	<b>V</b>	√
	HDC,SDC,RDC,RDH		Available	$\checkmark$	V	√	√	<b>√</b>	√

#### \* Pb in internal ceramic insert – exempt from RoHS annex 7 to Article 4.1

RoHS Status	Lead-Free Status / MSL level
External plating: 100% Matte Sn as Standard.	<ul> <li>※ Pb-free Reflow &amp; Wave Solder compliant, MSL=1</li> <li>• Reflow : 260° C max recommended.</li> <li>• Wave : 260° C max recommended,</li> <li>Wave &amp; Reflow profile refer to HEC recommended solder profile.</li> </ul>

Part Number Designation: (Generally no change to P/N, but available as P/N prefix at customer request)

**Product Marking:** 

(available at customer request, highlighted or marked on reel and container)

RoHS Compliant : No Change to P/N Pb-Free : No Change to P/N

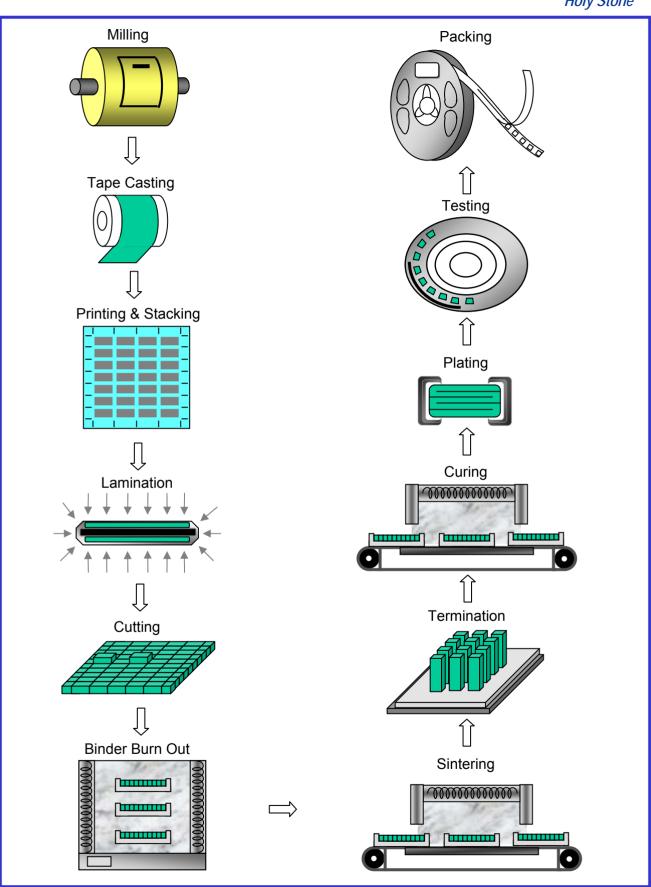
Pb free: Pb free



refer to JEDEC&IPC Std.











# ISO Certification

Plant	Certificated	Date	Organization	Registration No.
Lung Tan Manufacturing	ISO 9001:1994	17, Jul.,2000	BSI	FM 38437
Lung Tan Manufacturing	ISO 9001:2000	20,May,2002	BVQI	107405
Lung Tan Manufacturing	ISO 14001:1996	29,May,2003	BVQI	131145
Dongguan Manufacturing	ISO 9001:2000	16.Dec.,2003	BVQI	107405
Lung Tan Manufacturing	QS 9000 : 1998	04.Oct.,2004	BVQI	162522

ISO 9001:2000



ISO 14001:1996



QS 9000:2004



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Fax:886-7-5366105

Zip code: 806

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Fax: 86-21-62826722

Zip Code: 200052

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Tel: 951-696-4300 Fax: 951-696-4301

Website: www.holystonecaps.com info@holystonecaps.com

• Lungtan Plant/龍潭生產事業處

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HsiangTao Yuan County, Taiwan, R.O.C.

Tel: 886-3-4995288

Fax: 886-3-4995299

Zip code: 325

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Room 62A, Heshan Garden Garden Park. Binhe

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Fax:86-512-68095711

Zip code: 215021

● Hong Kong Office/香港分公司

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Fax: 852-23055789

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email: Sales@holystonecaps.co.uk